



INTEGRATED PHOTONICS TO THE RESCUE OF FEMTOSECOND BEAM DIAGNOSTICS

Franz X. Kärtner

Center for Free-Electron Laser Science (CFEL), DESY, Hamburg, Germany
Ultrafast Optics and X-Rays Division

Department of Physics and The Hamburg Center for Ultrafast Imaging,
University of Hamburg, Germany

and

Research Laboratory of Electronics, MIT, USA

IBIC 2017 - Grand Rapids, Michigan, USA



Acknowledgement

Femtosecond Timing:

M. Xin
A. Kalaydzhyan
M. Peng (JPL)
K. Safak, (Cycle GmbH)
A. Nejadmalayeri (Samsung)
J. Kim (KAIST)
J. Cox (Sandia National Laboratory)

Collaborators:

AdvR: P. Battle, T. Roberts
DESY: H. Schlarb, F. Ludwig,
C. Löhl, M. Felber, C. Sydlo

Integrated Photonics - ADC:

P. Callahan
N. Sing
K. Styrkova
K. Ravi
F. Gan (SIMIT)
C. Sorace-Agaskar (MIT – LL)
A. Khilo (Boston University)
O. O. Olubuyide
M. Park
M. A. Popovic (Boston University)
M. Y. Sander (Boston University)

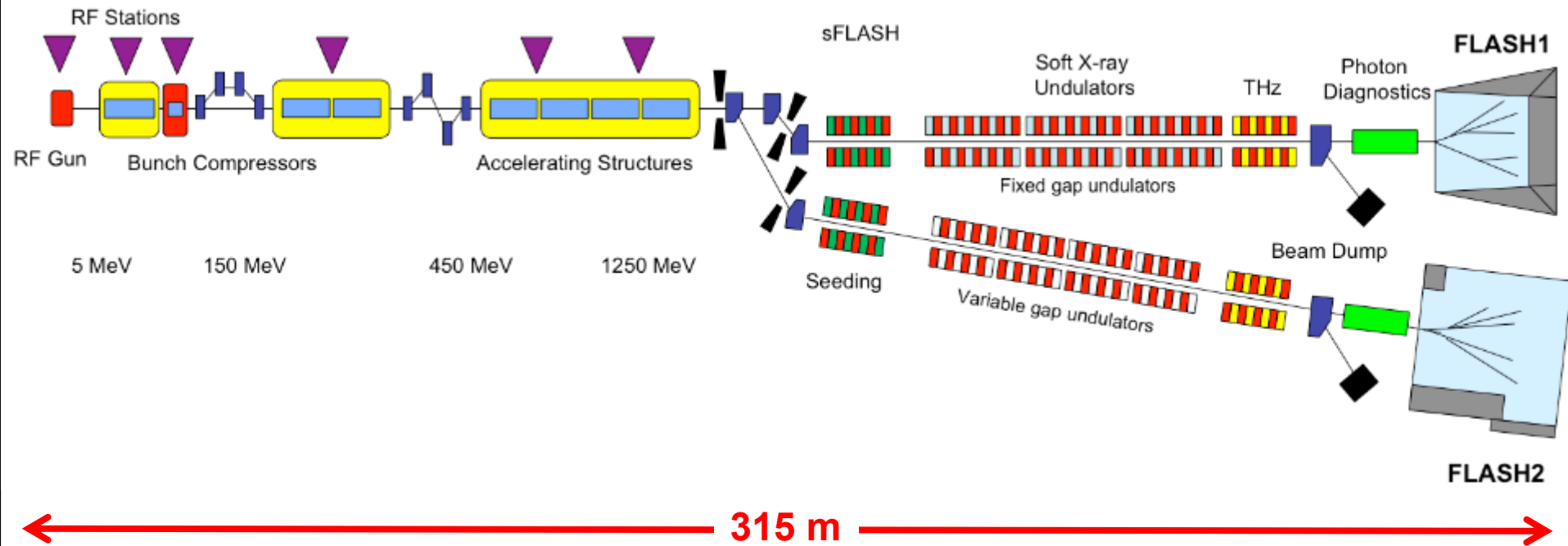
Collaborators:

MIT: E. Ippen, M. Watts, M. Perrott
MIT-LL: T. Lyszczarz, M. Geis,
M. Grein, S. Spector, J. Wang,
J. Yoon

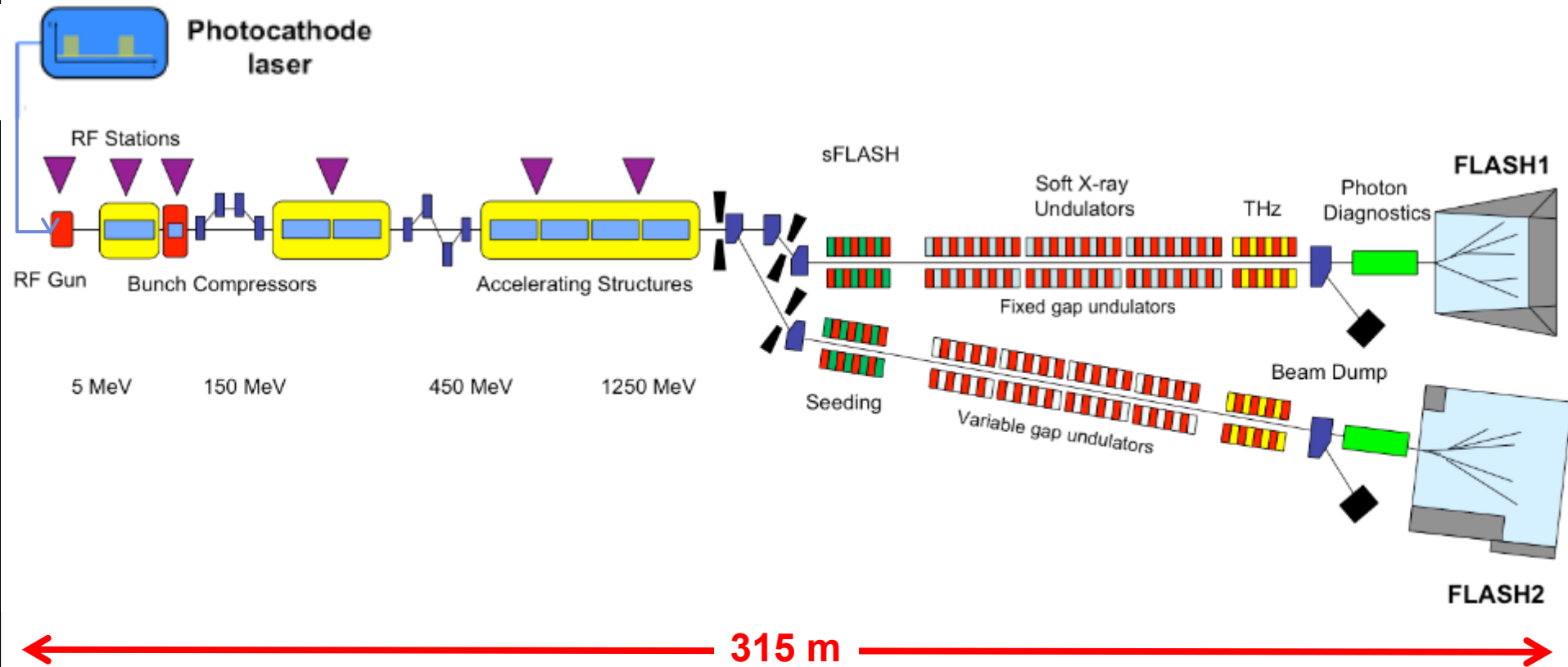
X-Ray FELs: Combined Accelerator and Laser Facilities



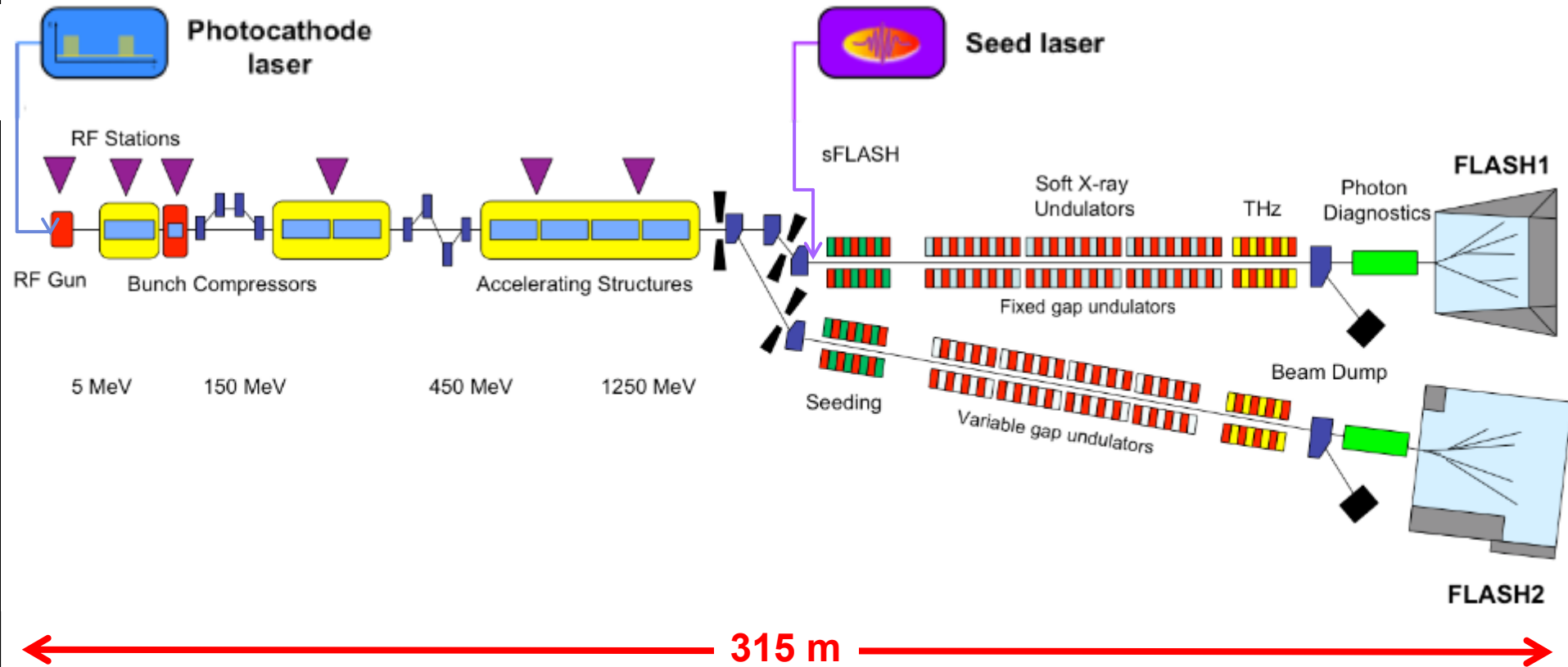
Lasers in FLASH



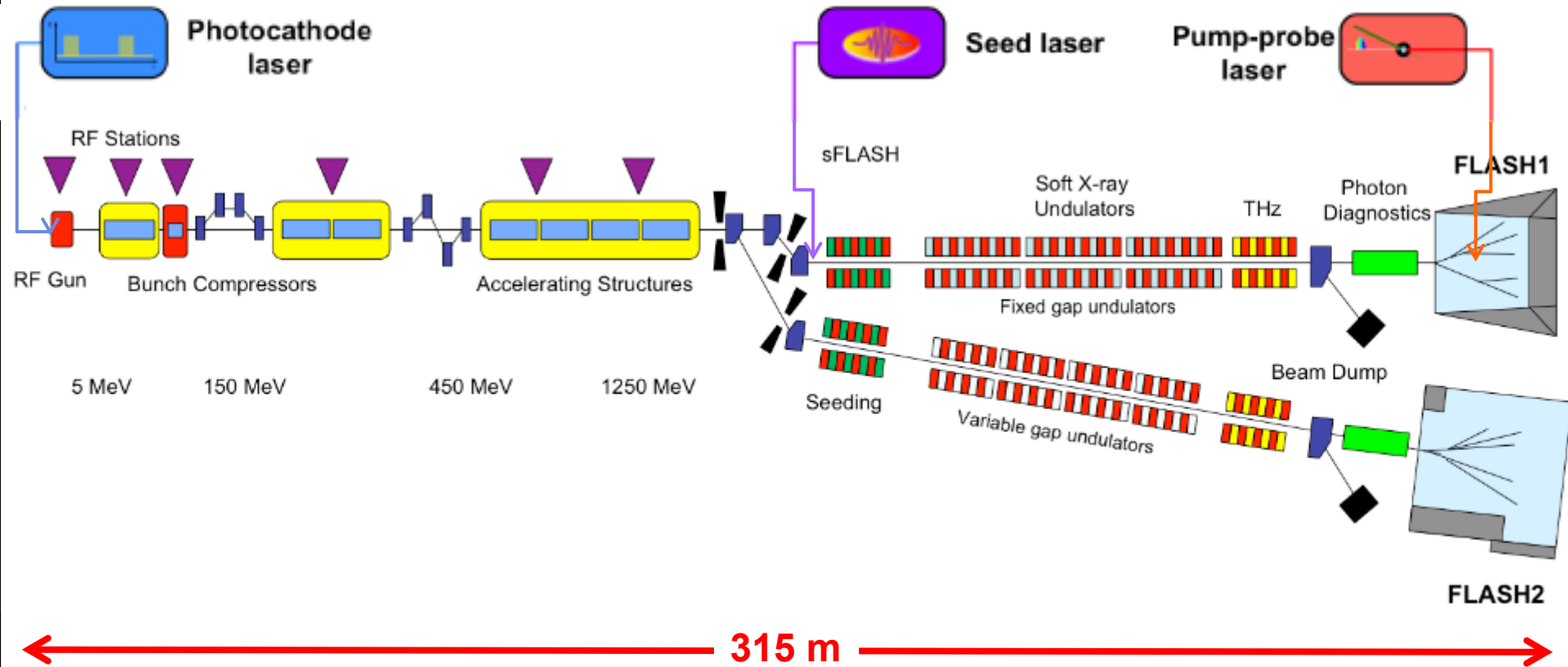
Lasers in FLASH



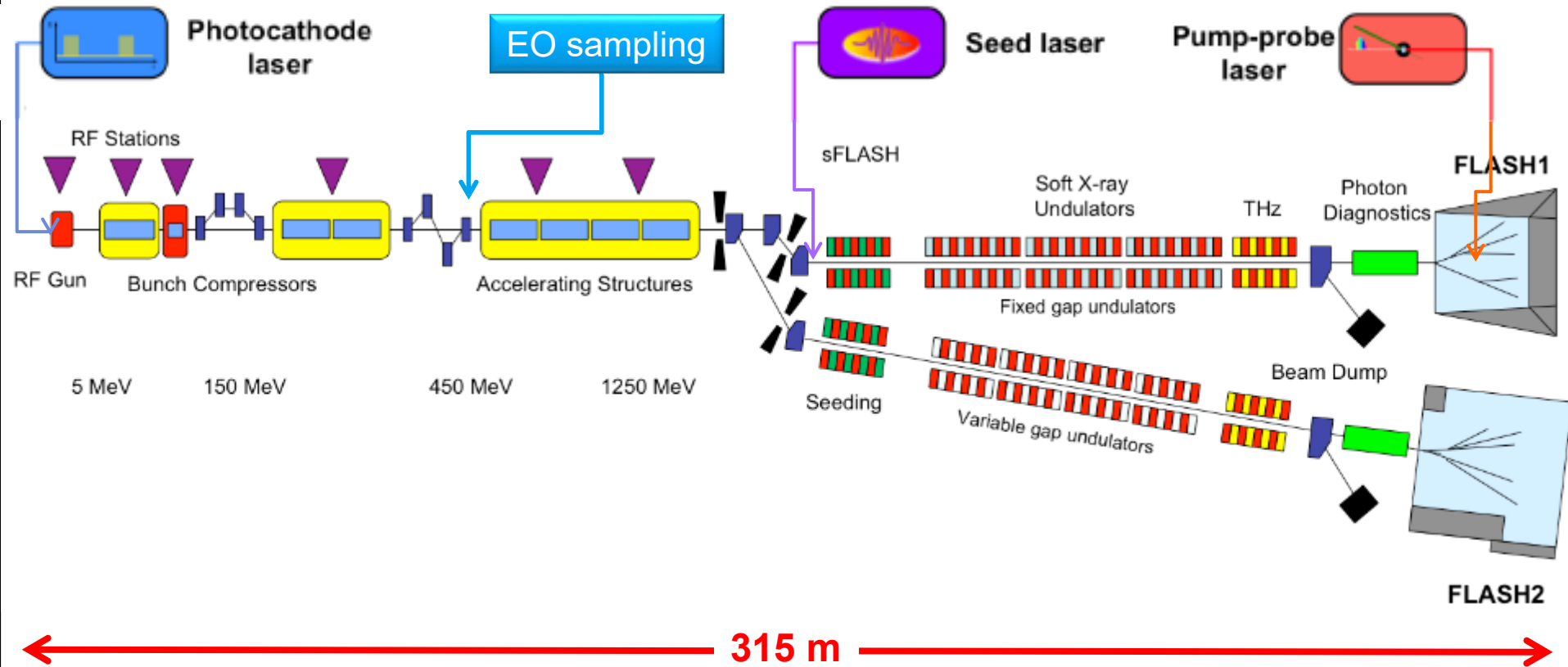
Lasers in FLASH



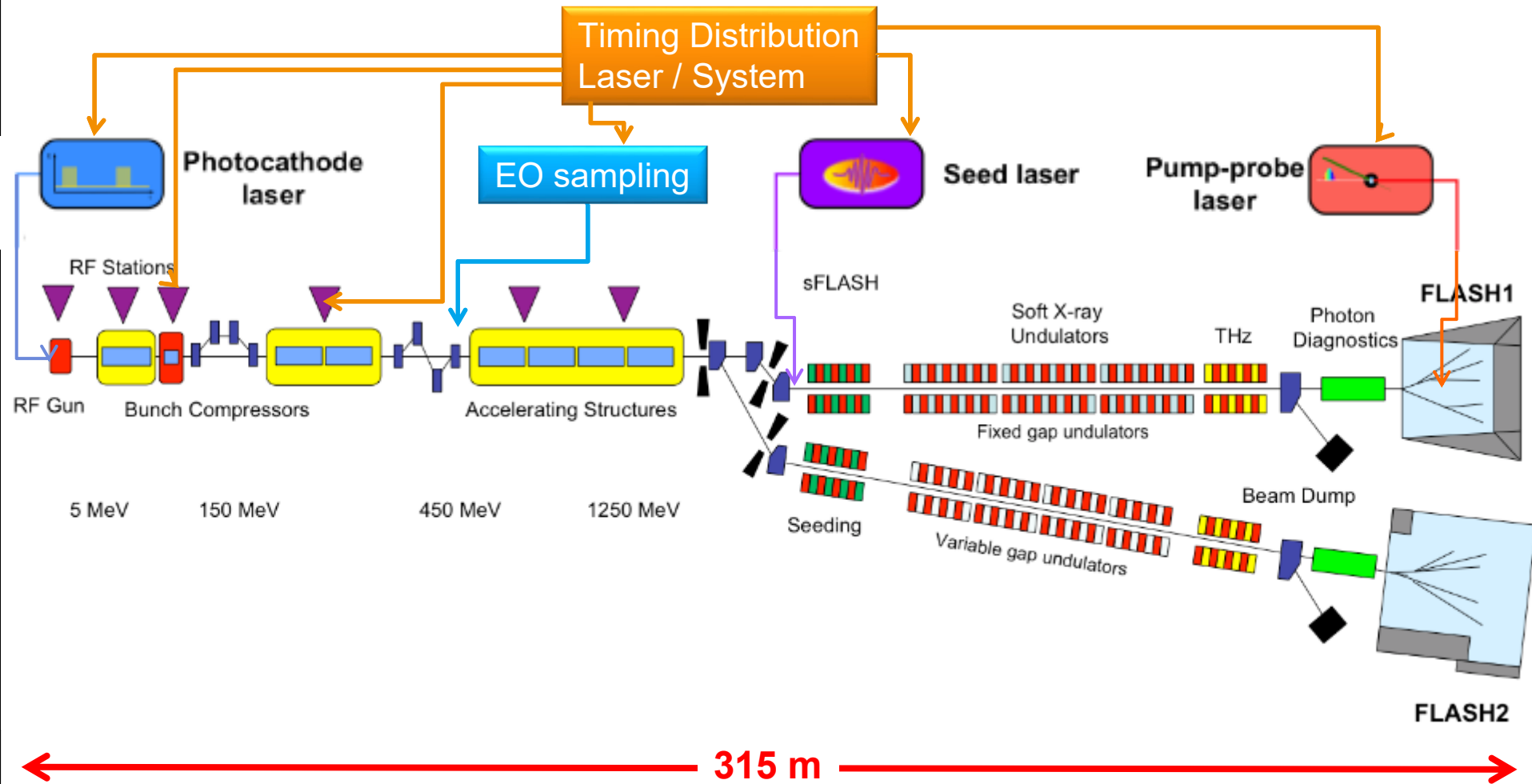
Lasers in FLASH



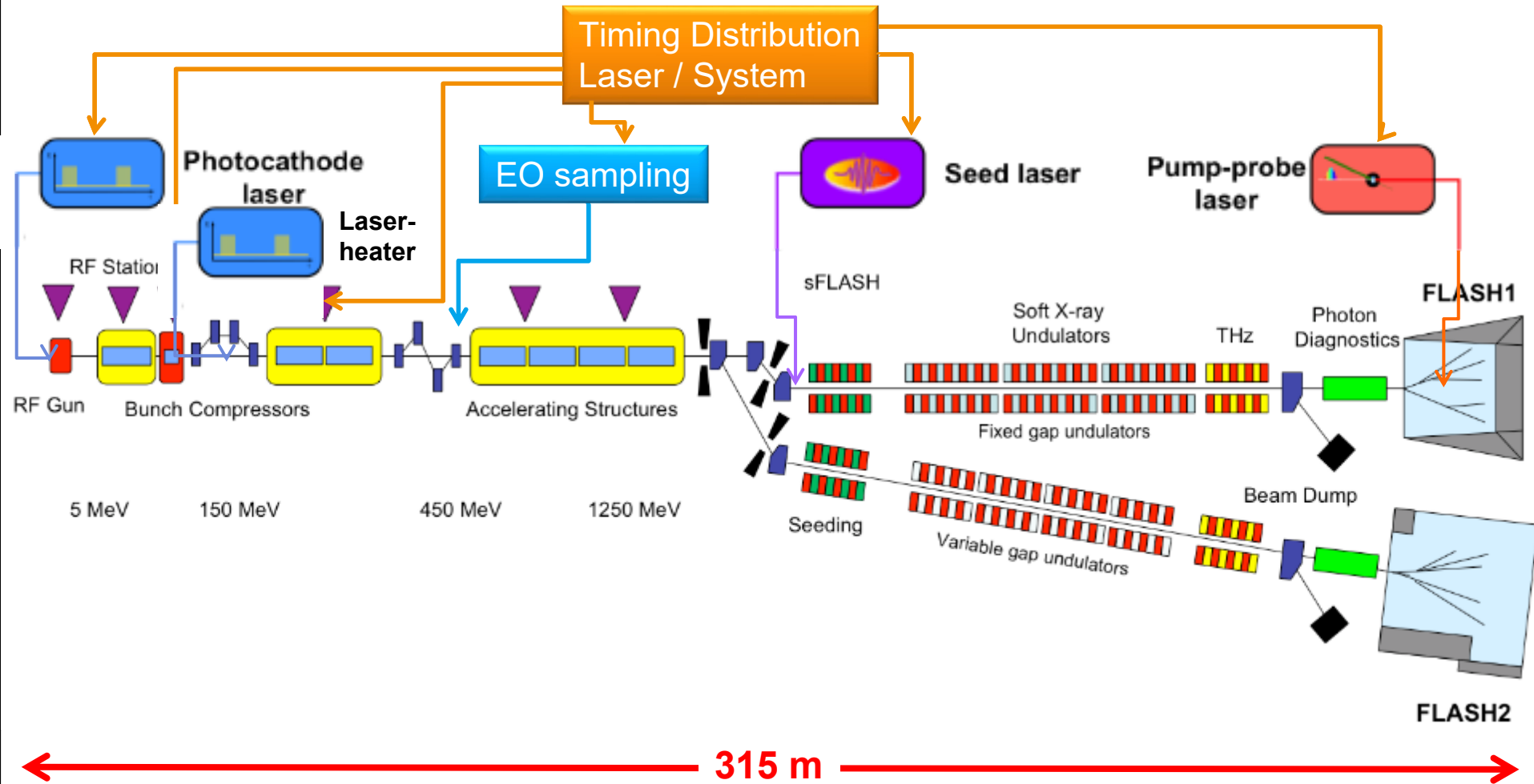
Lasers in FLASH



Lasers in FLASH

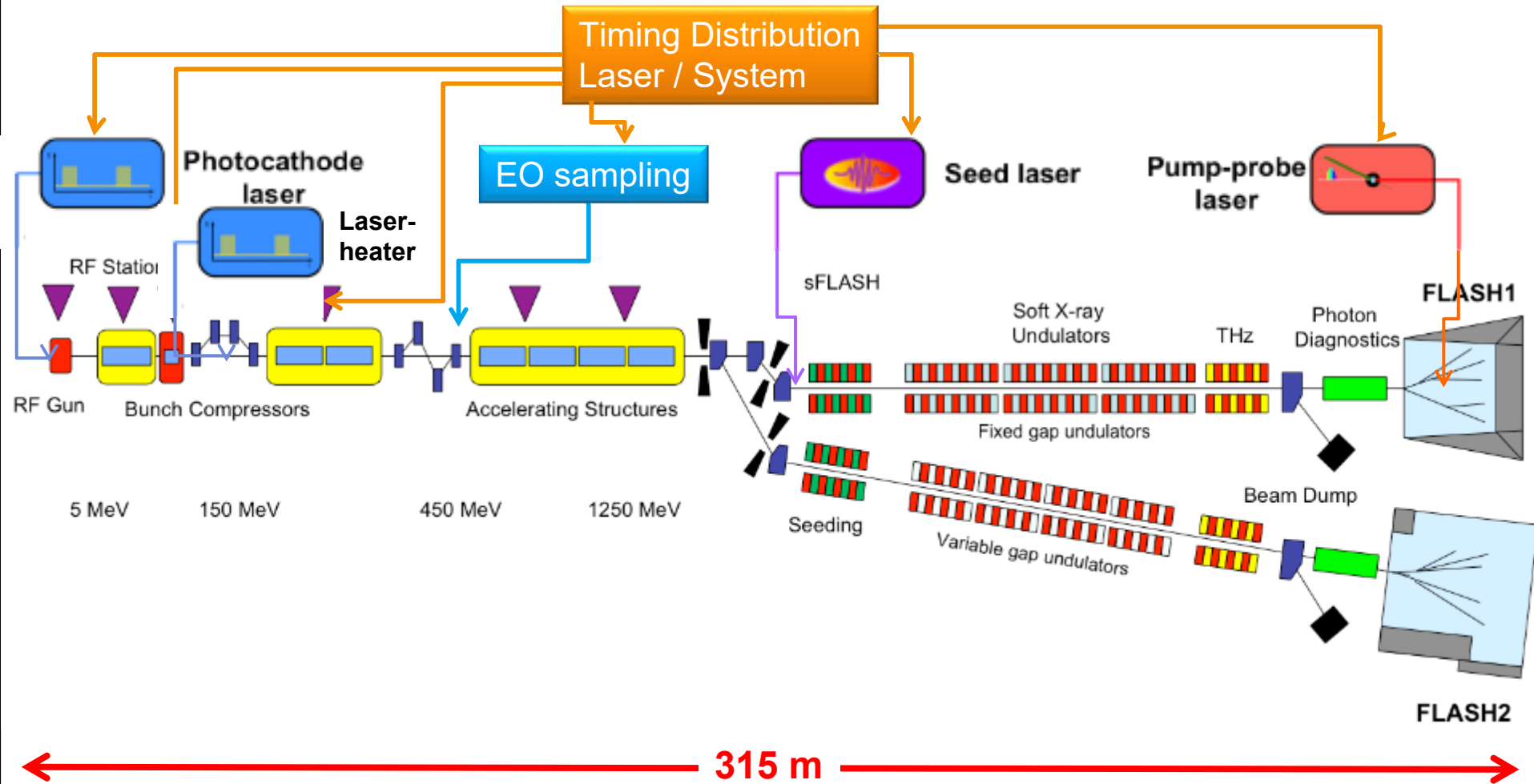


Lasers in FLASH

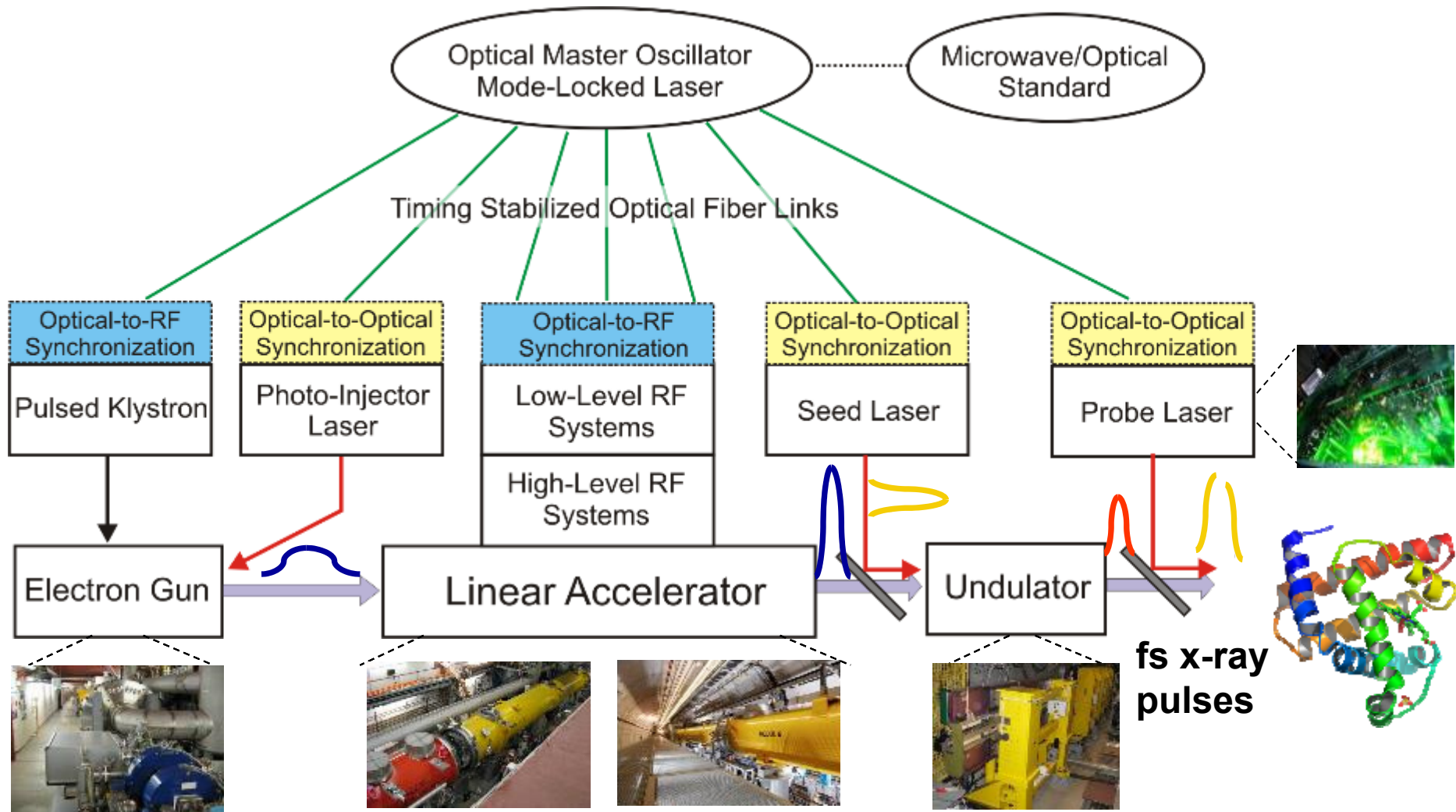


Lasers in FLASH

Ultralow loss femtosecond laser



Pulsed femtosecond timing distribution

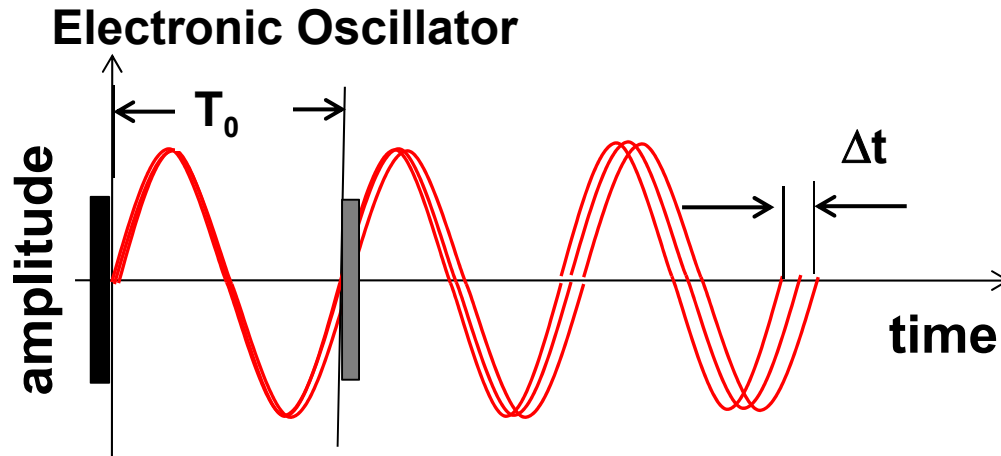


What more can optics, especially integrated optics, do for diagnostics and control?

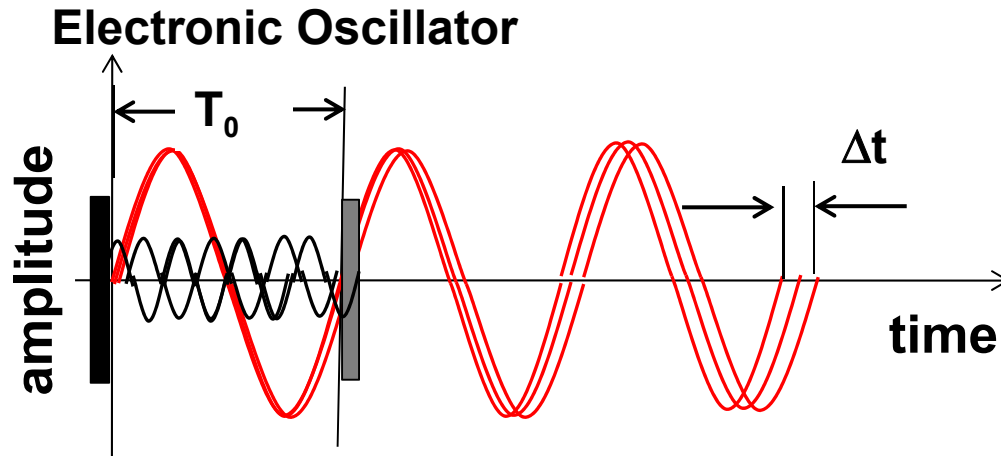
Outline

- **Ultralow Noise Properties of Femtosecond Lasers**
 - Inherently lower timing jitter than microwave sources
 - Short pulses, large bandwidth → sharp markers in time
 - (fs, as)
- **Integrated cross-correlators for improved timing**
- **Analog to Digital Conversion (ADCs)**
 - Potential for $> 10^3$ improvement in Bandwidth x Resolution
 - Silicon Photonics a path to broadband p-ADCs
 - Experimental results
 - Narrowband down-conversion for RF-phase measurement
- **MIT Silicon Photonics Platform (Prof. M. Watts)**
 - Modulators, Detectors, Filters, cw- and mode-locked Lasers

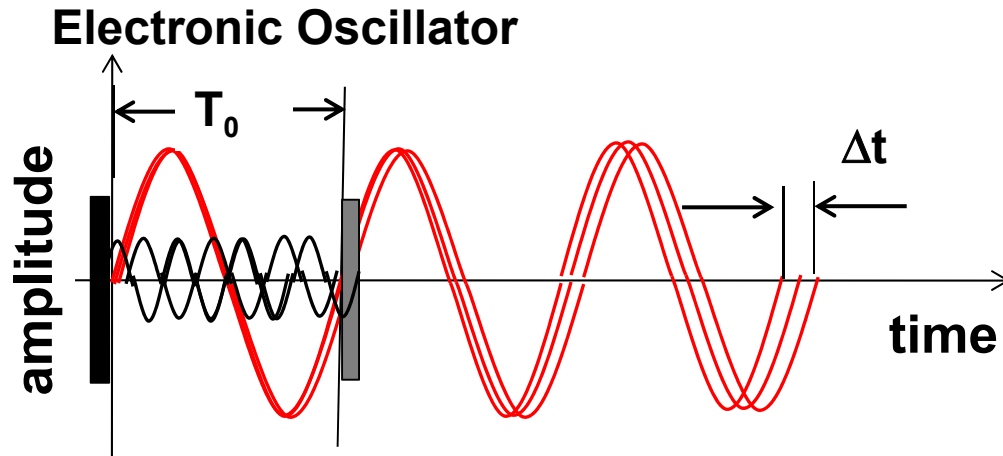
Timing Jitter of Femtosecond Lasers



Timing Jitter of Femtosecond Lasers



Timing Jitter of Femtosecond Lasers



Dissipation-Fluctuation Theorem

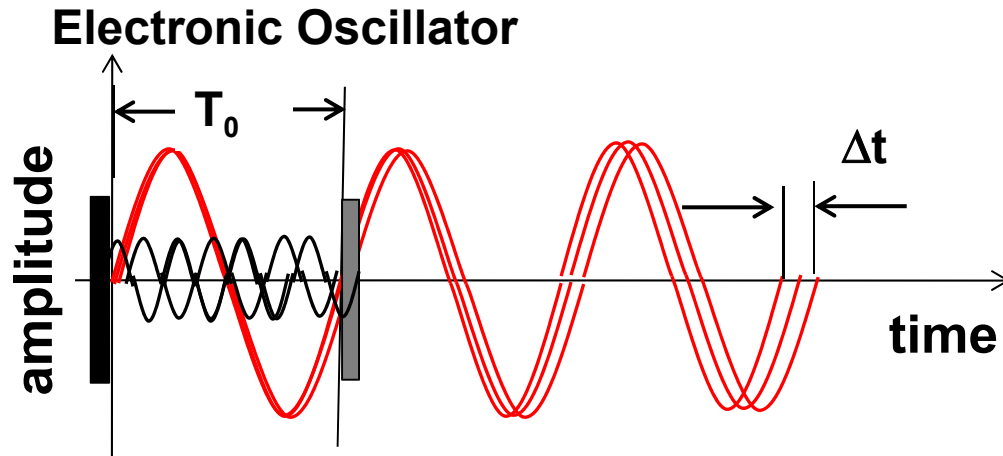
$$\frac{d}{dt} \langle \Delta t_{RF}^2 \rangle \approx T_0^2 \cdot \frac{1}{W_{mode}} \cdot \frac{kT}{\tau_{cav}}$$

↑
↑

period
~100ps
cavity
lifetime

kT = thermal energy

Timing Jitter of Femtosecond Lasers



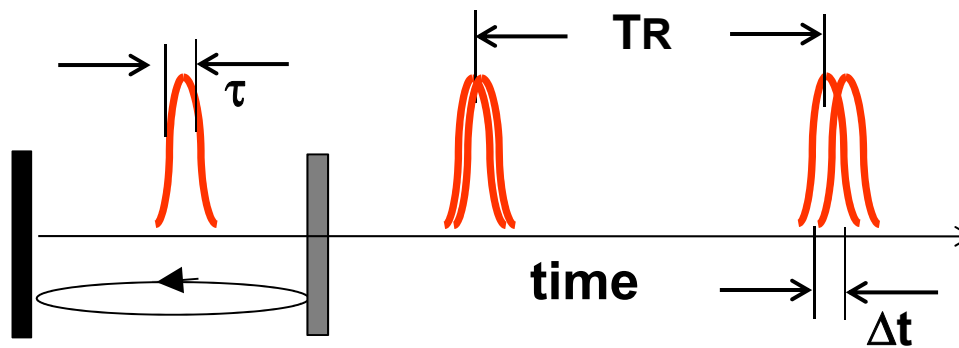
Dissipation-Fluctuation Theorem

$$\frac{d}{dt} \langle \Delta t_{RF}^2 \rangle \approx T_0^2 \cdot \frac{1}{W_{mode}} \cdot \frac{kT}{\tau_{cav}}$$

period
~100ps

cavity
lifetime

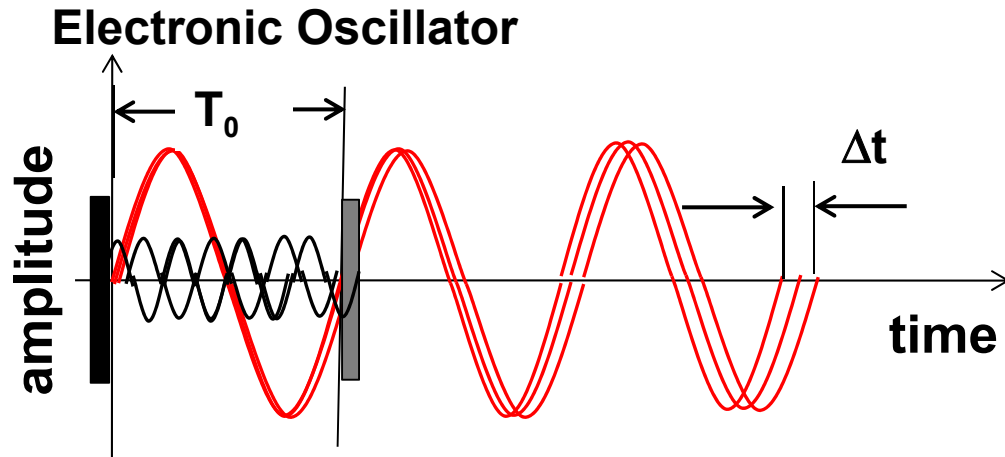
Femtosecond Laser



Optical Cavity

kT = thermal energy

Timing Jitter of Femtosecond Lasers



Dissipation-Fluctuation Theorem

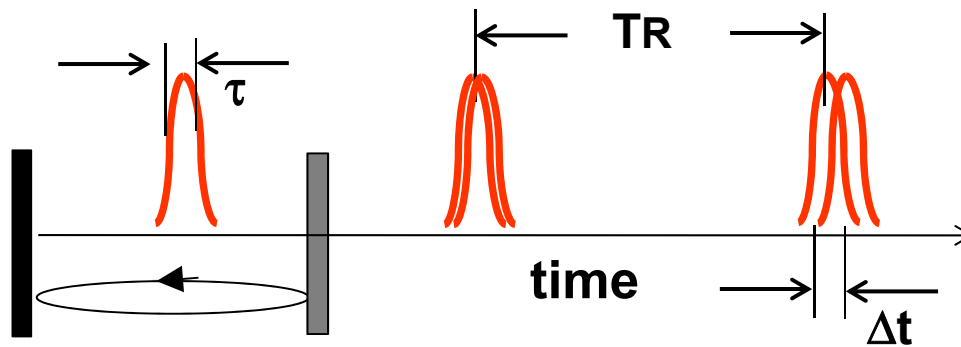
$$\frac{d}{dt} \langle \Delta t_{RF}^2 \rangle \approx T_0^2 \cdot \frac{1}{W_{mode}} \cdot \frac{kT}{\tau_{cav}}$$

period
~100ps

cavity
lifetime

10^{-6}

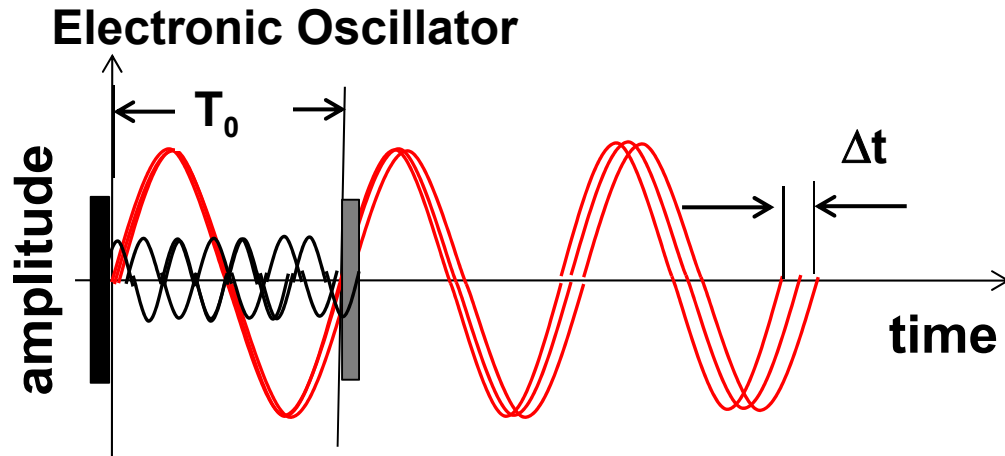
Femtosecond Laser



Optical Cavity

$kT = \text{thermal energy}$

Timing Jitter of Femtosecond Lasers



Dissipation-Fluctuation Theorem

$$\frac{d}{dt} \langle \Delta t_{RF}^2 \rangle \approx T_0^2 \cdot \frac{1}{W_{mode}} \cdot \frac{kT}{\tau_{cav}}$$

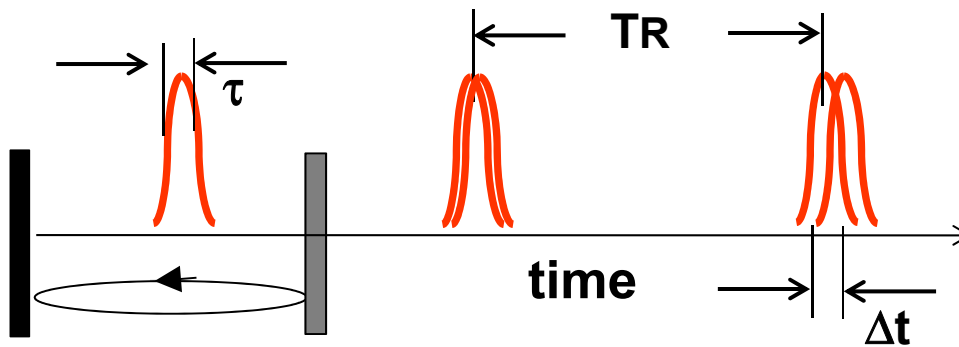
period
~100ps

cavity
lifetime

10⁻⁶ ←

pulse width
~100fs

Femtosecond Laser

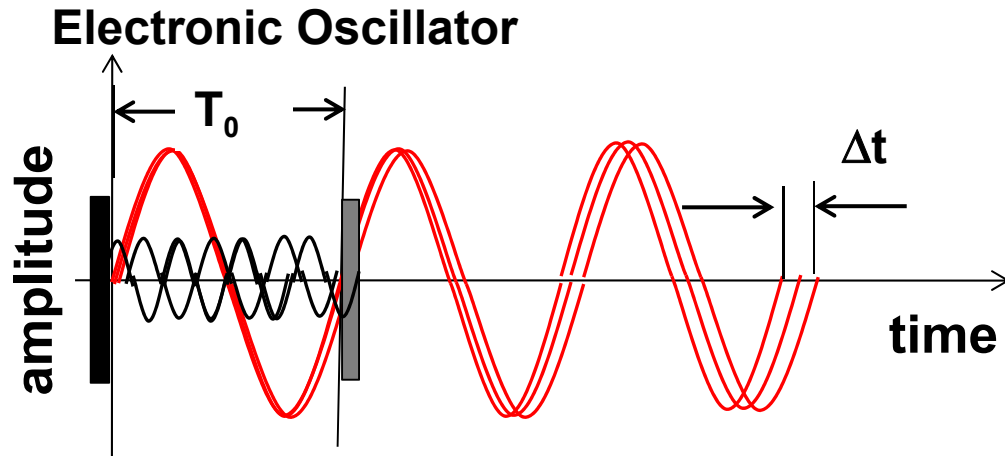


Optical Cavity

$$\frac{d}{dt} \langle \Delta t_{ML}^2 \rangle \approx \tau^2 \cdot \frac{1}{W_{pulse}} \cdot \frac{\hbar\omega_c}{\tau_{cav}}$$

→ $\hbar\omega_c \sim 50kT$
 kT = thermal energy
 $\hbar\omega_c$ = photon energy

Timing Jitter of Femtosecond Lasers



Dissipation-Fluctuation Theorem

$$\frac{d}{dt} \langle \Delta t_{RF}^2 \rangle \approx T_0^2 \cdot \frac{1}{W_{mode}} \cdot \frac{kT}{\tau_{cav}}$$

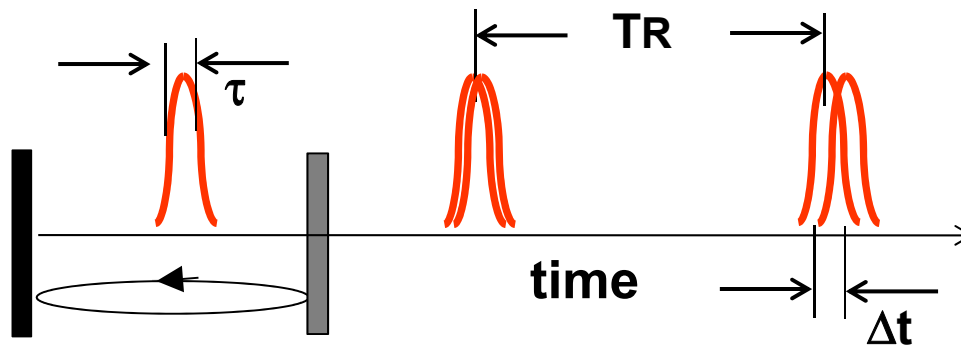
period
~100ps

cavity
lifetime

10^{-6}

pulse width
~100fs

Femtosecond Laser



$$\frac{d}{dt} \langle \Delta t_{ML}^2 \rangle \approx \tau^2 \cdot \frac{1}{W_{pulse}} \cdot \frac{\hbar\omega_c}{\tau_{cav}}$$

Optical Cavity

10^{-4}

$\hbar\omega_c \sim 50kT$
 kT = thermal energy
 $\hbar\omega_c$ = photon energy

Timing, Synchronization and Sampling

Femtosecond lasers are very low jitter:

- High intracavity pulse energy
 - High Q Cavity
 - 10 - 100 fs pulses, good time markers (e.g. EOS)
- sub-femtosecond jitter for $f > 1\text{kHz}$

Balanced optical cross correlation:

- High timing sensitivity (zeptoseconds)
 - low drift (only dielectrics involved)
 - attosecond laser to laser locks
- attosecond laser-to-laser locks and fiber links

Balanced optical microwave phase detection:

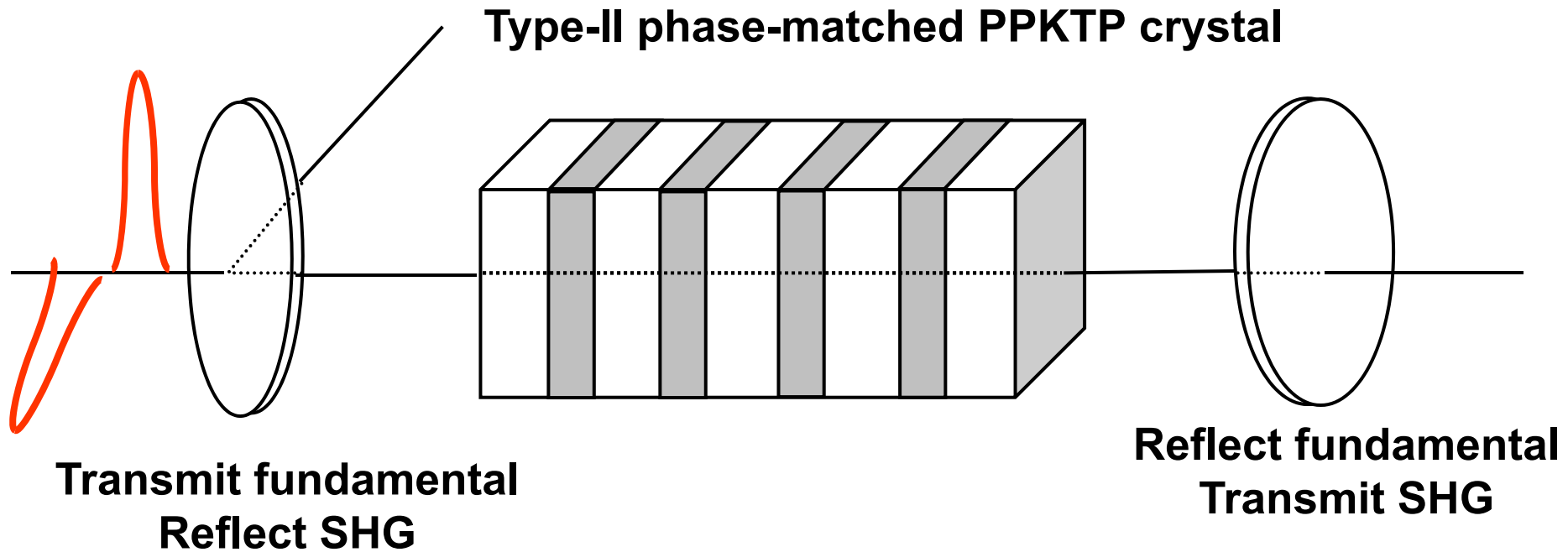
- sub-femtosecond jitter microwaves

How Do We Measure Low Jitter?

**Sensitive Time Delay Measurements
by
Balanced Optical Cross Correlation**

Single-crystal balanced cross-correlator

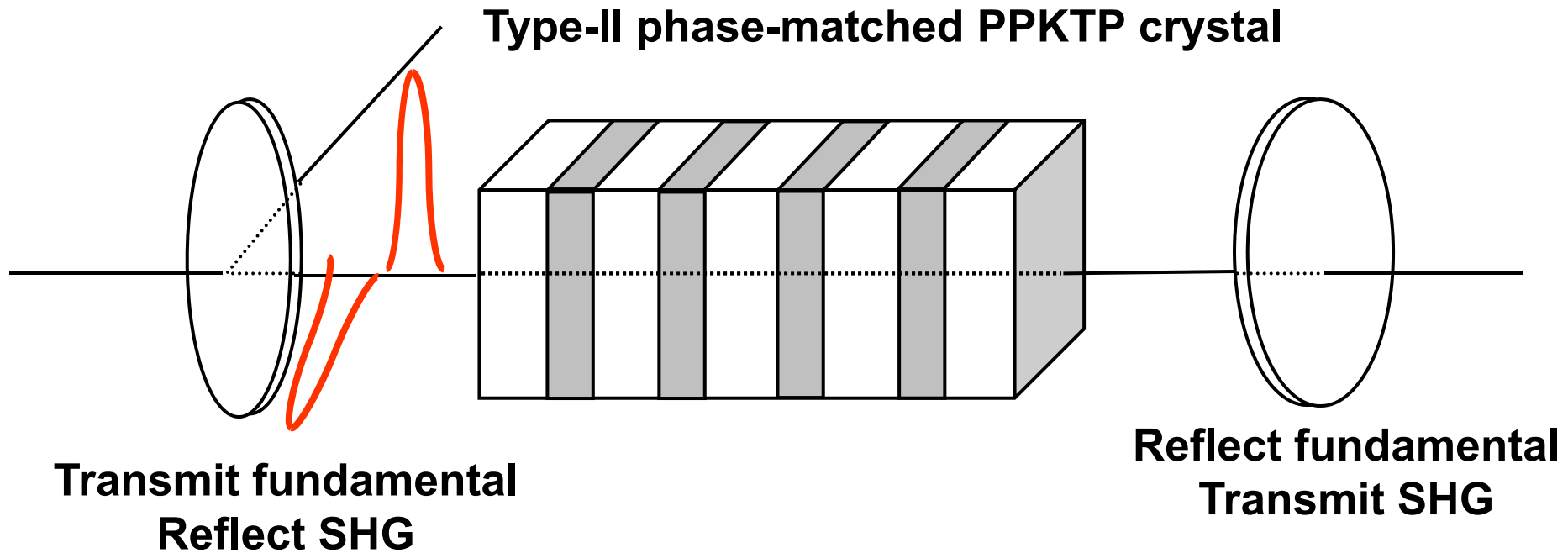
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

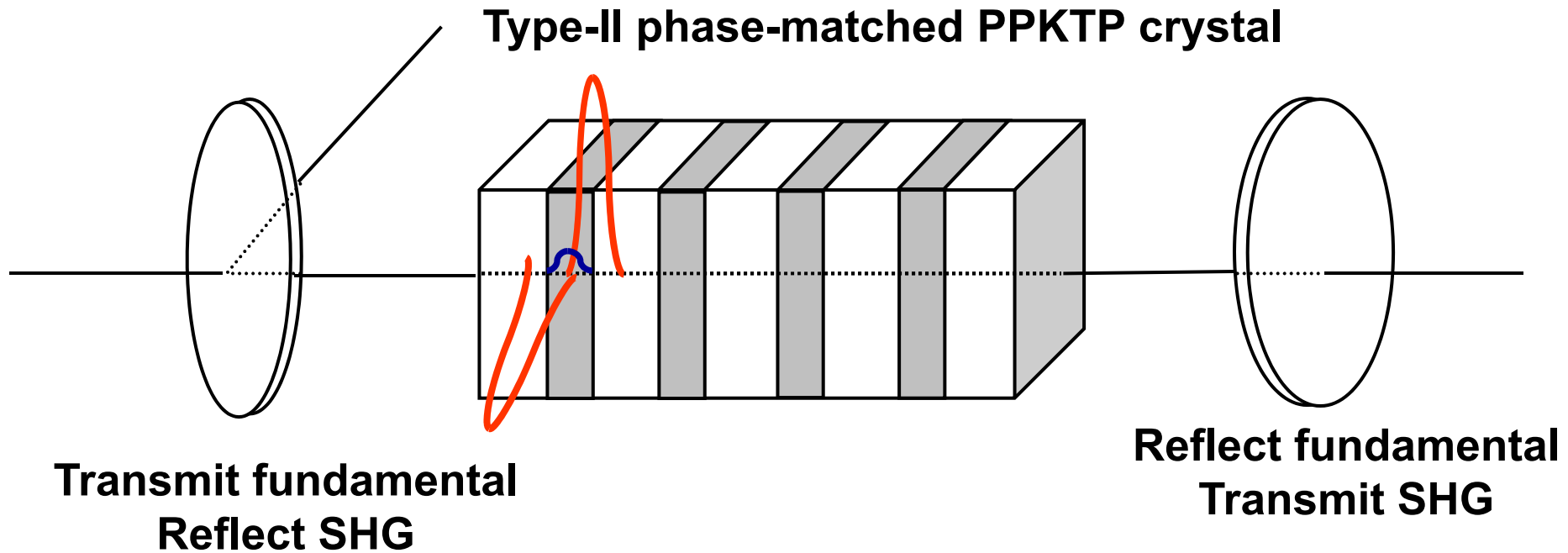
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

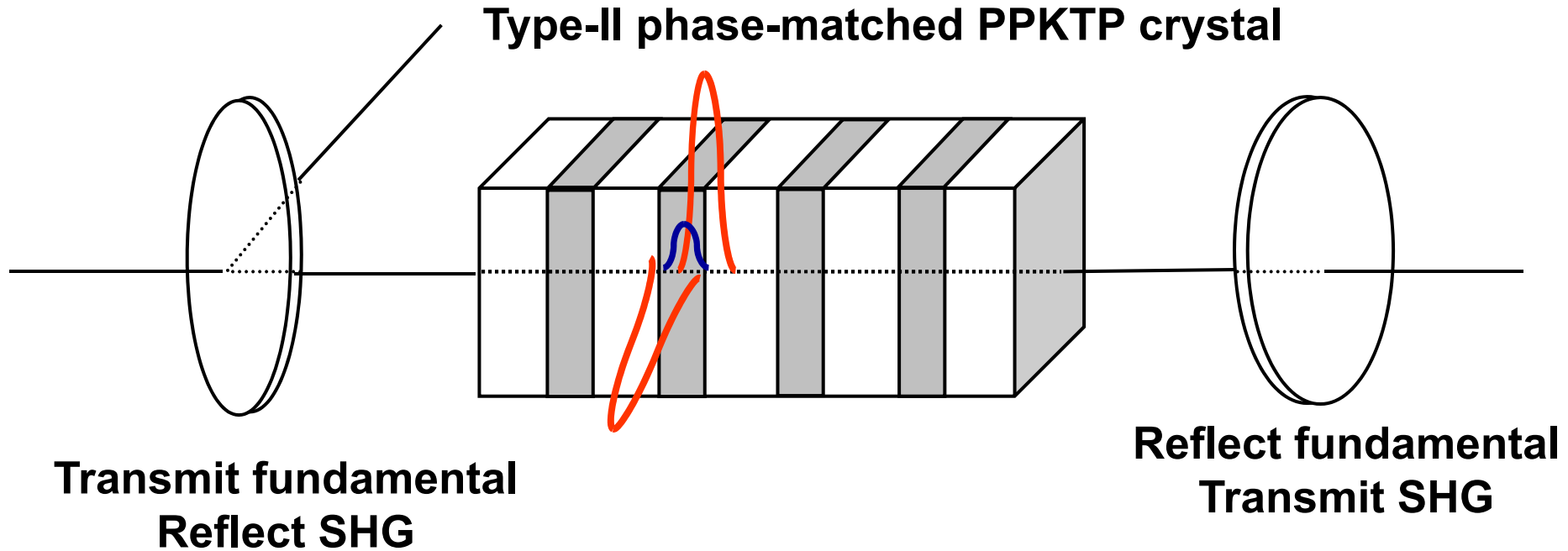
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

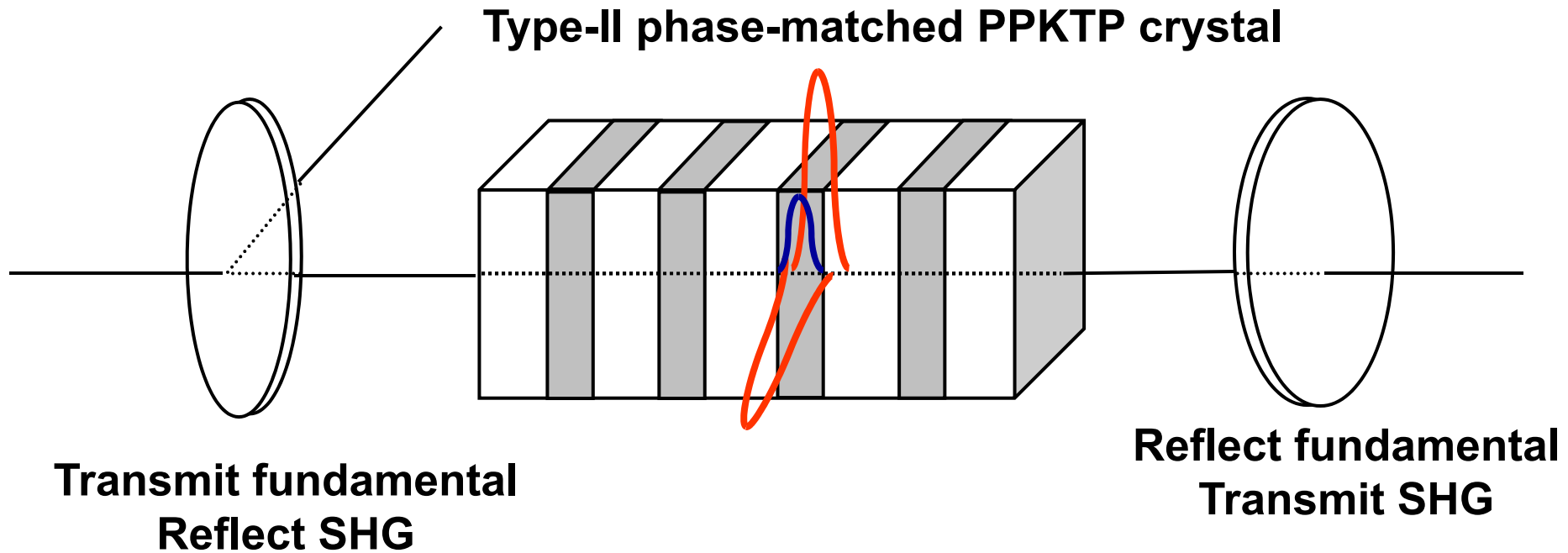
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

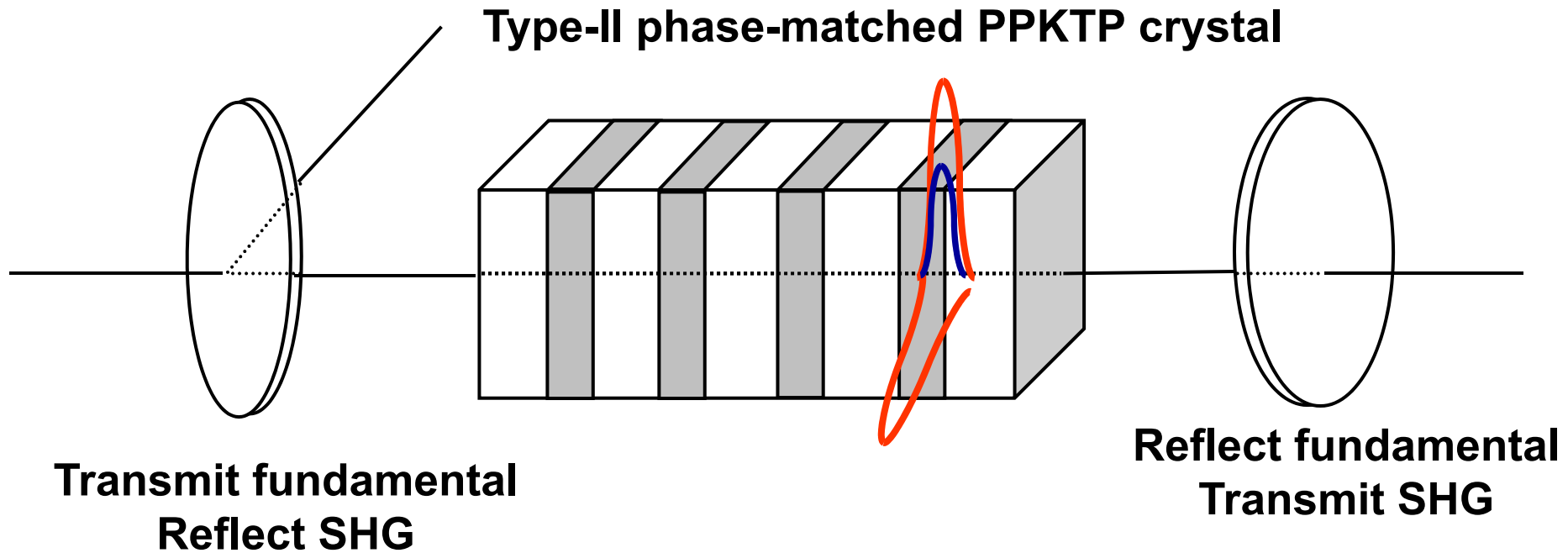
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

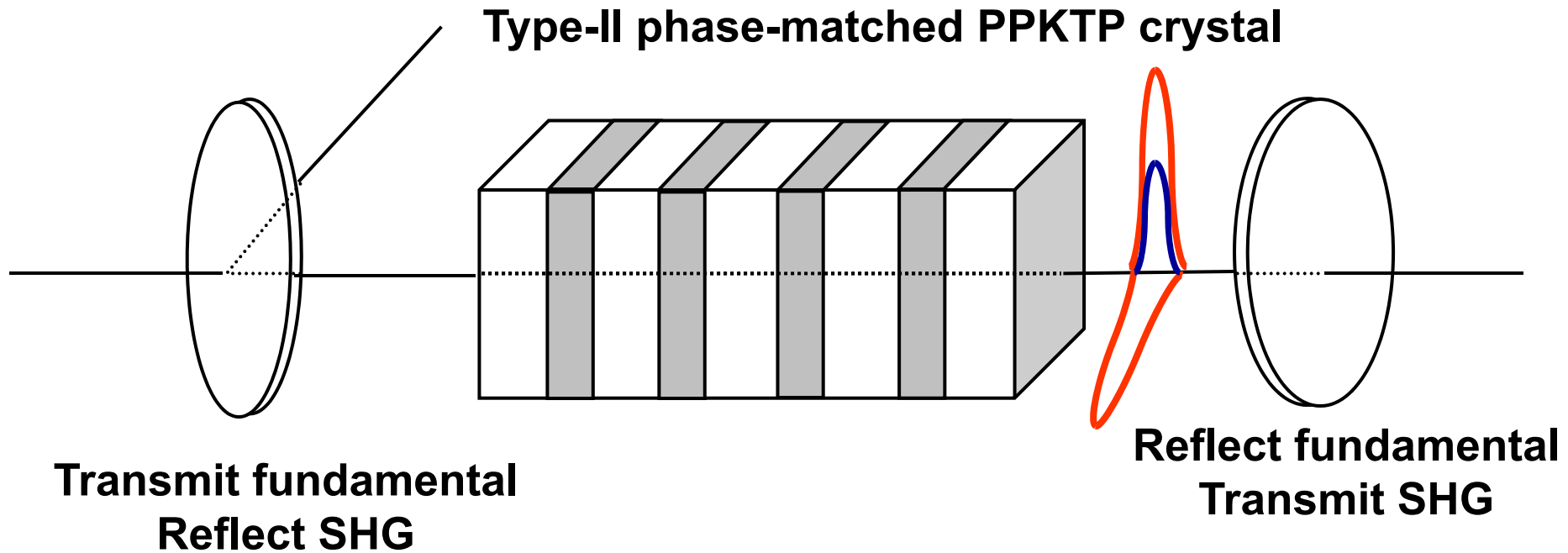
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

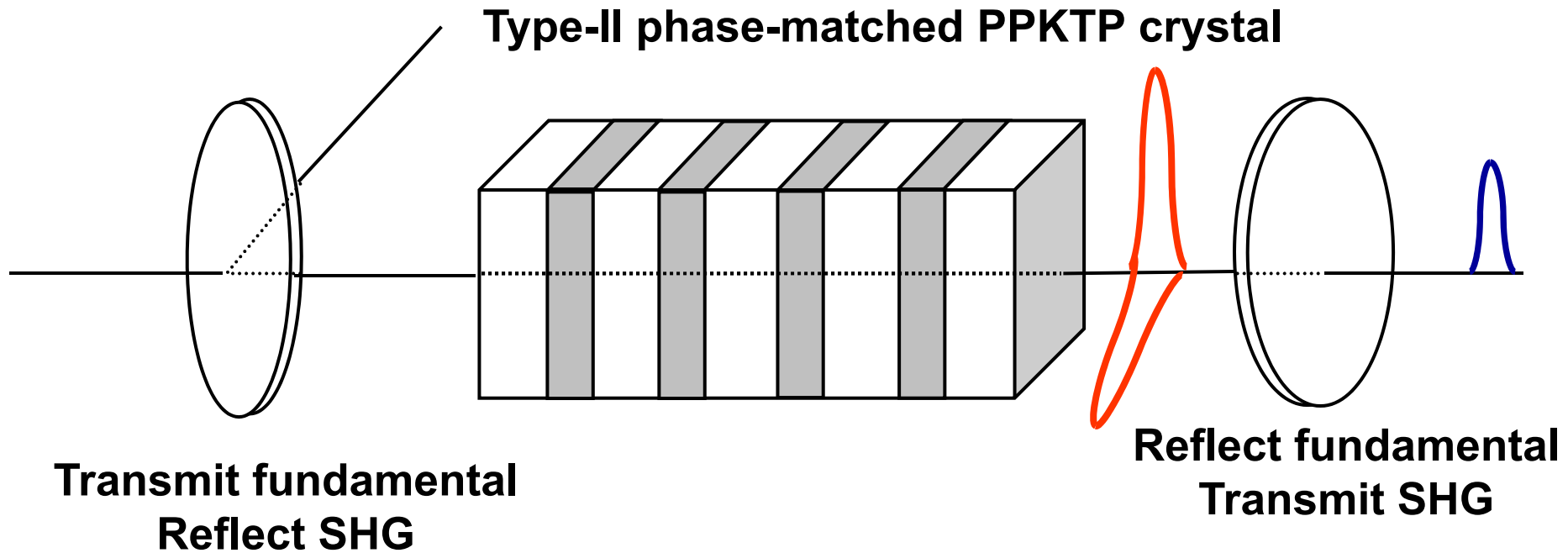
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

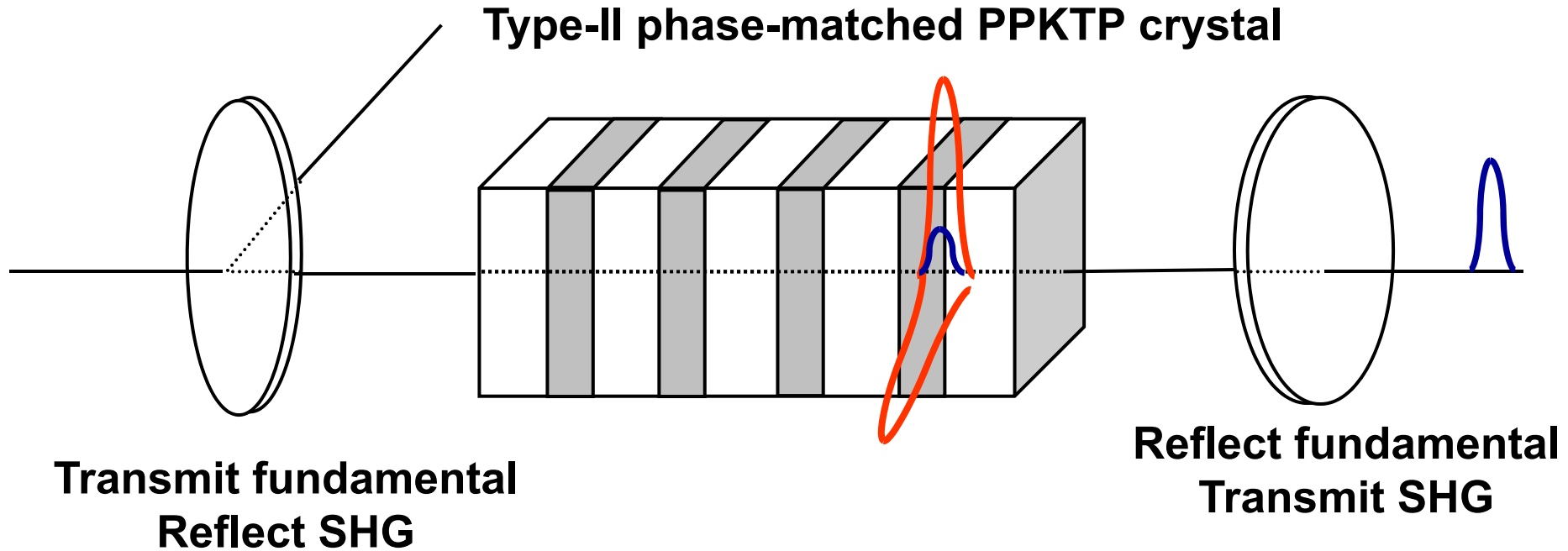
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

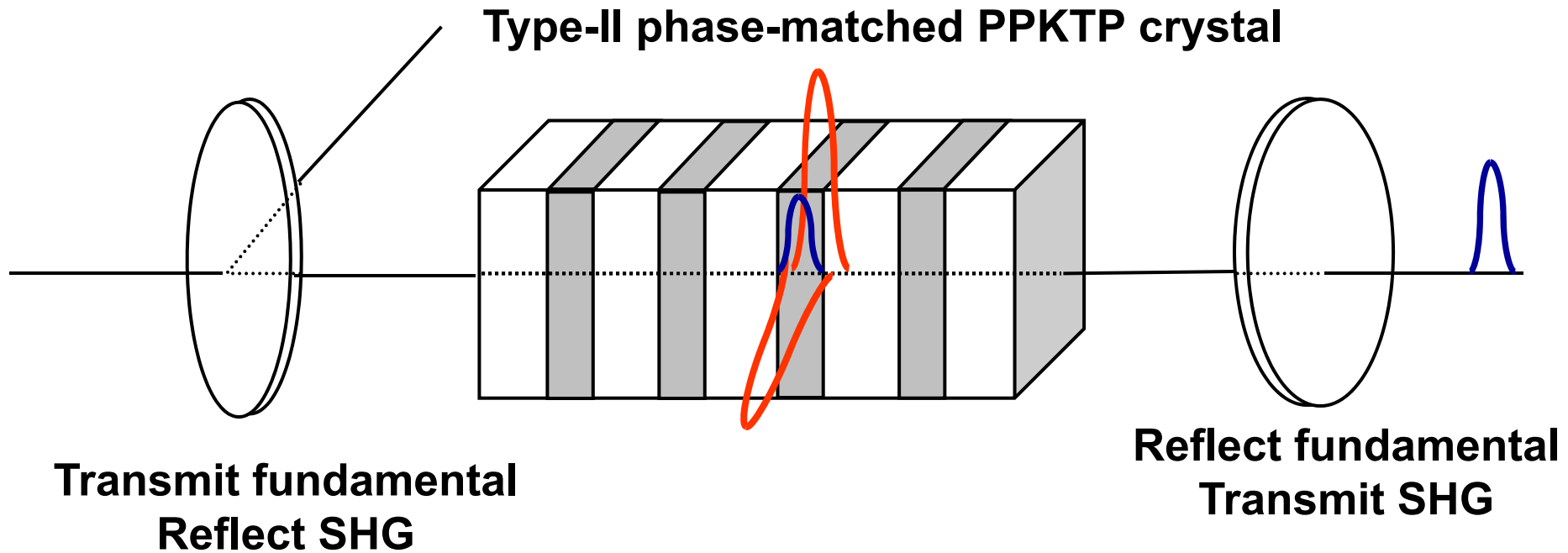
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

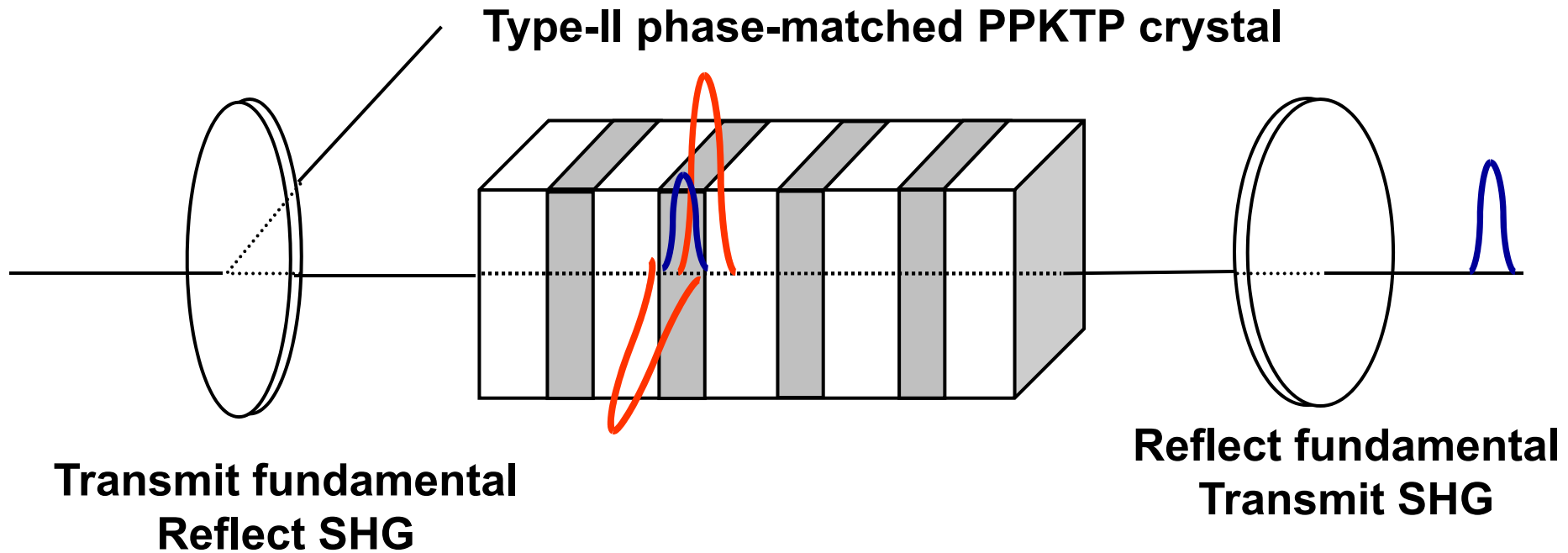
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

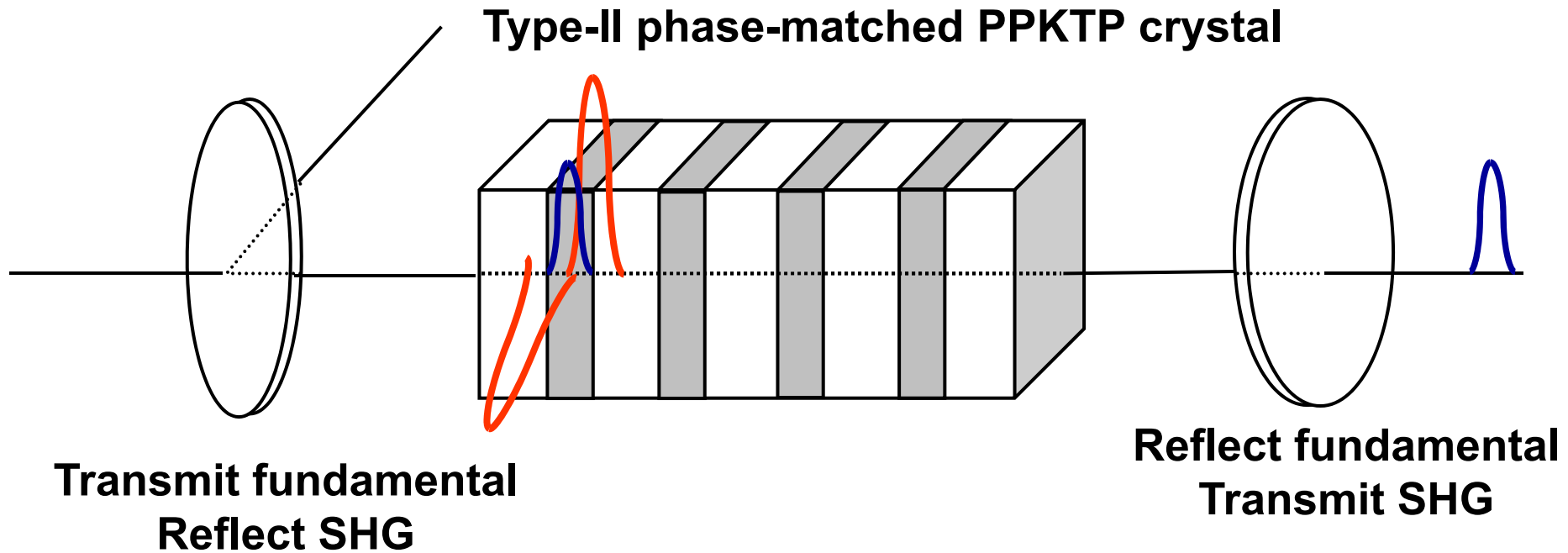
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

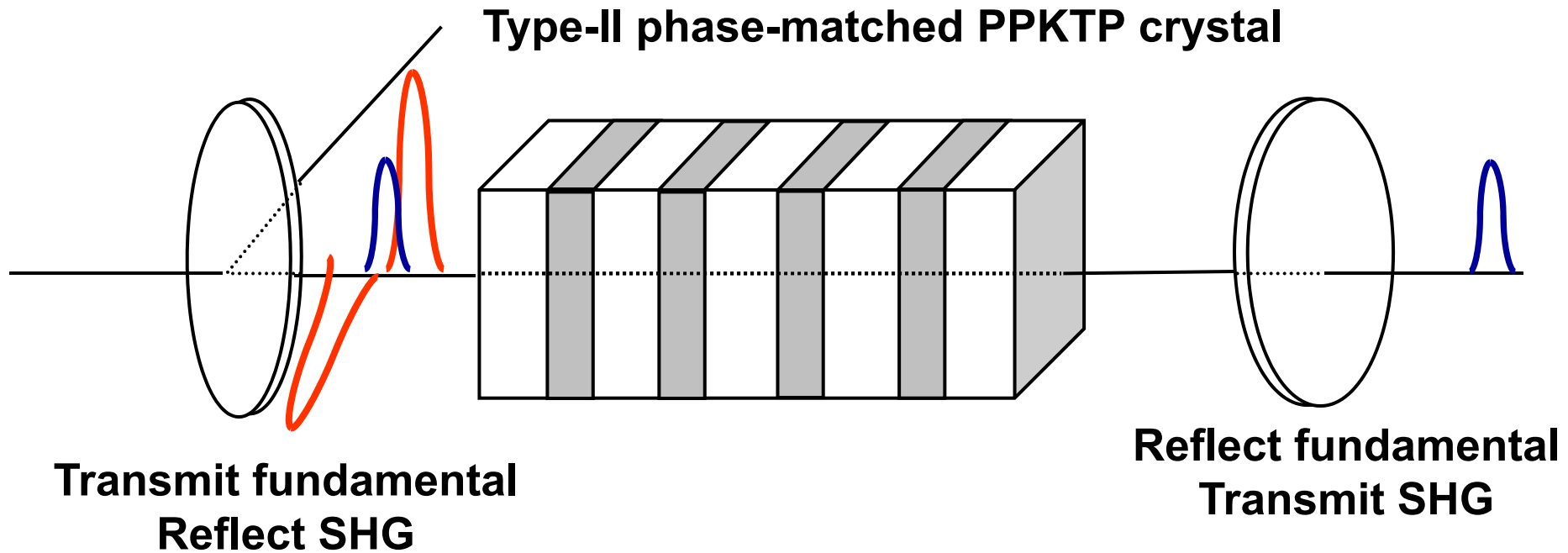
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

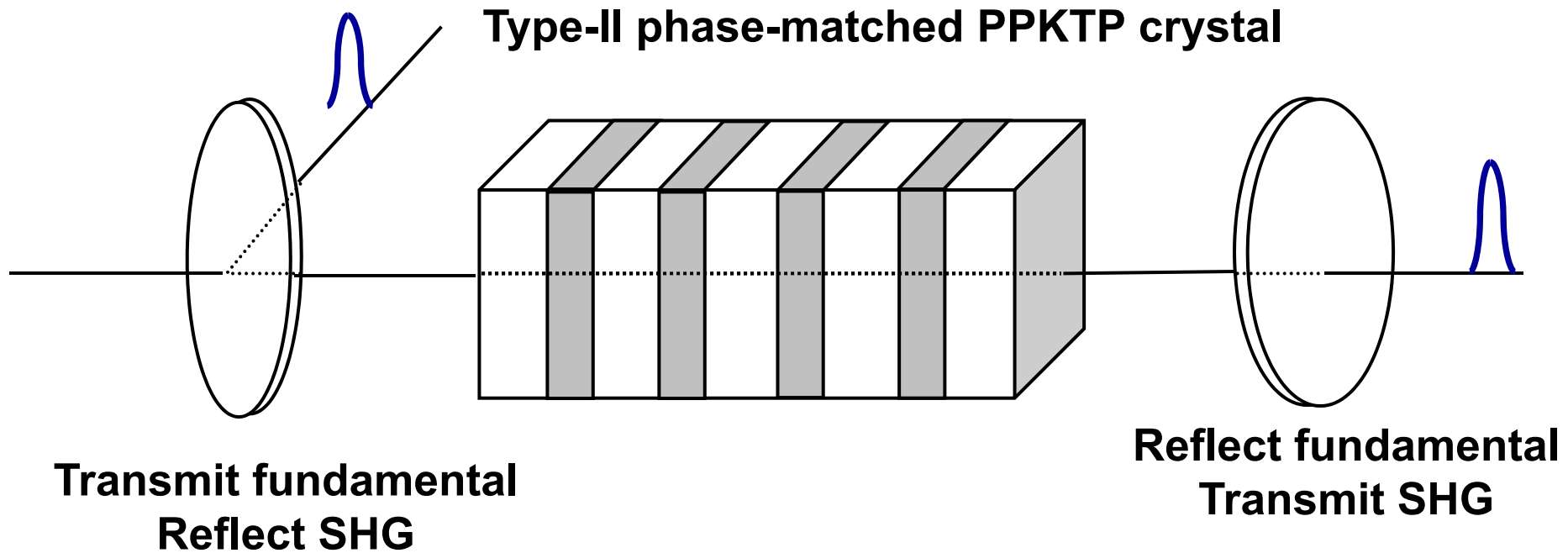
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

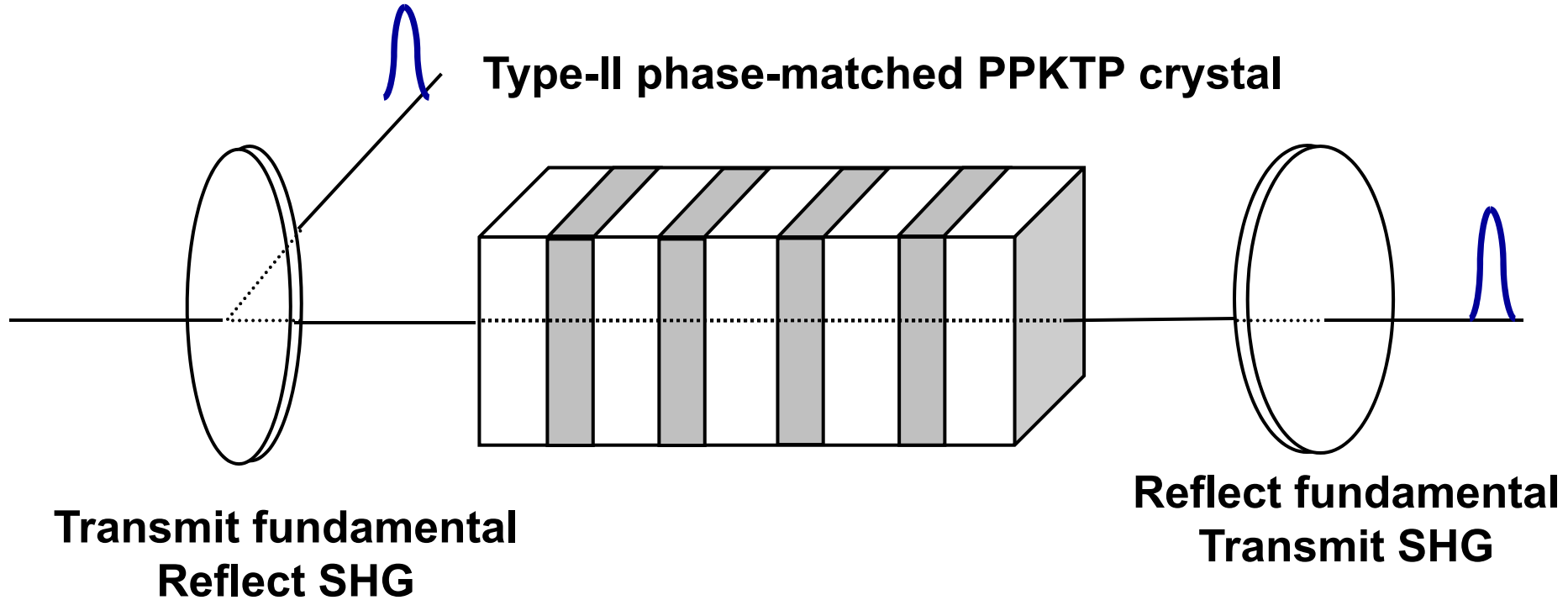
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

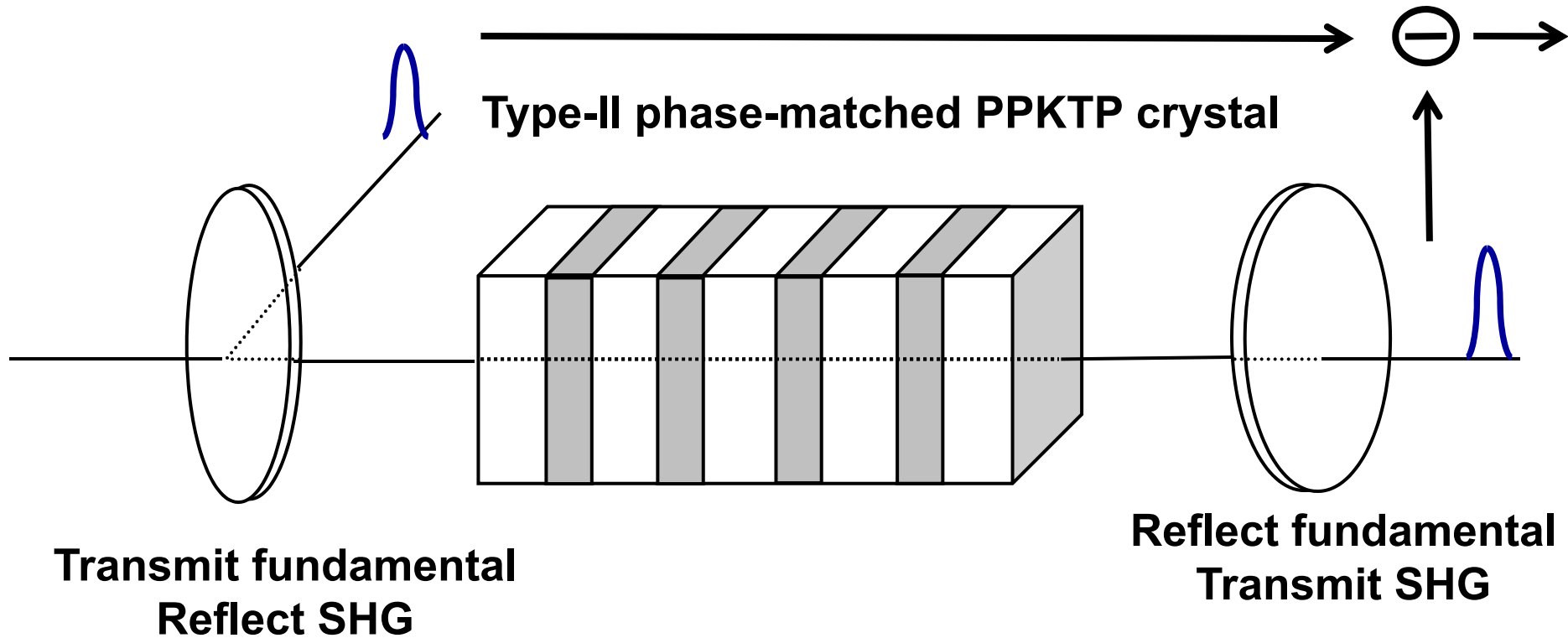
T. Schibli et al, OL 28, 947 (2003)



J. Kim et al., Opt. Lett. 32, 1044 (2007)

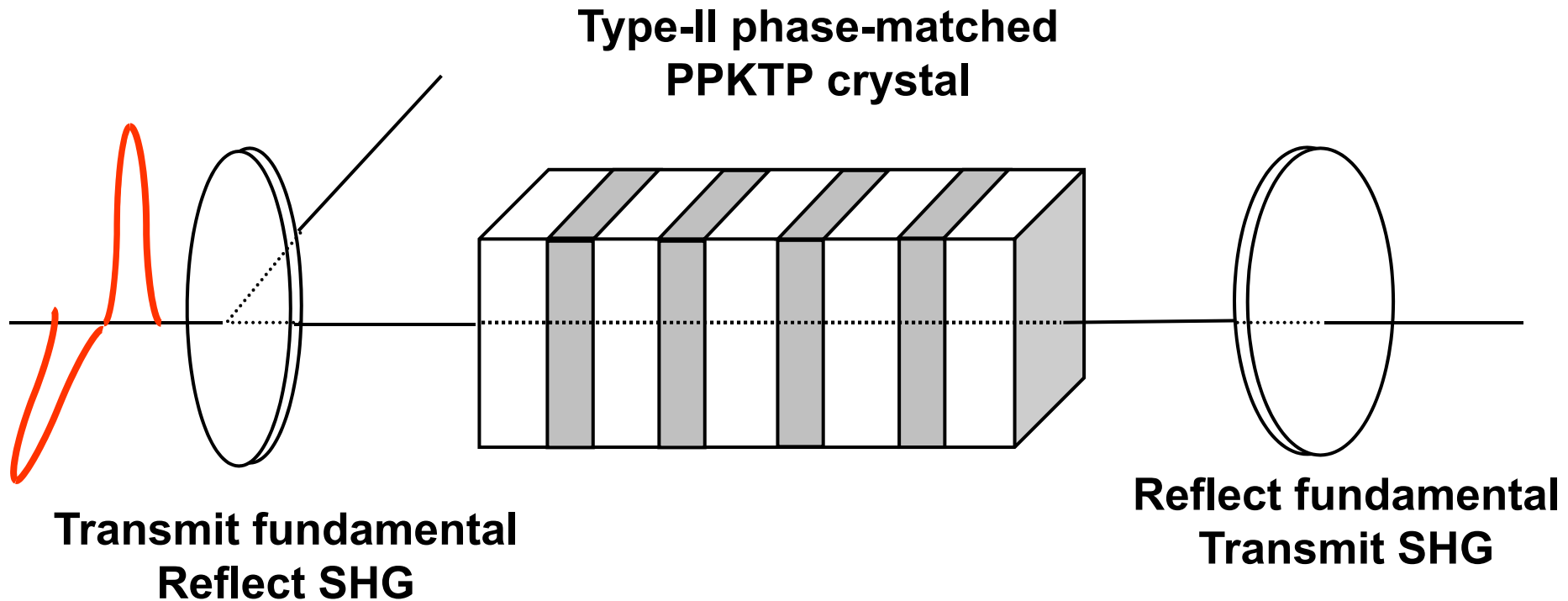
Single-crystal balanced cross-correlator

T. Schibli et al, OL 28, 947 (2003)



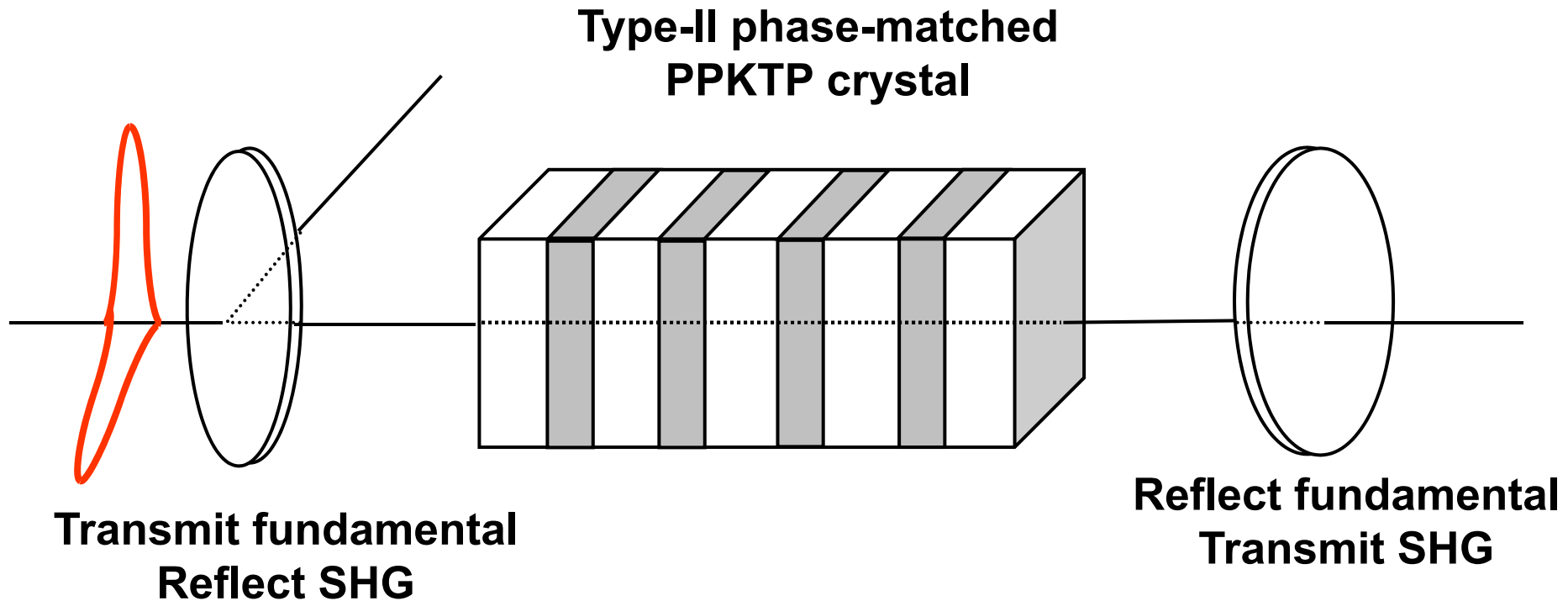
J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator



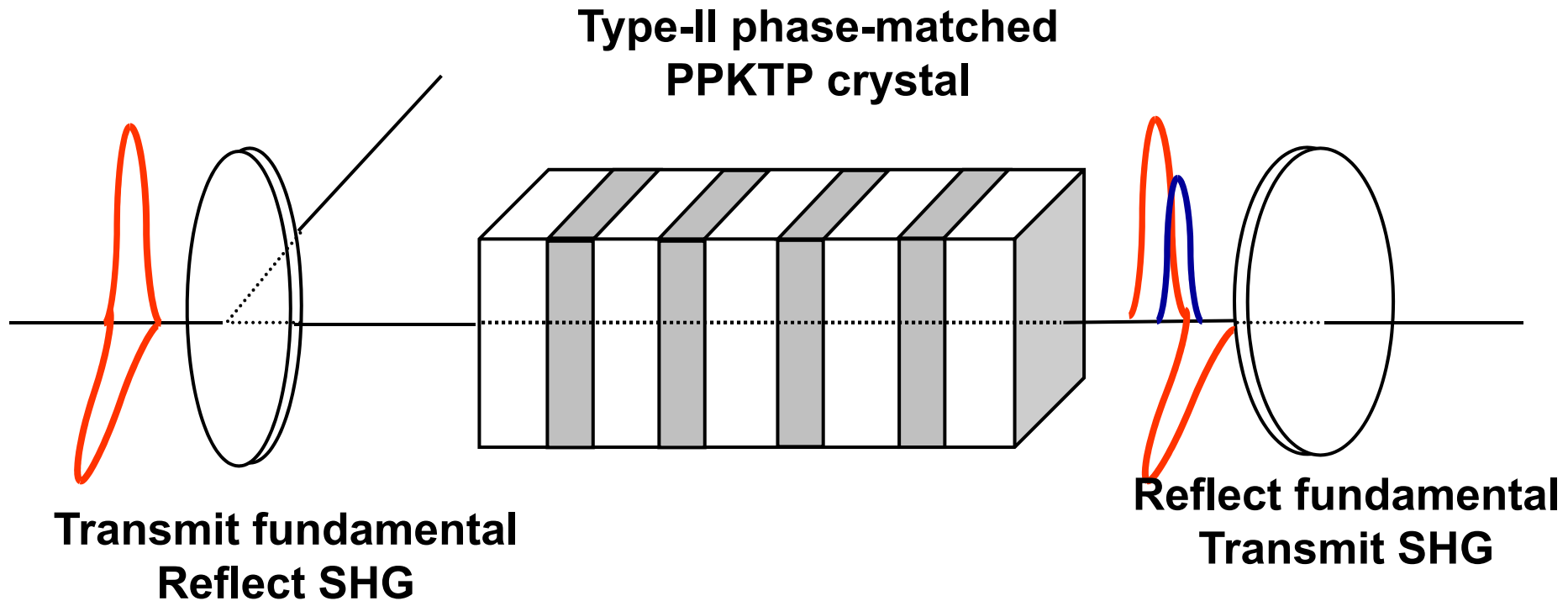
J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator



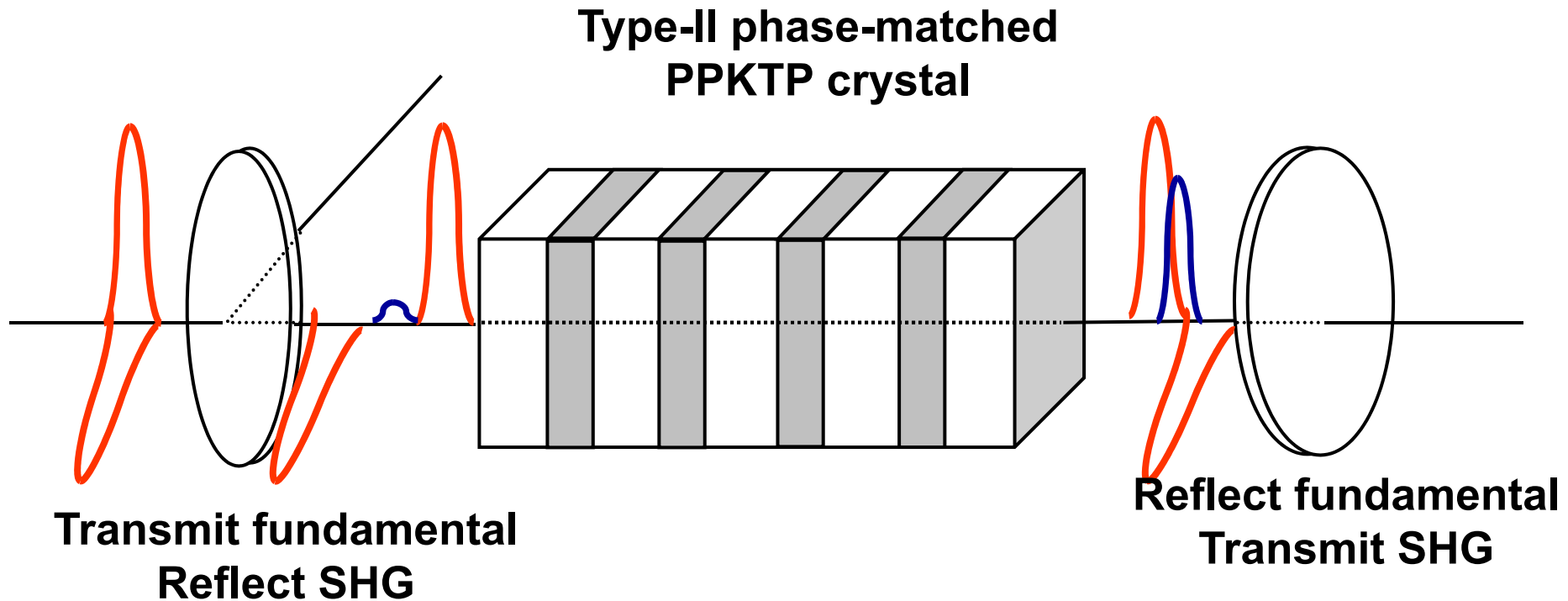
J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator



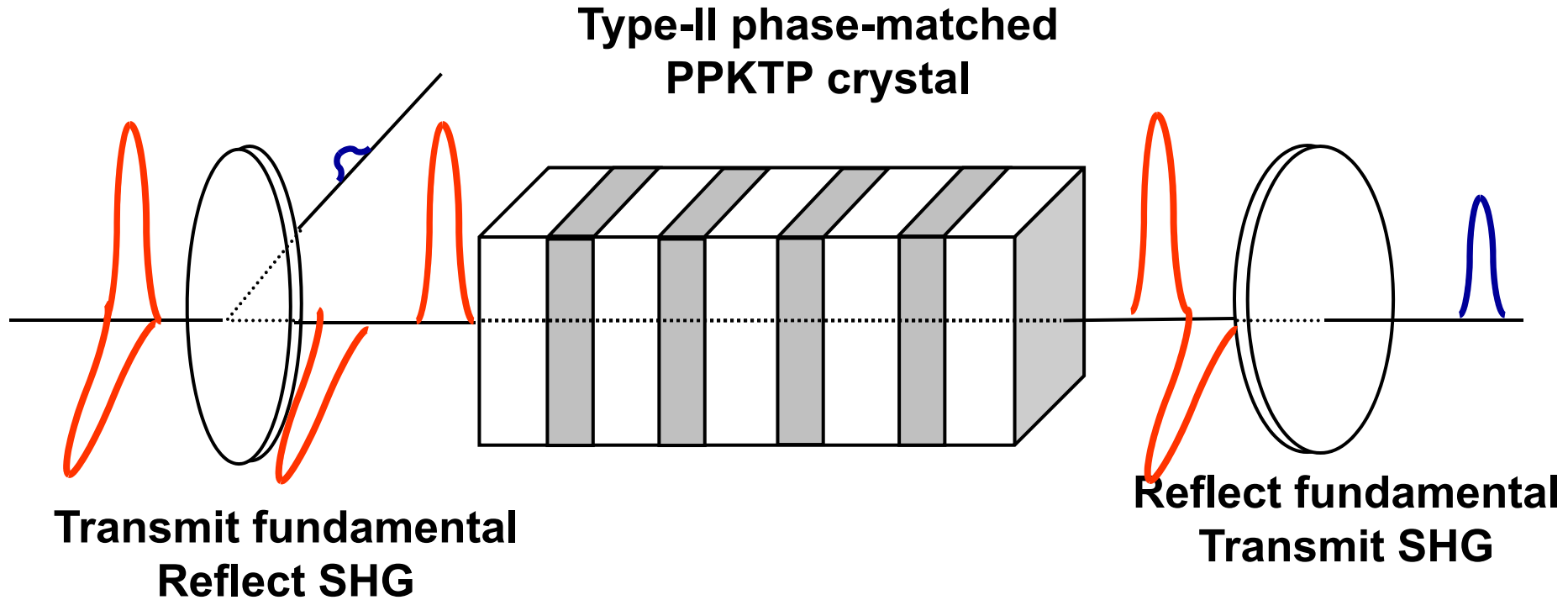
J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator



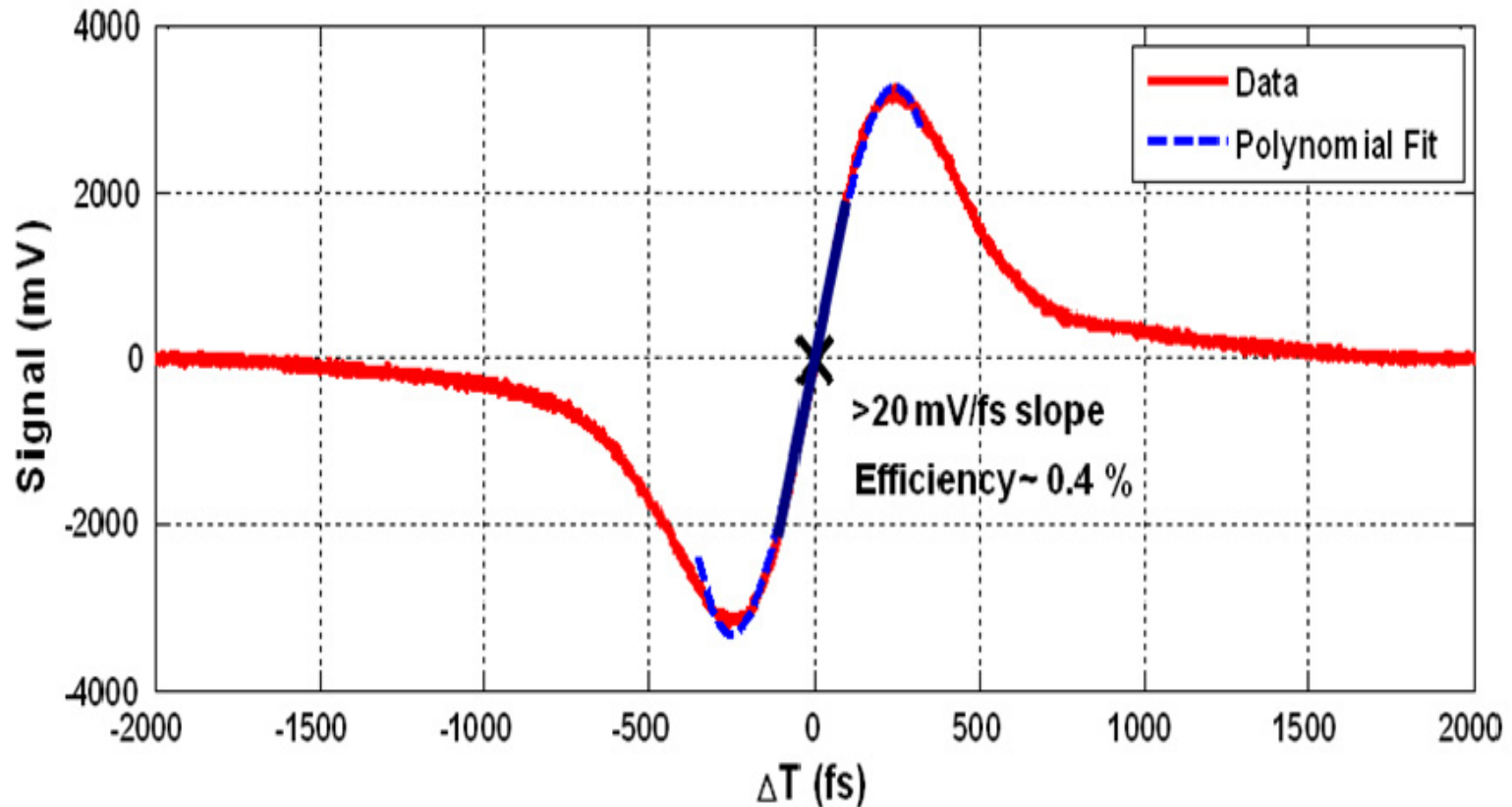
J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator



J. Kim et al., Opt. Lett. 32, 1044 (2007)

Single-crystal balanced cross-correlator

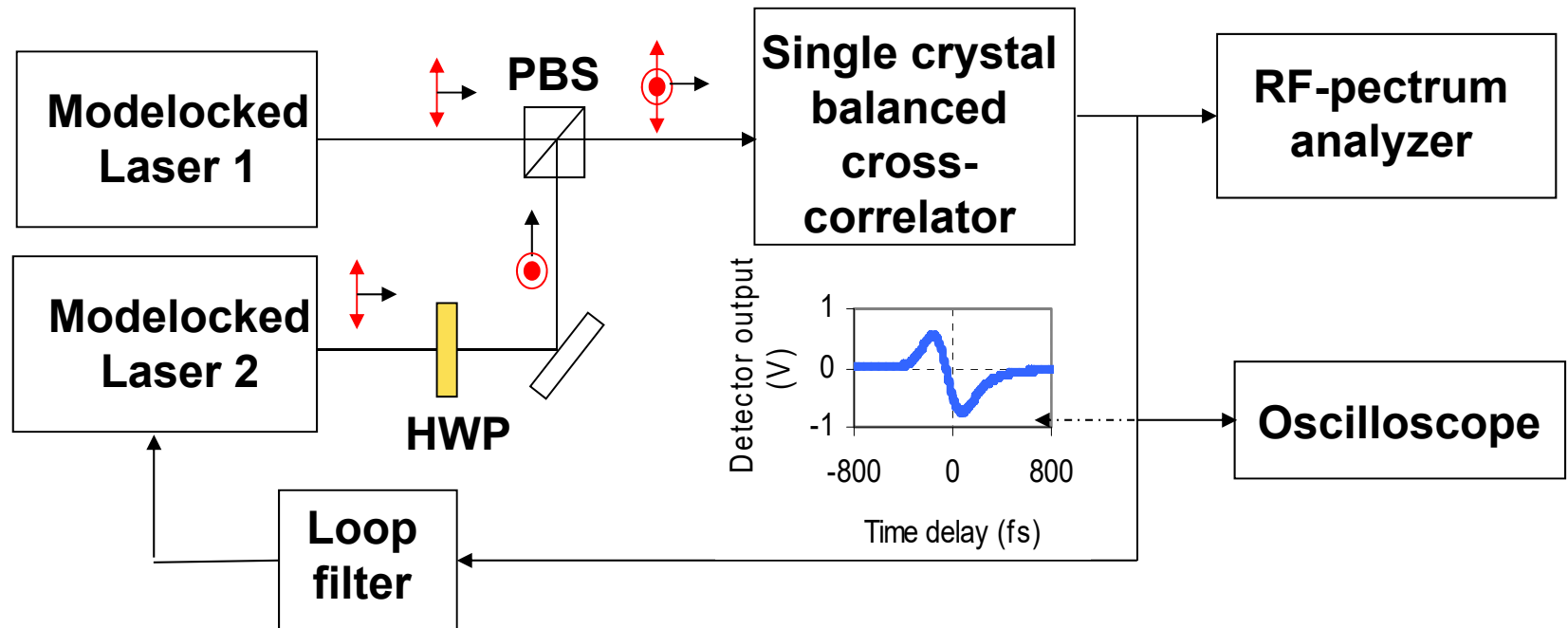


80 pJ, 200 fs
1550nm input pulses
at 200 MHz rep. rate

In comparison:
Typical microwave mixer
Slope ~1 μ V/fs @ 10 GHz
Greatly reduced thermal drifts!

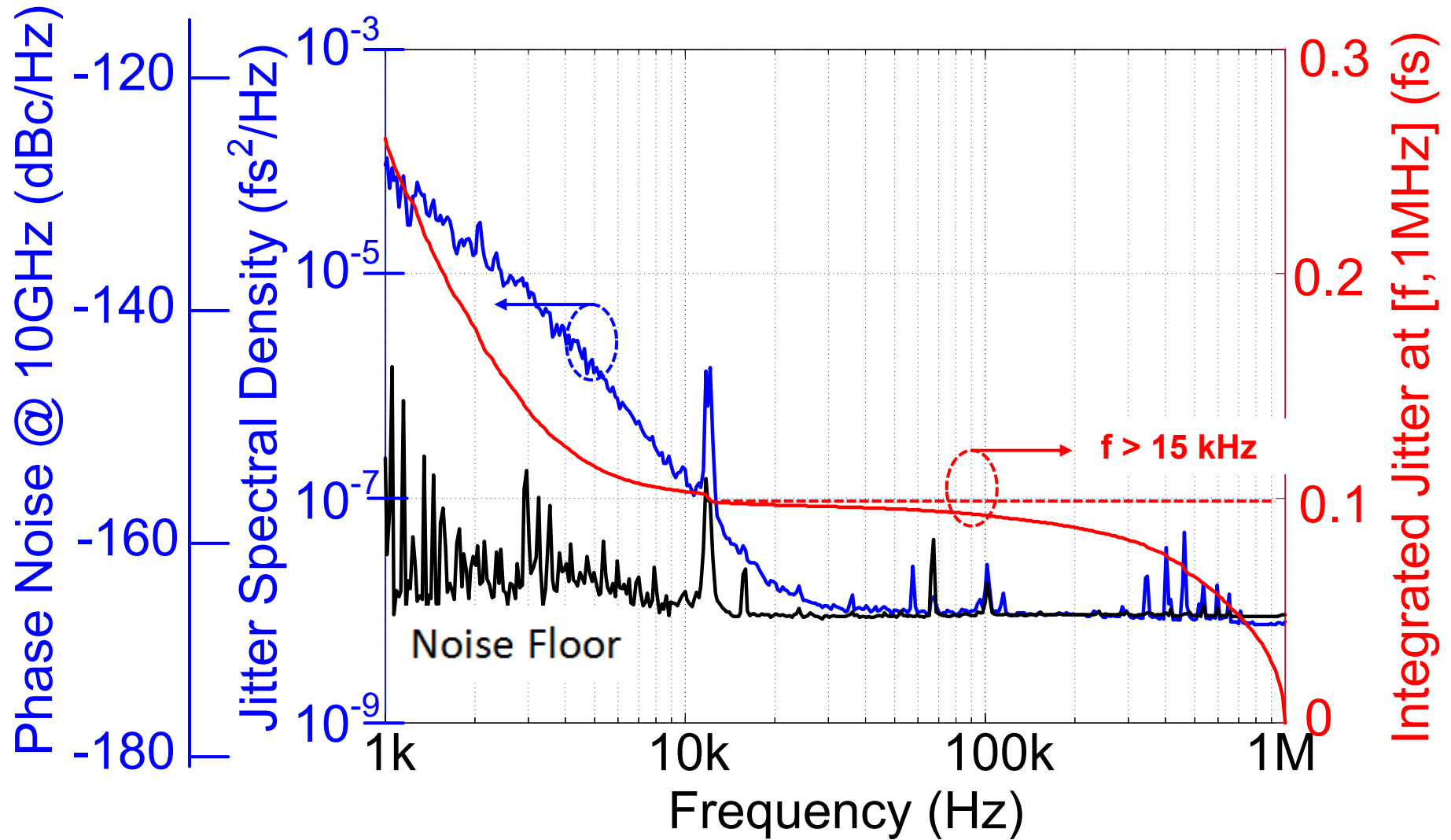
Timing jitter of lasers

Phase detector method → Timing Detector method



J. Kim, et al. , Opt. Lett. 32, 3519 (2007).

Timing jitter of OneFive:Origami Laser



Attosecond Timing ?

How do we get to Attosecond Jitter Lasers?

$$\frac{d}{dt} \langle \Delta t_{ML}^2 \rangle \approx \tau^2 \frac{1}{W_{pulse}} \cdot \frac{\hbar \omega_c}{\tau_{cav}}$$

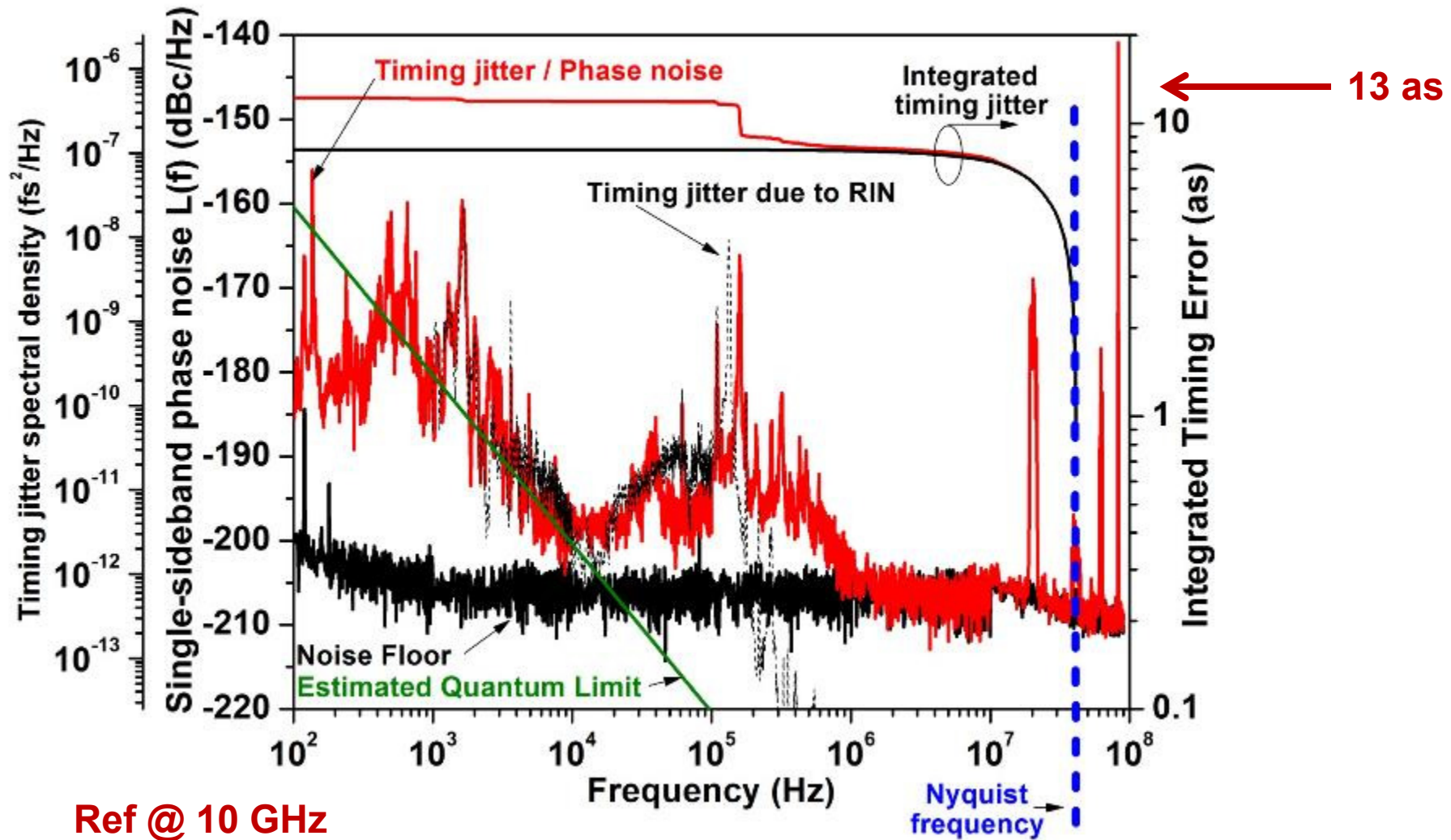
Intracavity losses down (Factor of 50)

Intracavity energy up (Factor of 50)

10-fs pulses (Factor of 100)

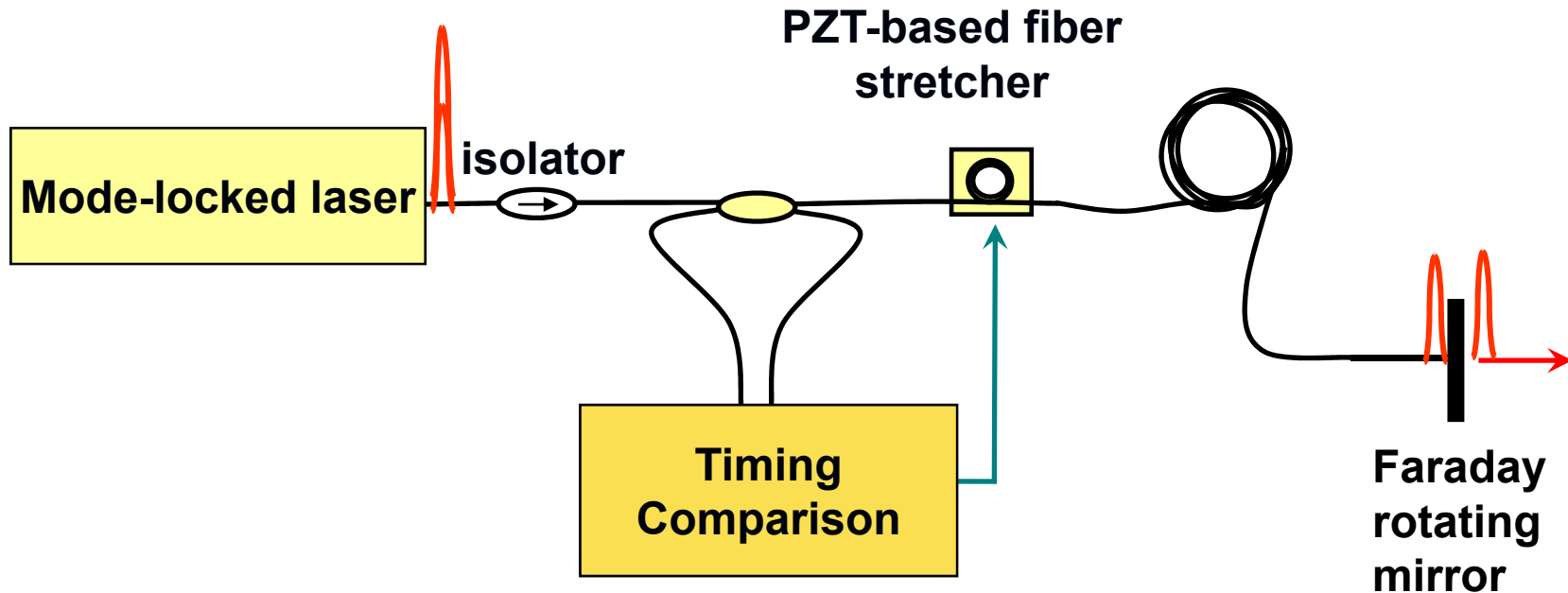
$\sim 10^6$ Is it true?

Two 10-fs Ti:Sapphire Lasers Synchronized within 13 as



Timing-stabilized fiber links

Fiber link ~ 100m - 5km
SMF/DCF or PM/PMDCF

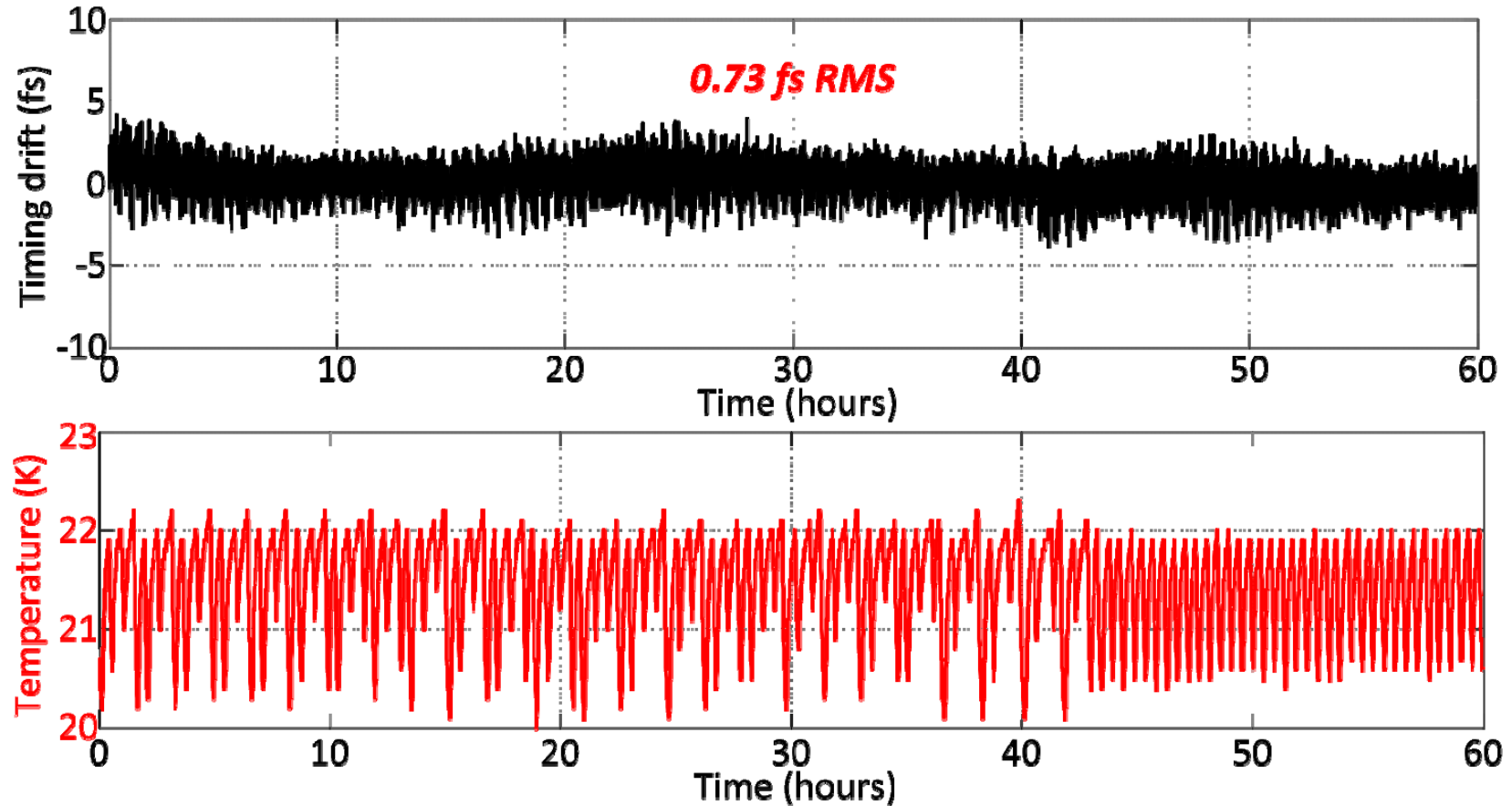


Cancel fiber length fluctuations slower than the pulse travel time ($2nL/c$).

1 km fiber: travel time = $10 \mu\text{s}$ \rightarrow ~ 100 kHz BW

60 hours operation in commercial system

Out-of-loop timing jitter between two 150 m PM-links in a 16-link system



Courtesy



Cycle GmbH

Balanced Optical-Microwave Phase Detector

Microwave
Signal

Optical Pulse
Train

From
link output

θ_e

(BOM-PD)

DC
current

Balanced Optical-Microwave Phase Detector

Microwave
Signal

Optical Pulse
Train

From
link output

θ_e

(BOM-PD)

DC
current

Convert
Phase /Timing
information in
optical domain
into intensity
modulation

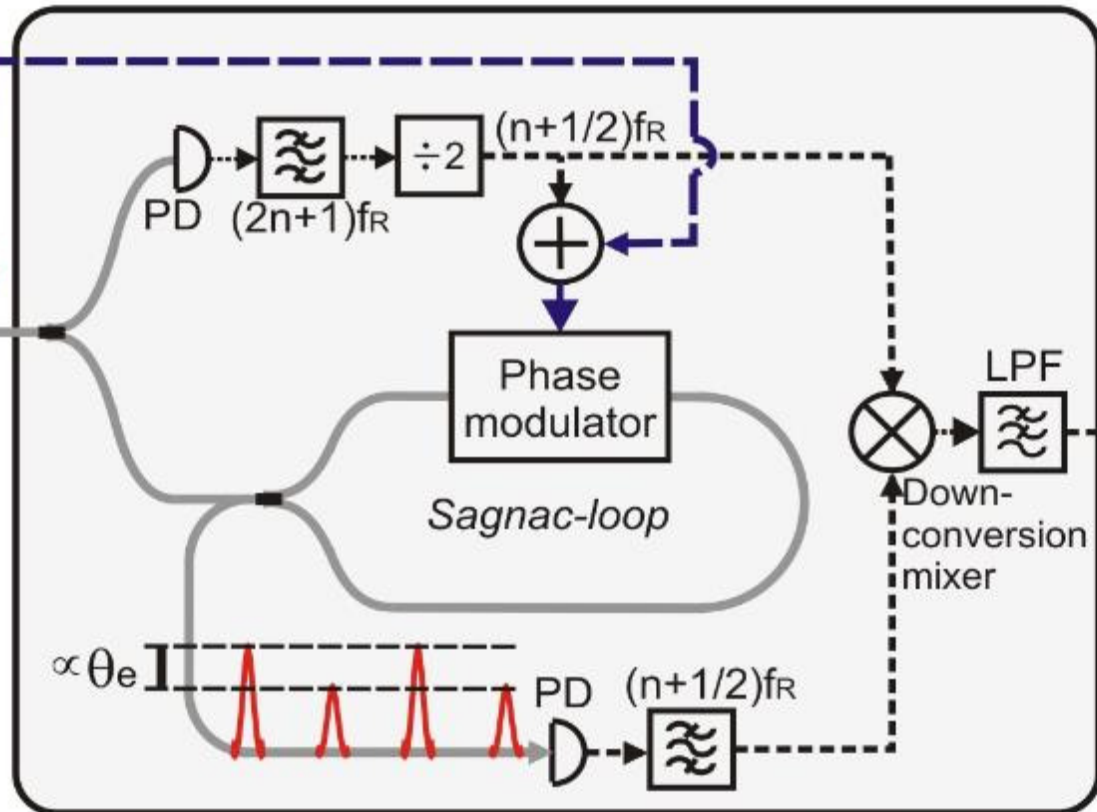
Balanced Optical-Microwave Phase Detector

Microwave Signal

Optical Pulse Train

From link output θ_e

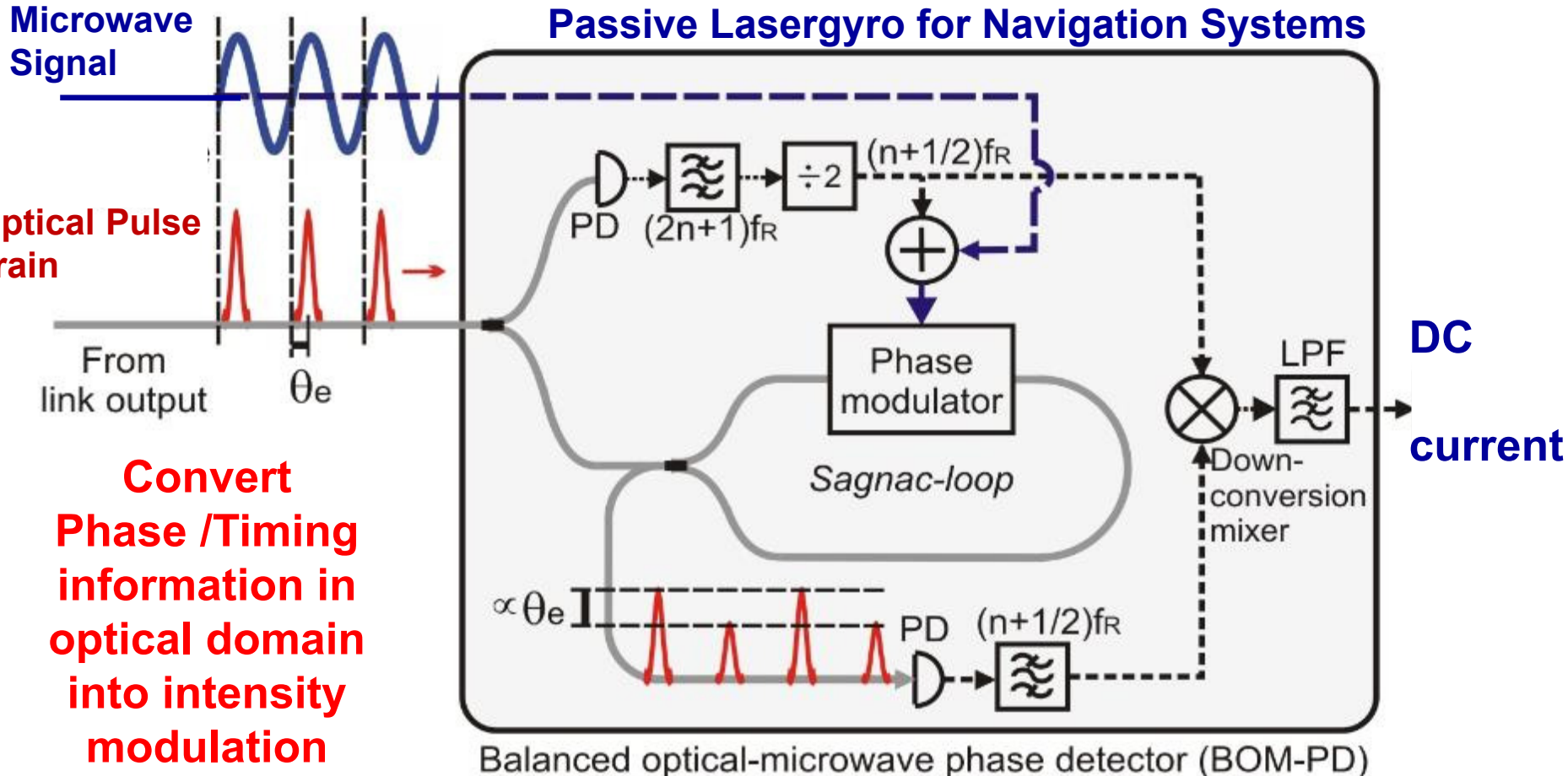
Convert Phase / Timing information in optical domain into intensity modulation



Balanced optical-microwave phase detector (BOM-PD)

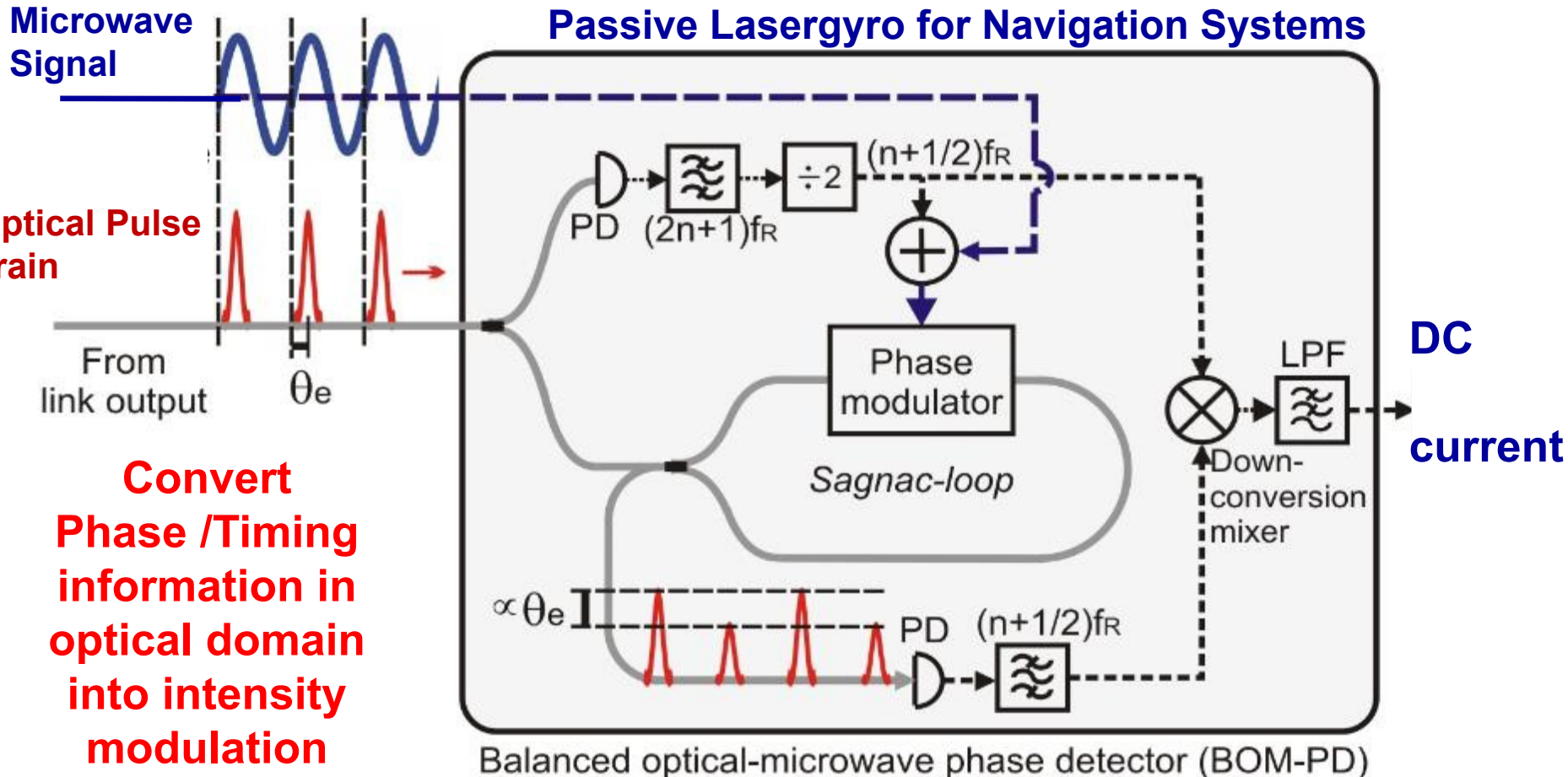
Balanced Optical-Microwave Phase Detector

Passive Lasergyro for Navigation Systems



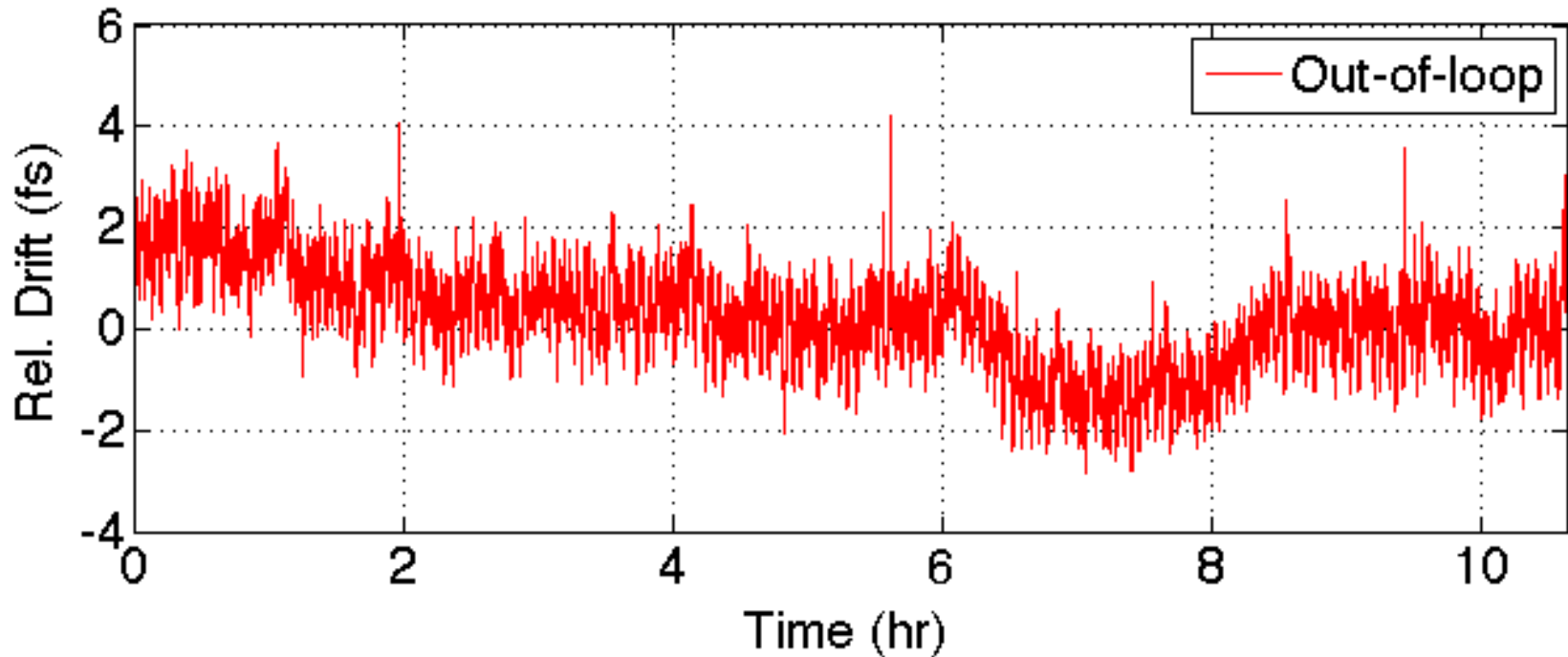
Balanced Optical-Microwave Phase Detector

Passive Lasergyro for Navigation Systems



Electro-optic sampling of microwave signal with optical pulse train

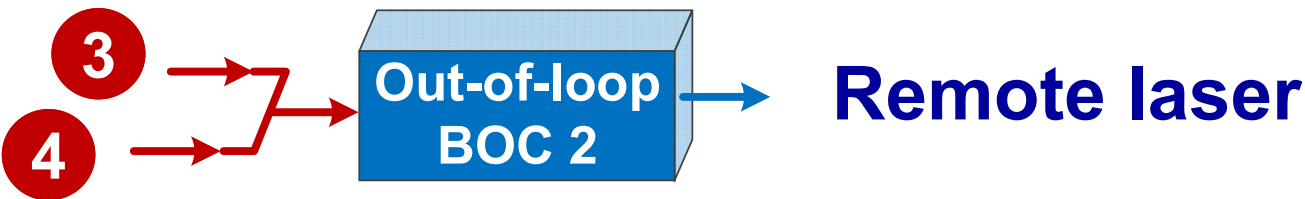
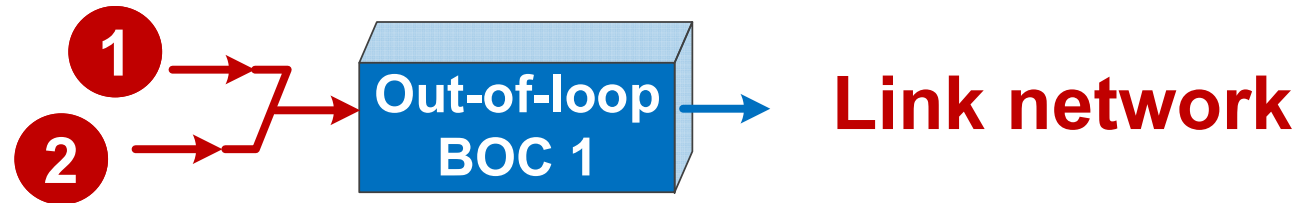
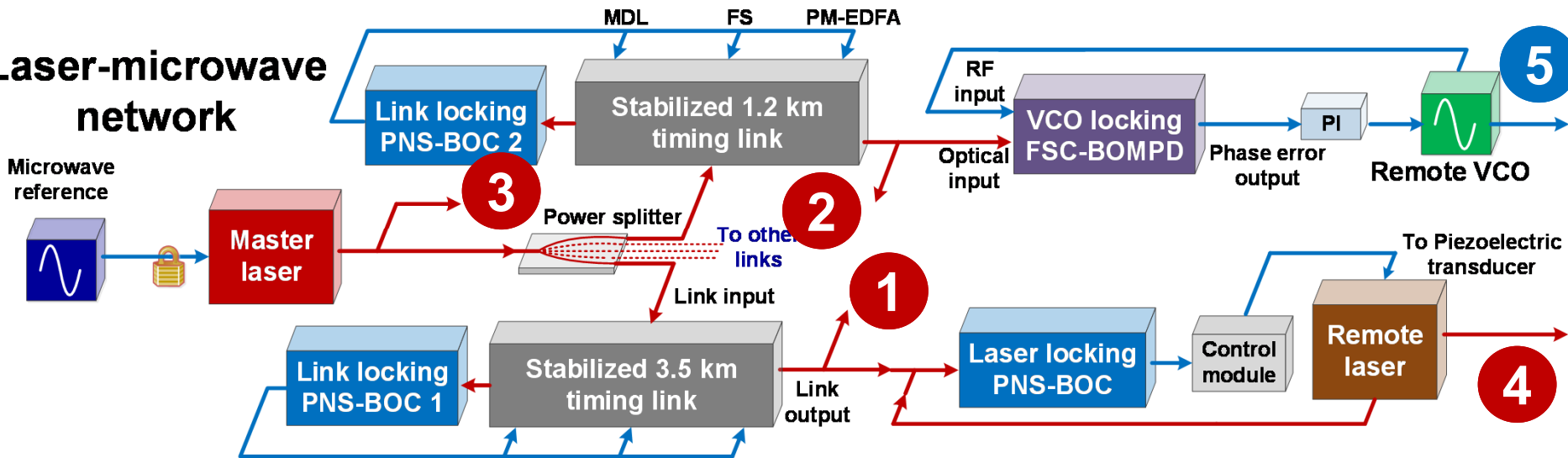
Long-term stability: < 1 fs rms drift over 10 hours



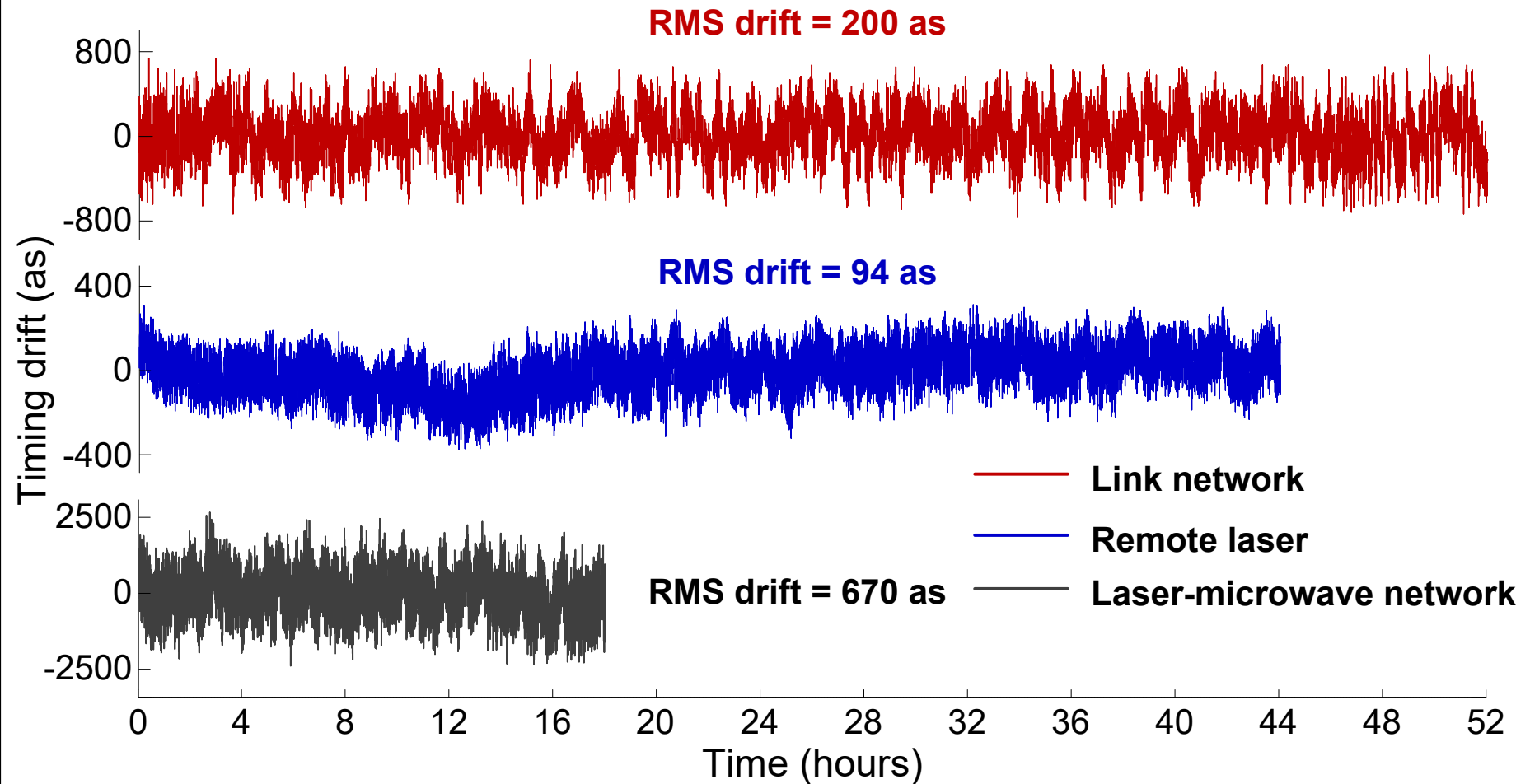
M. Y. Peng, A. Kalaydzhyan, F. X. Kärtner, *Opt. Express*, 22:(22) pp.27102 (2014).

4.7 - km laser-microwave network

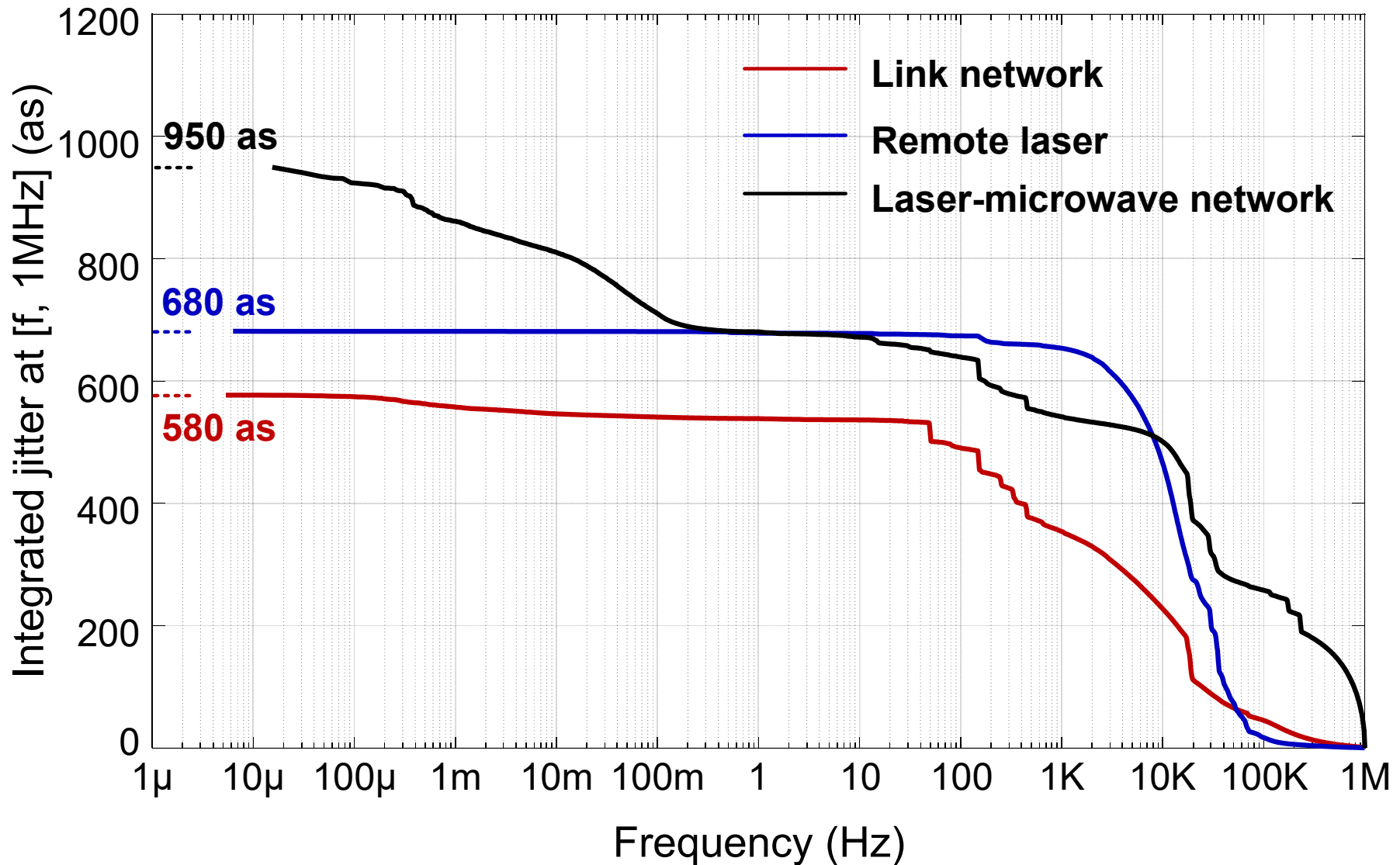
Laser-microwave network



Results—long-term timing drift



Results—Integrated timing jitter

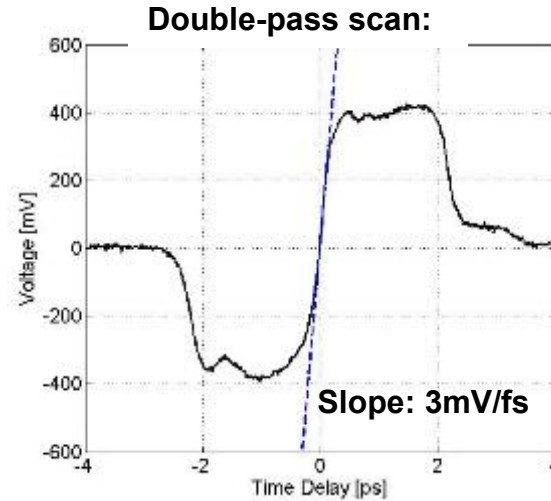
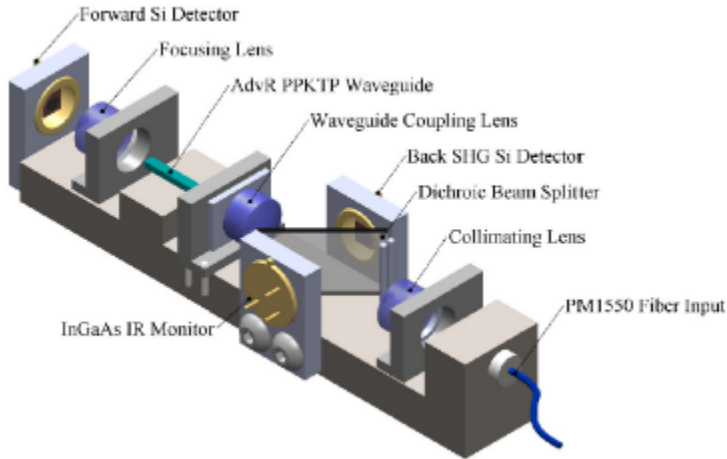


Integrated Optics

BOC and (BOMPD)

Integrated Waveguide BOCs

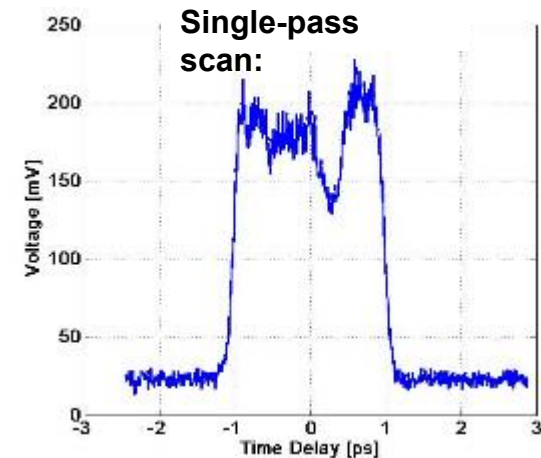
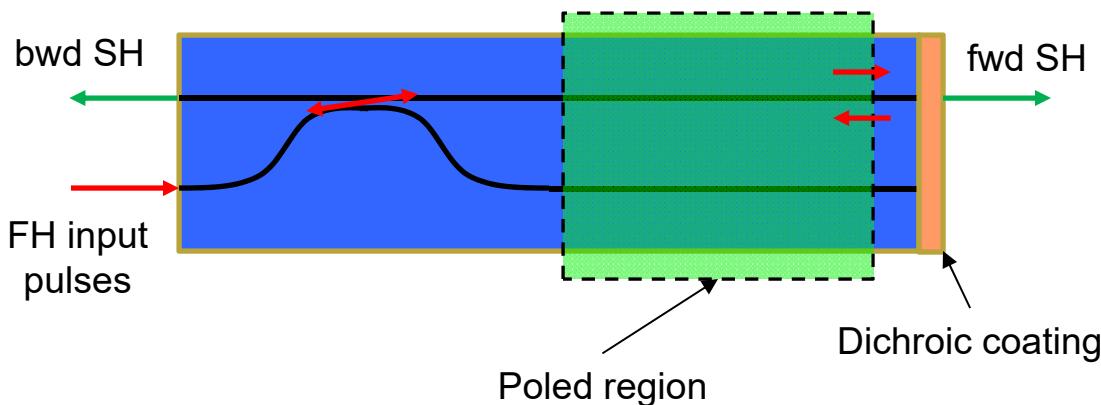
- Packaged waveguide BOC module with miniaturized coupling optics:



Input:
 $P_{avg} = 10 \text{ mW}$
 $f_{rep} = 80 \text{ MHz}$
 $\tau = 200 \text{ fs}$

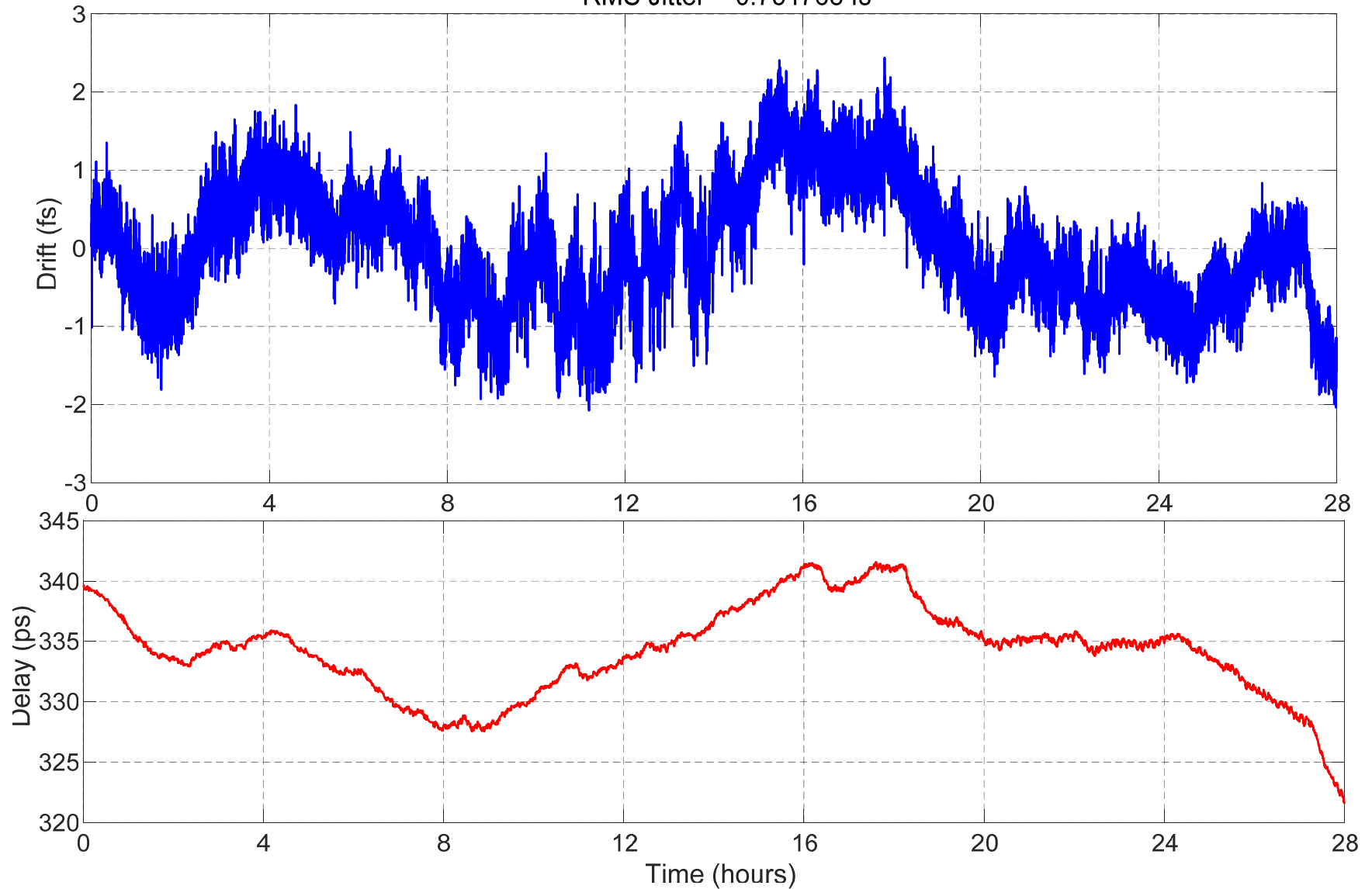
With TIA
 $P_{avg} = 2 \text{ mW}$
 $f_{rep} = 80 \text{ MHz}$
 $\tau = 200 \text{ fs}$
30mV/fs

- Next generation devices: KTP waveguides with integrated WDM couplers



First Results

RMS Jitter = 0.754768 fs



Photonic ADCs

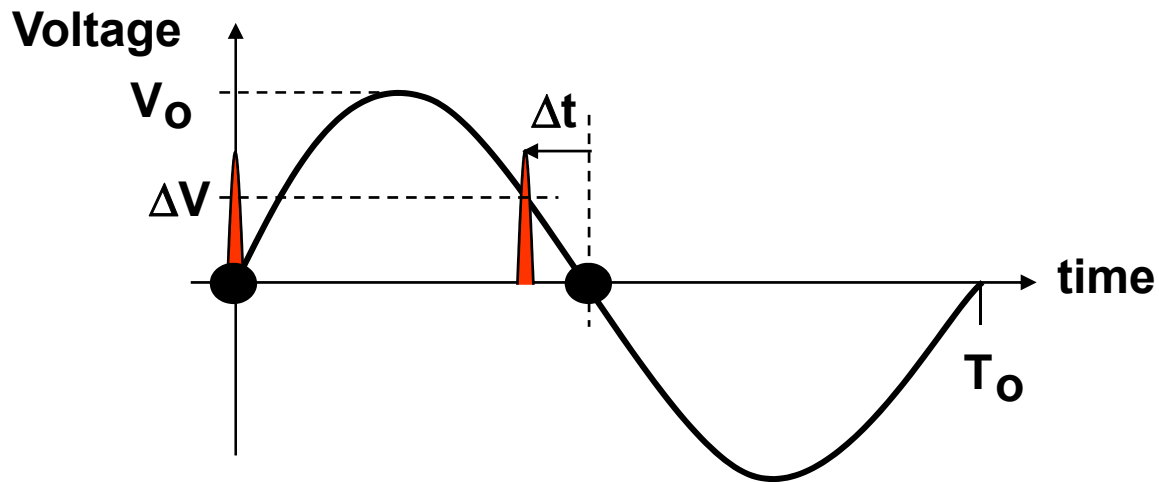
Why Photonically Assisted ADCs?

- Enables extremely low jitter (attoseconds) sampling and high speed information transmission and demultiplexing (Tbit/s)
- Electronics enables high-speed information processing (multi-Gbits/s), electrons directly interact
- Integration of both technologies enables maximum information acquisition, transport and processing on the multi-Tbit/s level, **low parasitics, easier cross channel calibration**
- Integration on a common silicon-platform enables
 - **reduced size, cost and power at much increased performance**

Applications

- **Cognitive radio**
- **Wideband high resolution spectral detection**
- **Multisensor input, Radar**
- **High-speed optical communication systems**
- **RF test equipment**
- **Essentially eliminating analog microwave hardware downwards from the antenna for systems operating up to 50 GHz**

Challenge in Sampling of Microwaves

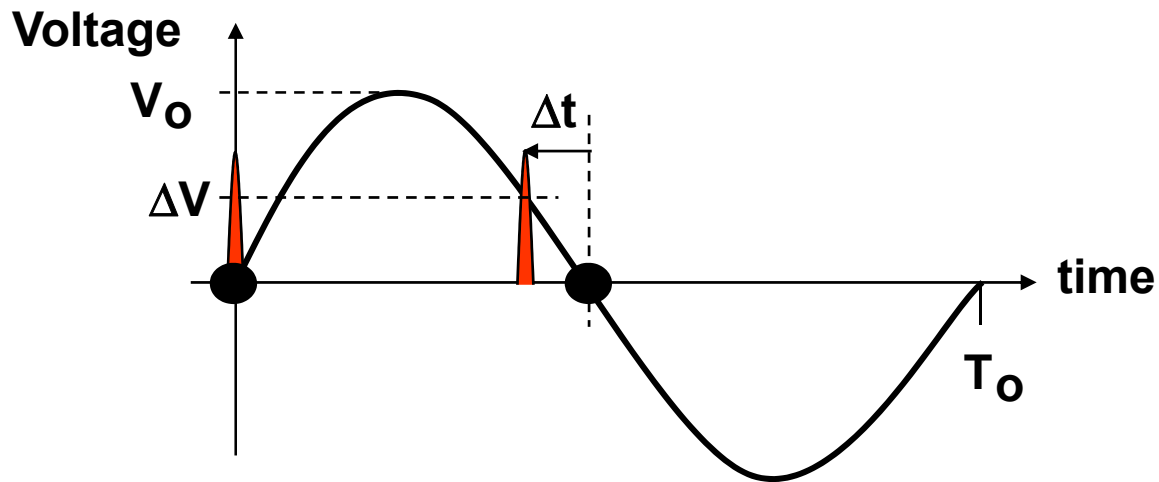


$$\frac{\Delta V}{V_0} = 2\pi \frac{\Delta t}{T_0} = \frac{1}{\sqrt{3} \cdot 2^N}$$

$$\Delta t = \frac{T_0}{2\pi\sqrt{3} \cdot 2^N}$$

Required sampling jitter

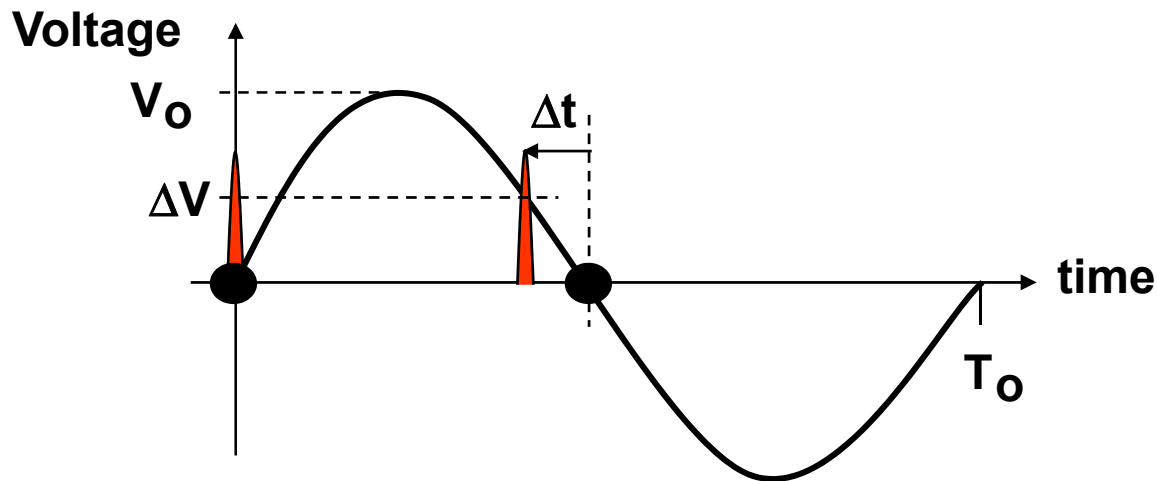
Challenge in Sampling of Microwaves



$$\frac{\Delta V}{V_0} = 2\pi \frac{\Delta t}{T_0} = \frac{1}{\sqrt{3} \cdot 2^N}$$

$$\Delta t = \frac{T_0}{2\pi\sqrt{3} \cdot 2^N}$$

Challenge in Sampling of Microwaves



$$\frac{\Delta V}{V_0} = 2\pi \frac{\Delta t}{T_0} = \frac{1}{\sqrt{3} \cdot 2^N}$$

$$\Delta t = \frac{T_0}{2\pi\sqrt{3} \cdot 2^N}$$

Targeted resolution	Required sampling jitter	
	10 GHz	50 GHz
14-bit	0.5 fs	0.1 fs
12-bit	2 fs	0.4 fs
10-bit	9 fs	1.8 fs
8-bit	36 fs	7.2 fs
6-bit	144 fs	30 fs

State of the Art Electronic ADC and Beyond

Nortel Inc.: 40 GSa/s CMOS

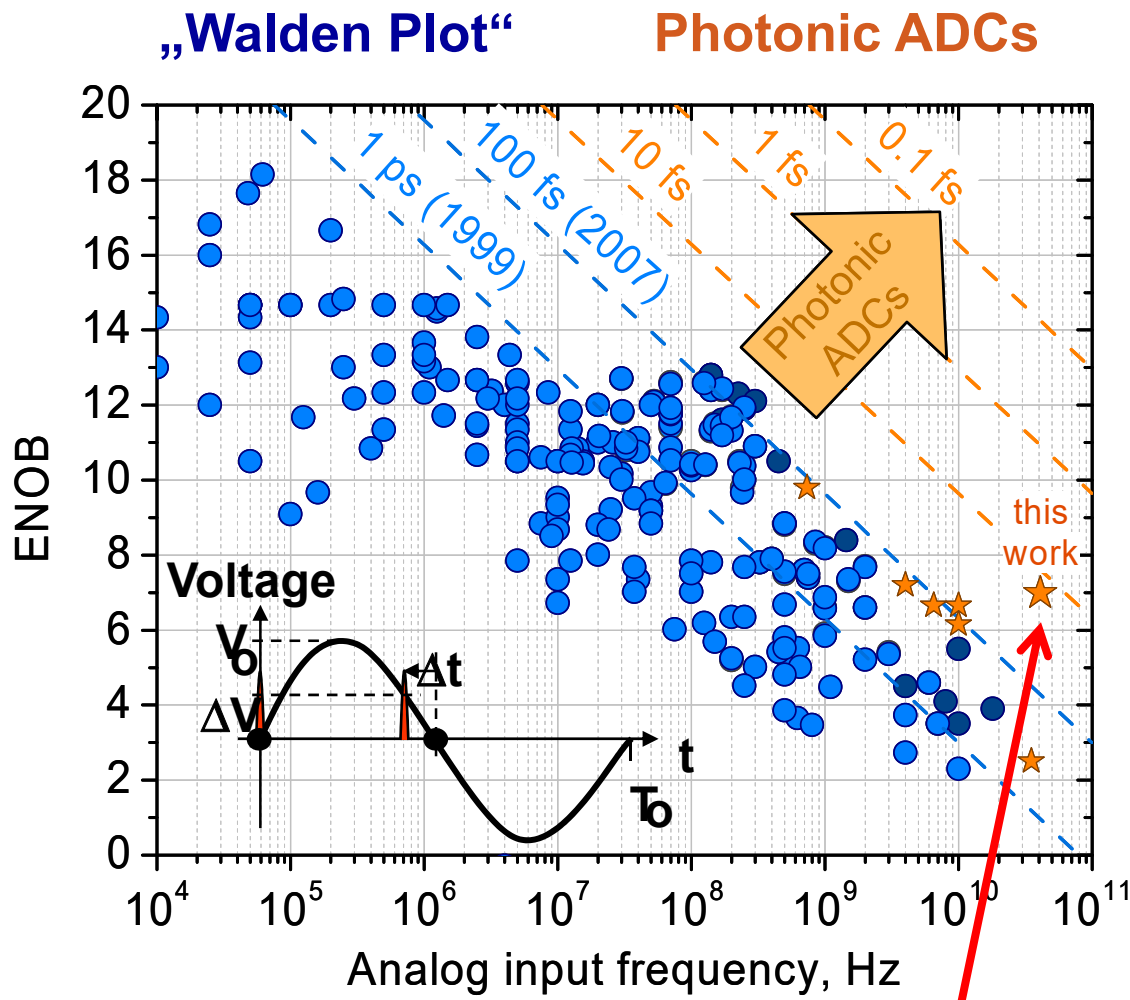
Y. M. Greshishchev, et al.
ISSCC, paper 21.7
(2010).

Fujitsu Inc.: 65 GSa/s CMOS

<http://www.fujitsu.com>

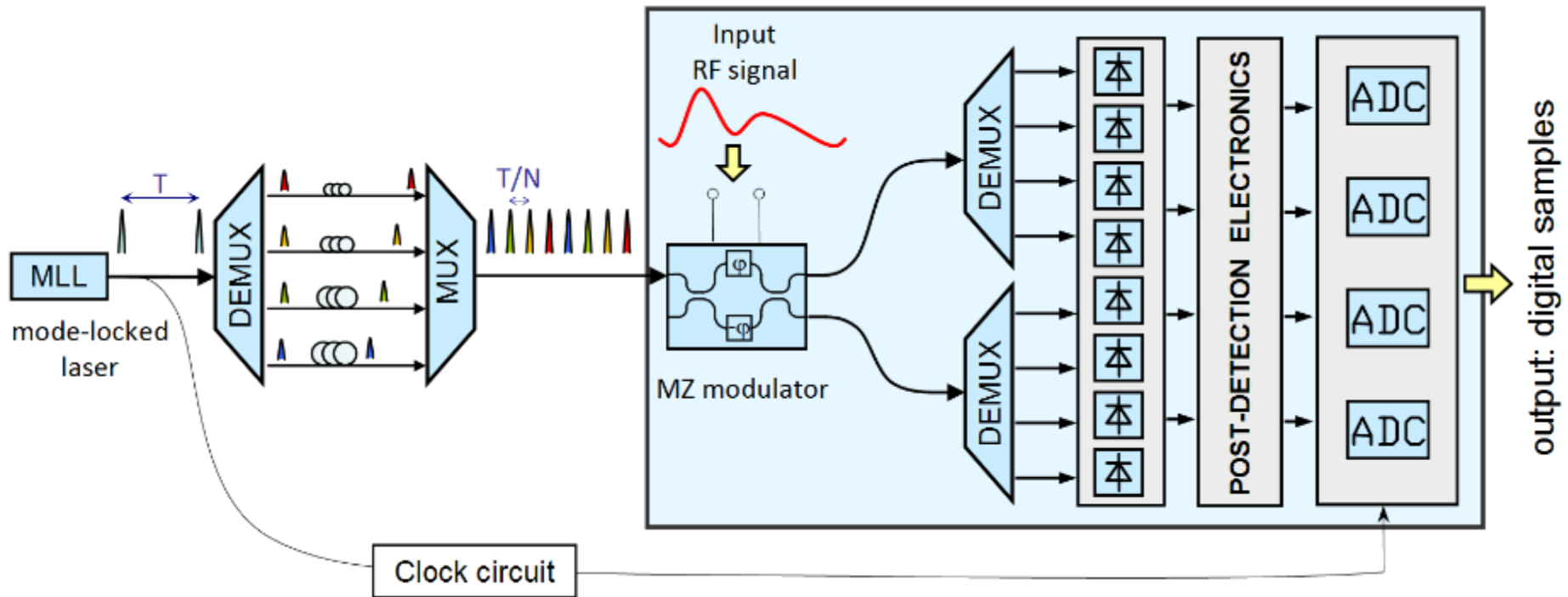
RPI: 40 GSa/s SiGe ADC

M. Chu, et al. IEEE J. Solid State Circuits 45, 380
(2010).



40.99 GHz, 7.0 ENOB, 16 fs jitter

Wavelength Multiplexed Optical Sampling



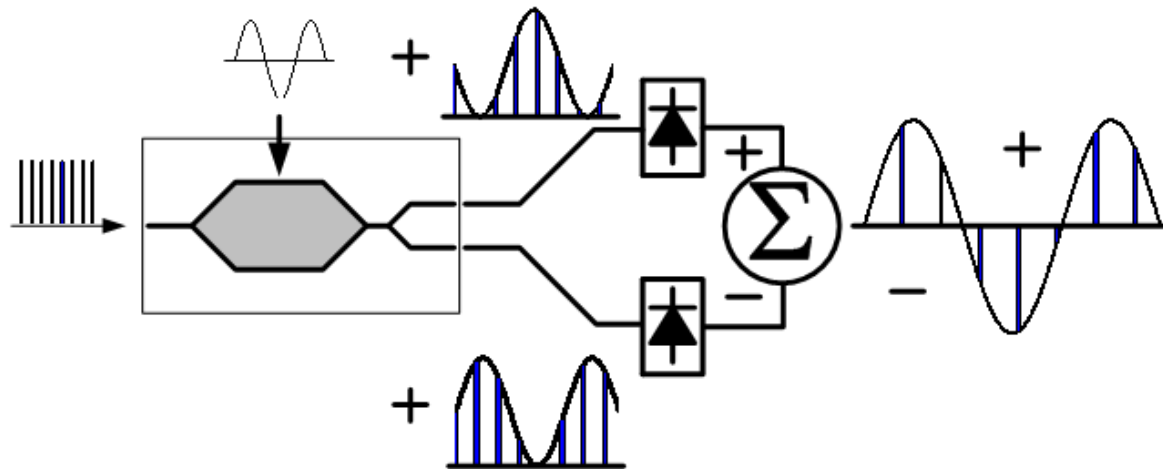
- Effective sampling rate = laser rep rate ($1/T$) x number of multiplexed channels (N)
- Sampling jitter is set by MLL timing jitter
- Digitization is performed in electronic domain
- Down counting by WDM

T. Clark, "Time and wavelength interleaved phot. Sampler", PTL 99.

**DARPA EPIC
2004 - 2009**

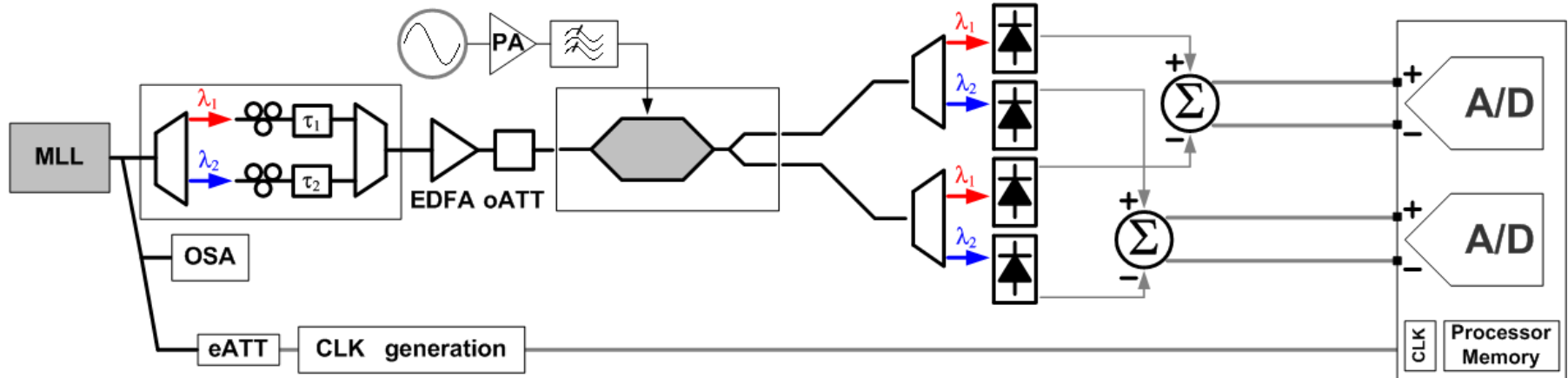


Balanced Detection – Enhanced S/N



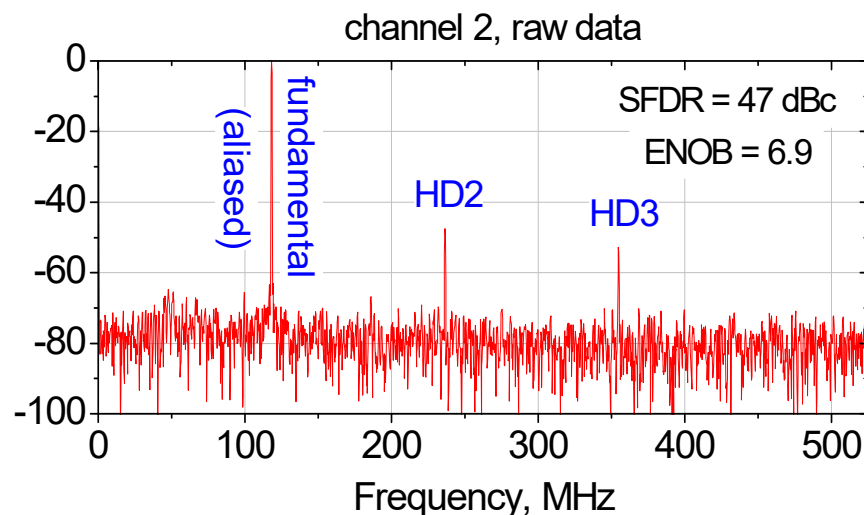
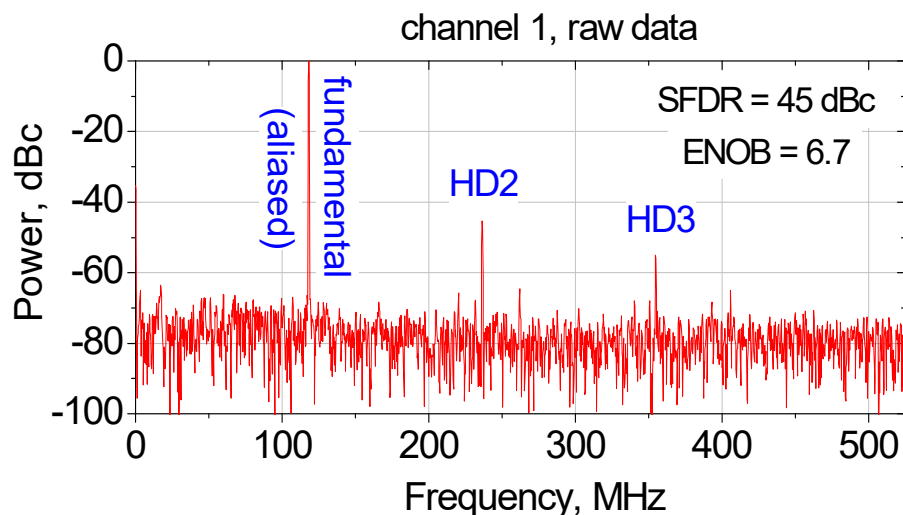
- Outputs of MZ intensity modulator are 180° out-of-phase
- Single photodetector can only generate a unipolar (positive) electrical signal
- Balanced detection generates a bipolar signal
- Voltage (x2) \rightarrow Signal Power (\uparrow 6 dB)

Two Wavelength Channel COTS System



- High performance ADCs: National Semiconductors
1 GSa/s, 9 ENOB
- EO-Space 40 GHz bandwidth modulator
- MLL rep rate = 1.048 GHz → Sampling rate = 2.1 Gsa/s
- RF freq = 40.99 GHz

Results: RF Spectra – individual channels



$$y_1 = \arcsin(\alpha_1 + \beta_1 \cdot x_1) \quad \text{Wavelength \#1}$$

$$y_2 = \arcsin(\alpha_2 + \beta_2 \cdot x_2) \quad \text{Wavelength \#2}$$

$$\alpha \approx \frac{1}{100} (\beta \cdot x)$$

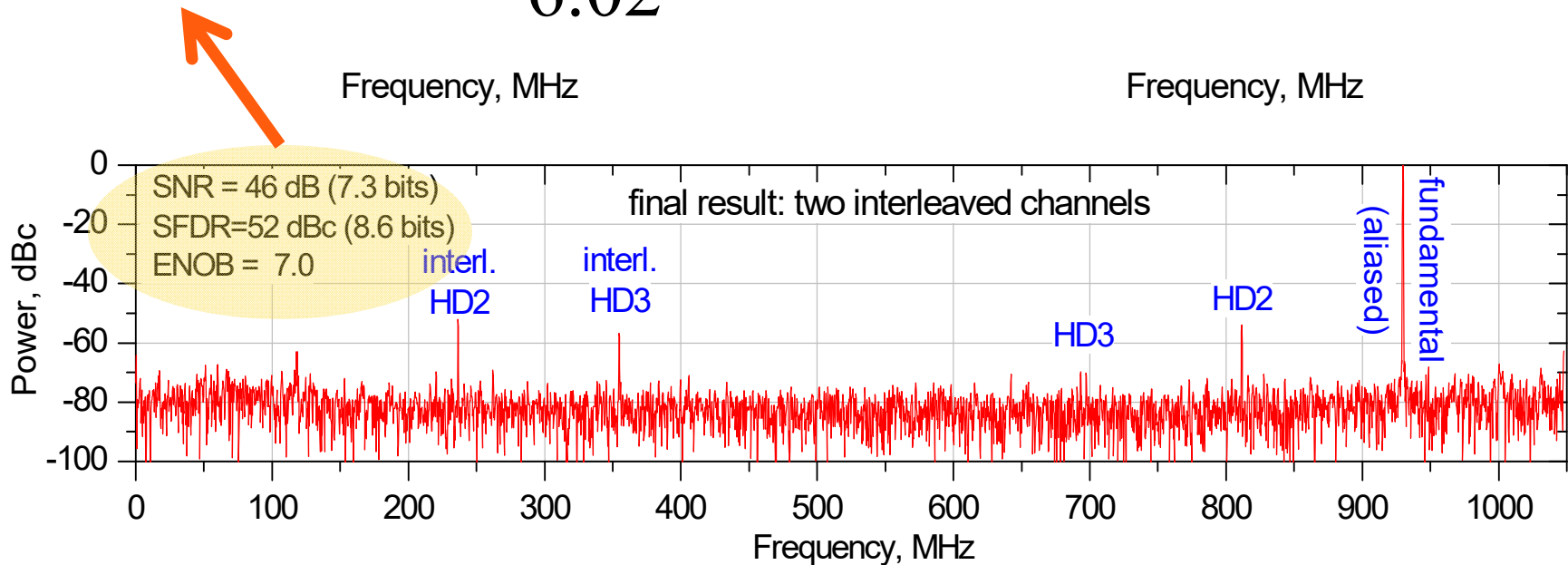
$$\max(y_1) - \min(y_1) = \max(y_2) - \min(y_2) \quad \text{Constraint}$$

- x : outputs of the balanced photoreceivers / y : RF signals

Results: Aggregate RF Spectra

- Noise limited
- Aperture jitter: 15 fs
- $SNDR = \text{Signal(dB)} - \text{Noise(dB)} - \text{Total-Distortion(dB)}$

$$ENOB = \frac{SNDR(dB) - 1.76}{6.02}$$

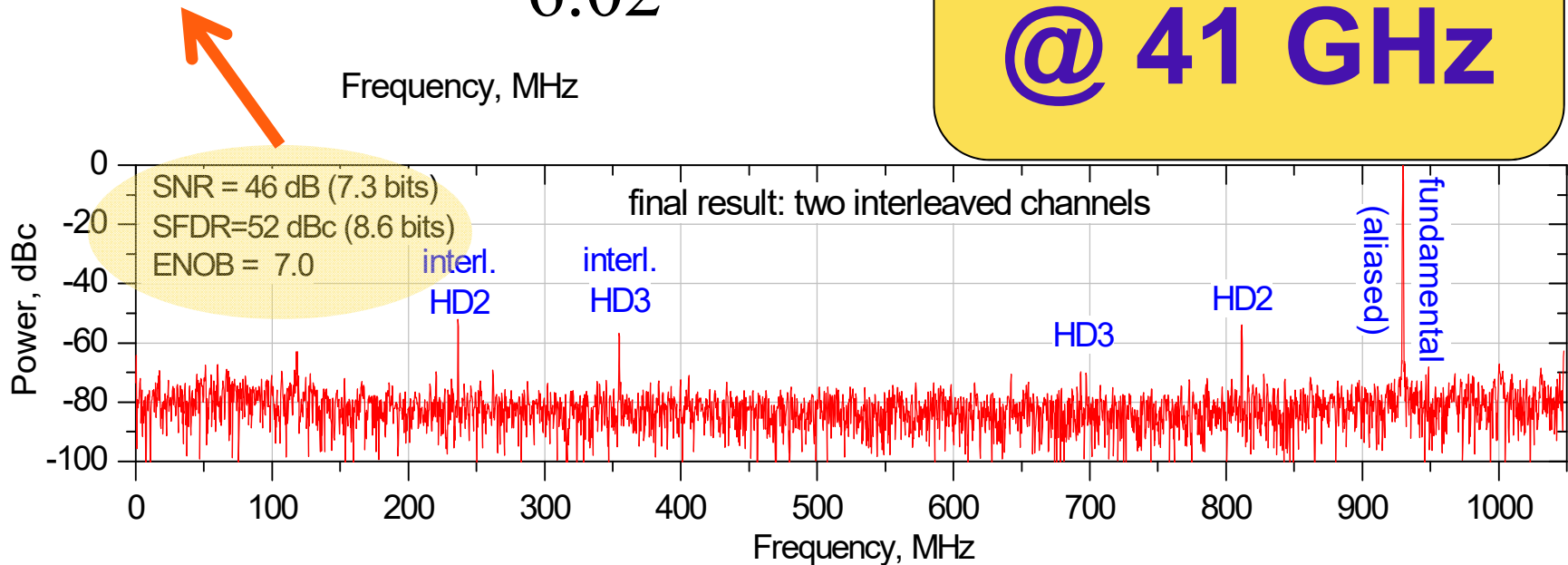


Results: Aggregate RF Spectra

- Noise limited
- Aperture jitter: 15 fs
- $SNDR = \text{Signal(dB)} - \text{Noise(dB)} - \text{Total-Distortion(dB)}$

$$ENOB = \frac{SNDR(dB) - 1.76}{6.02}$$

**7.0 ENOB
@ 41 GHz**



Integrated Photonic ADC

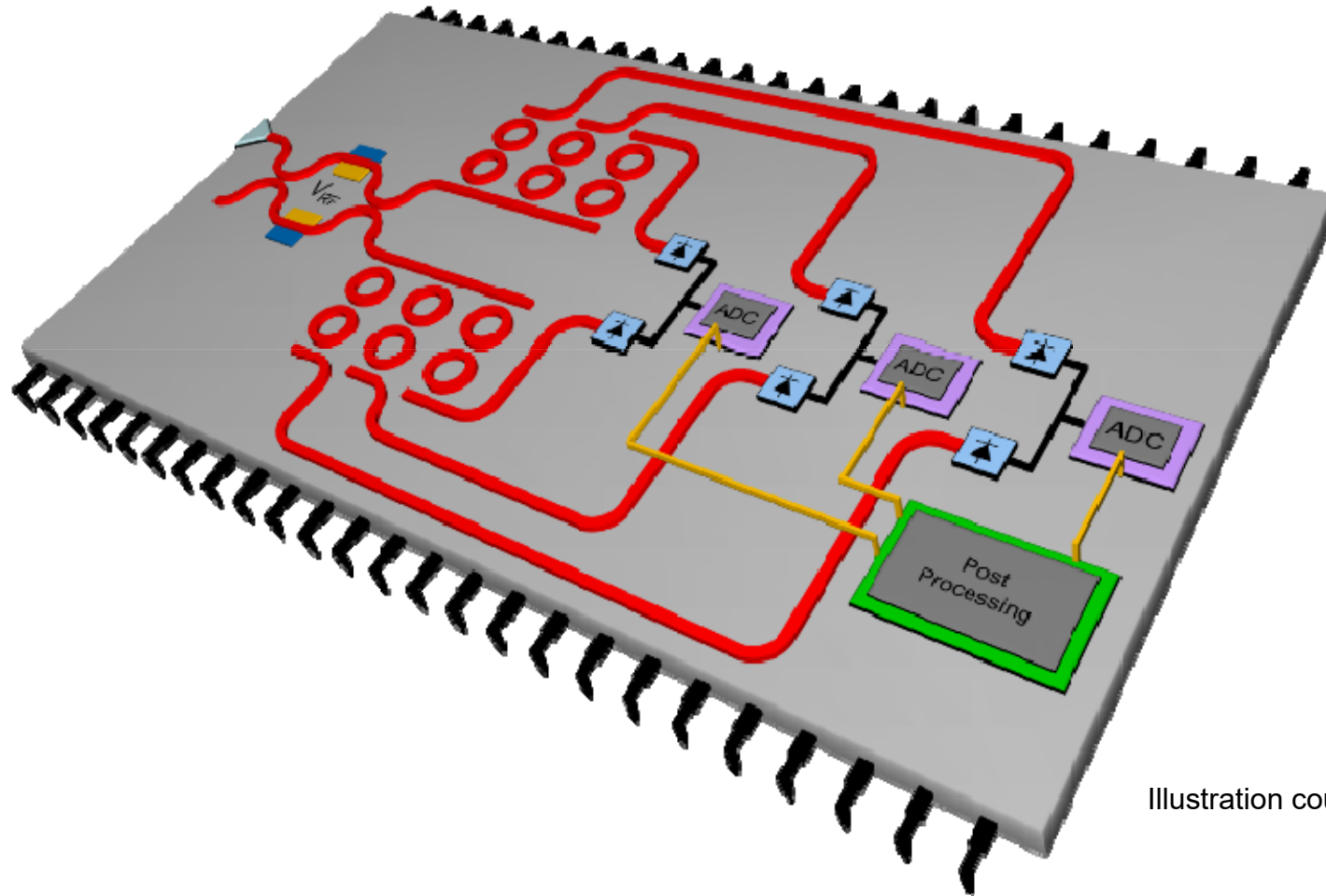


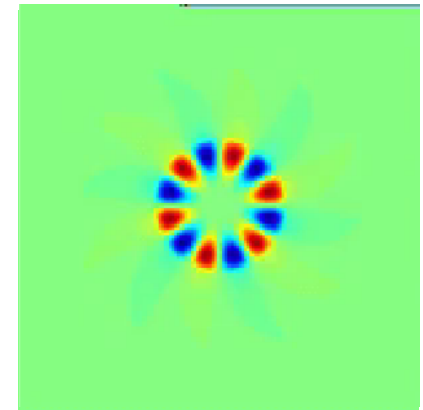
Illustration courtesy of Marcus Dahlem

Khilo *et al.*, Opt. Exp. (20) 4454 (2012)

High Index Contrast Integrated Photonics

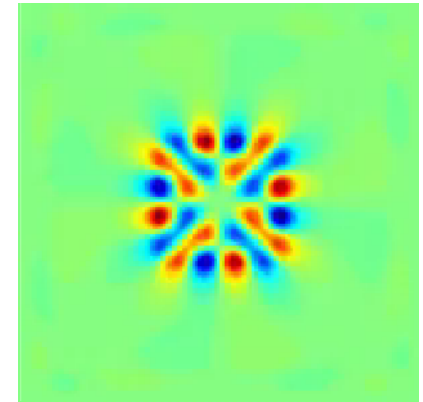
- **Optical resonators** - no good conductors
- optical confinement by index discontinuity
- **High Index Contrast: ~50-200%** (conventional <2%)
 - **Material is Si:SiN:SiO₂:air = 3.5:2.2:1.45:1.0**
 - **Dimensions: waveguide <1 μm, ring resonators <15 μm**

<u>HIC Benefits</u>	<u>HIC Challenges</u>
Low radiation loss (large free spectral range: FSR)	Reduce scattering loss (sidewall roughness)
Dense integration small size, efficient interaction with carriers	Fiber-chip coupling
	Polarization sensitivity (res. frequency, coupling)



Traveling-wave resonator

in Si:air (3.0:1.0 index)

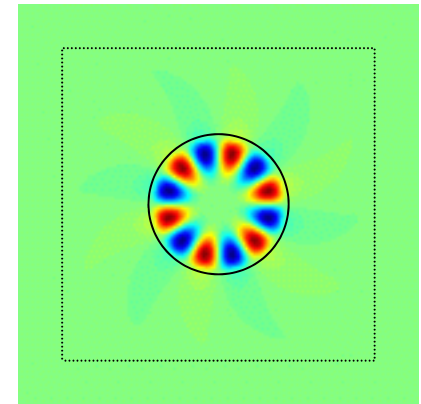


Standing-wave resonator

Silicon Photonics

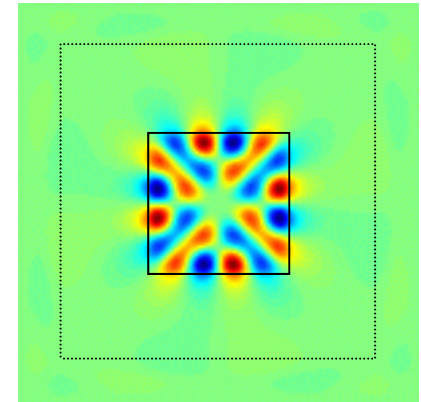
- **Optical resonators** - no good conductors
- optical confinement by index discontinuity
- **High Index Contrast:** ~50-200% (conventional <2%)
 - Material is Si:SiN:SiO₂:air = 3.5:2.2:1.45:1.0
 - Dimensions: waveguide <1 μm, ring resonators <15 μm

<u>HIC Benefits</u>	<u>HIC Challenges</u>
Low radiation loss (large free spectral range: FSR)	Reduce scattering loss (sidewall roughness)
Dense integration small size, efficient interaction with carriers	Fiber-chip coupling
	Polarization sensitivity (res. frequency, coupling)



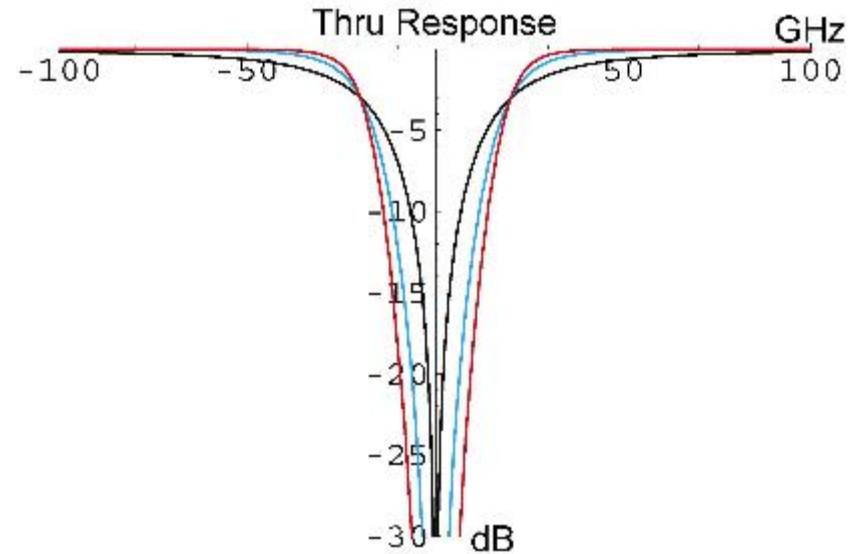
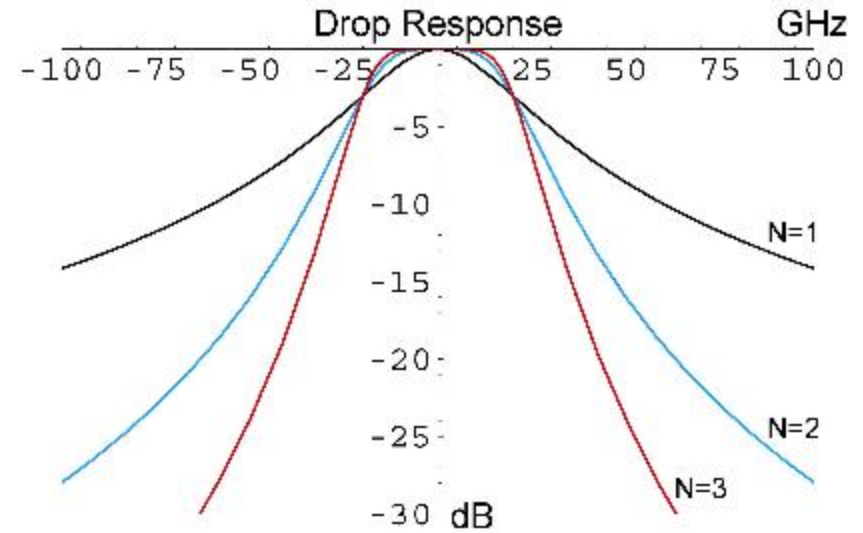
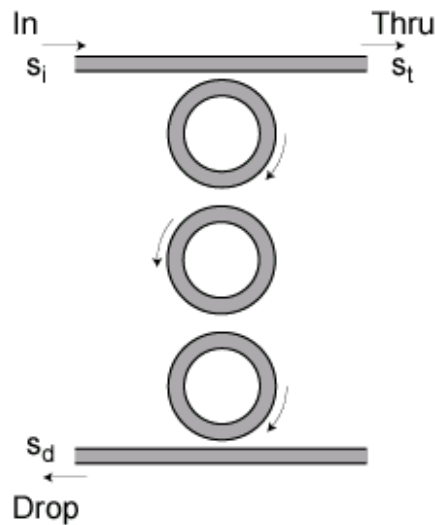
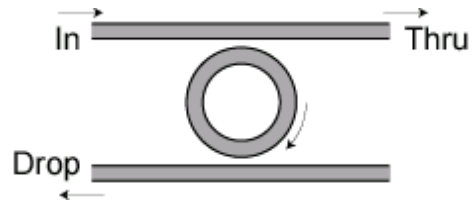
Traveling-wave resonator

in Si:air (3.0:1.0 index)

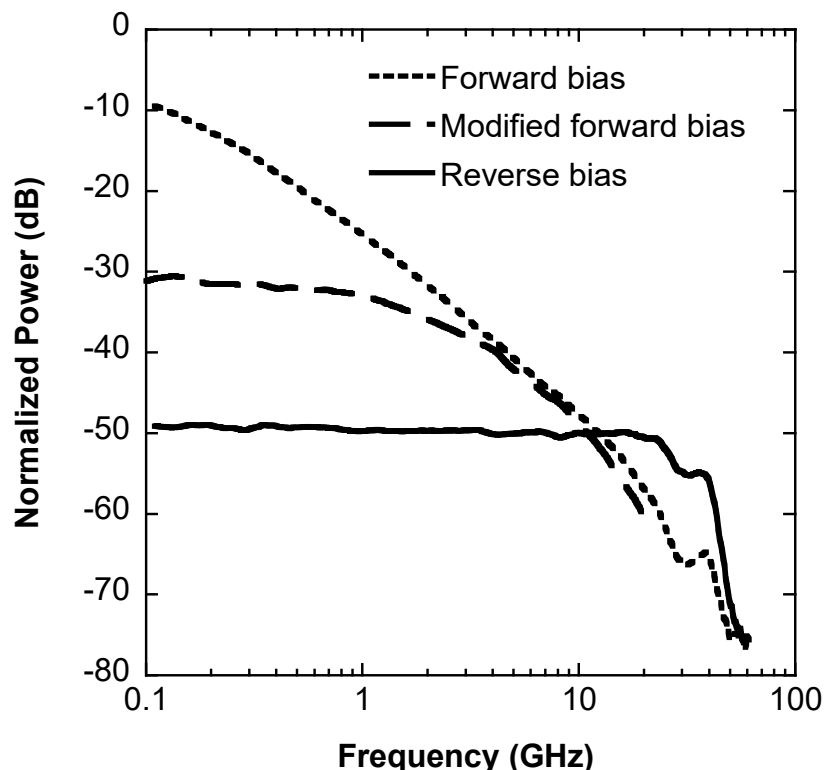
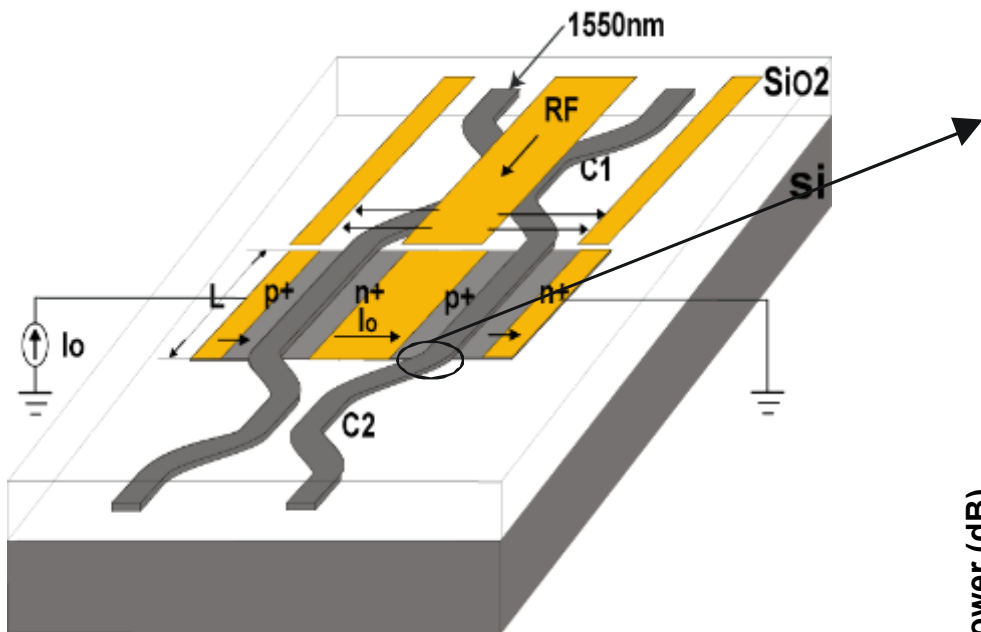


Standing-wave resonator

Microring Resonator Filters



High-Speed Si-Modulator



Forward or reversed biased PIN-sections

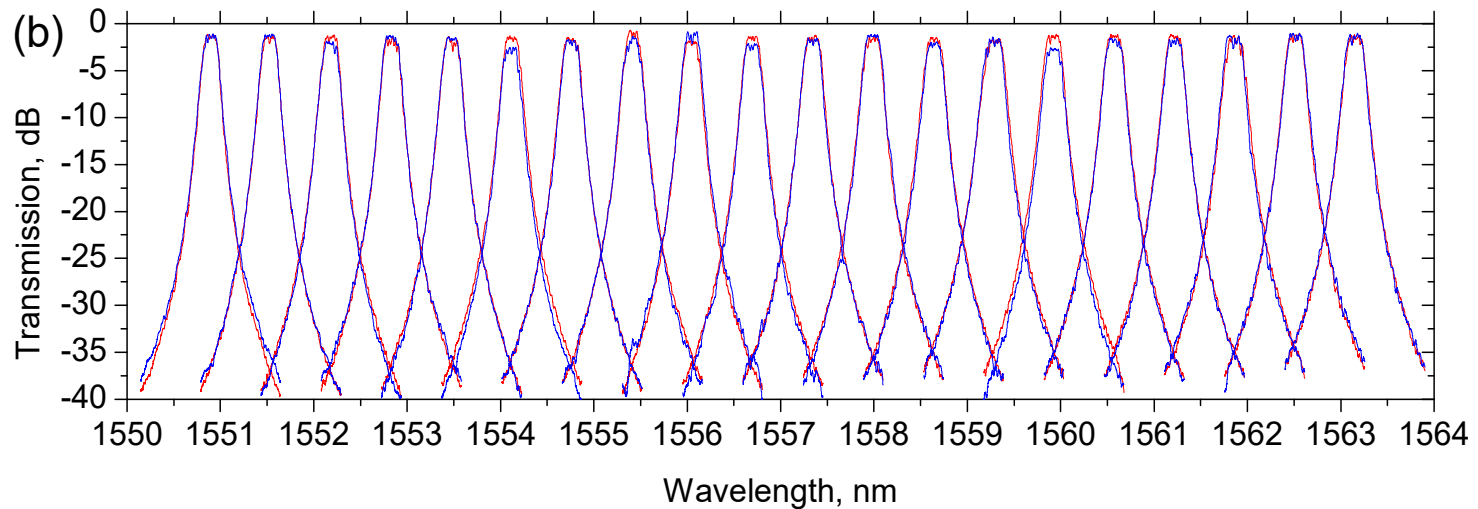
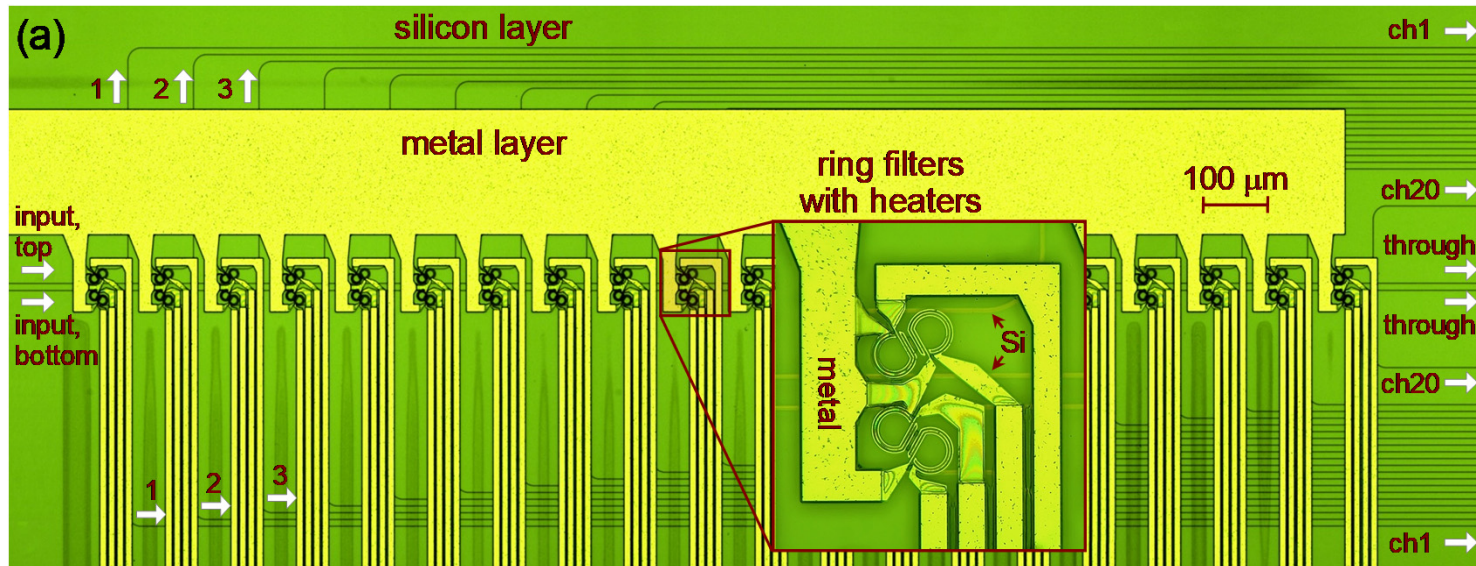
Optimized doping profile:

--> low loss, high-speed > 20GHz

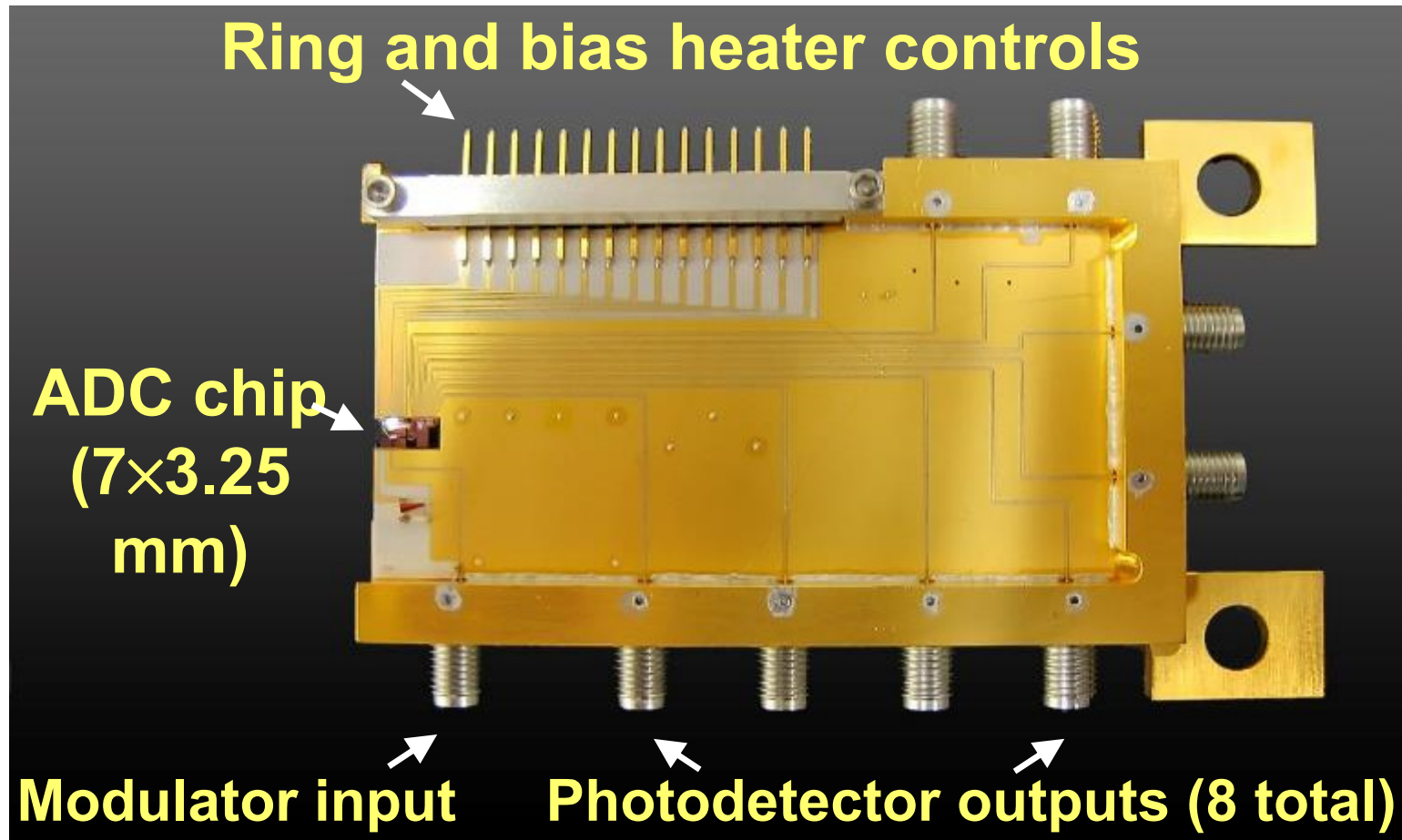
Typical insertion loss: 3-5 dB

$V_{\pi}L \sim 0.5 \text{ V}\cdot\text{cm}$

20-Channel Silicon Photonic Filter Bank



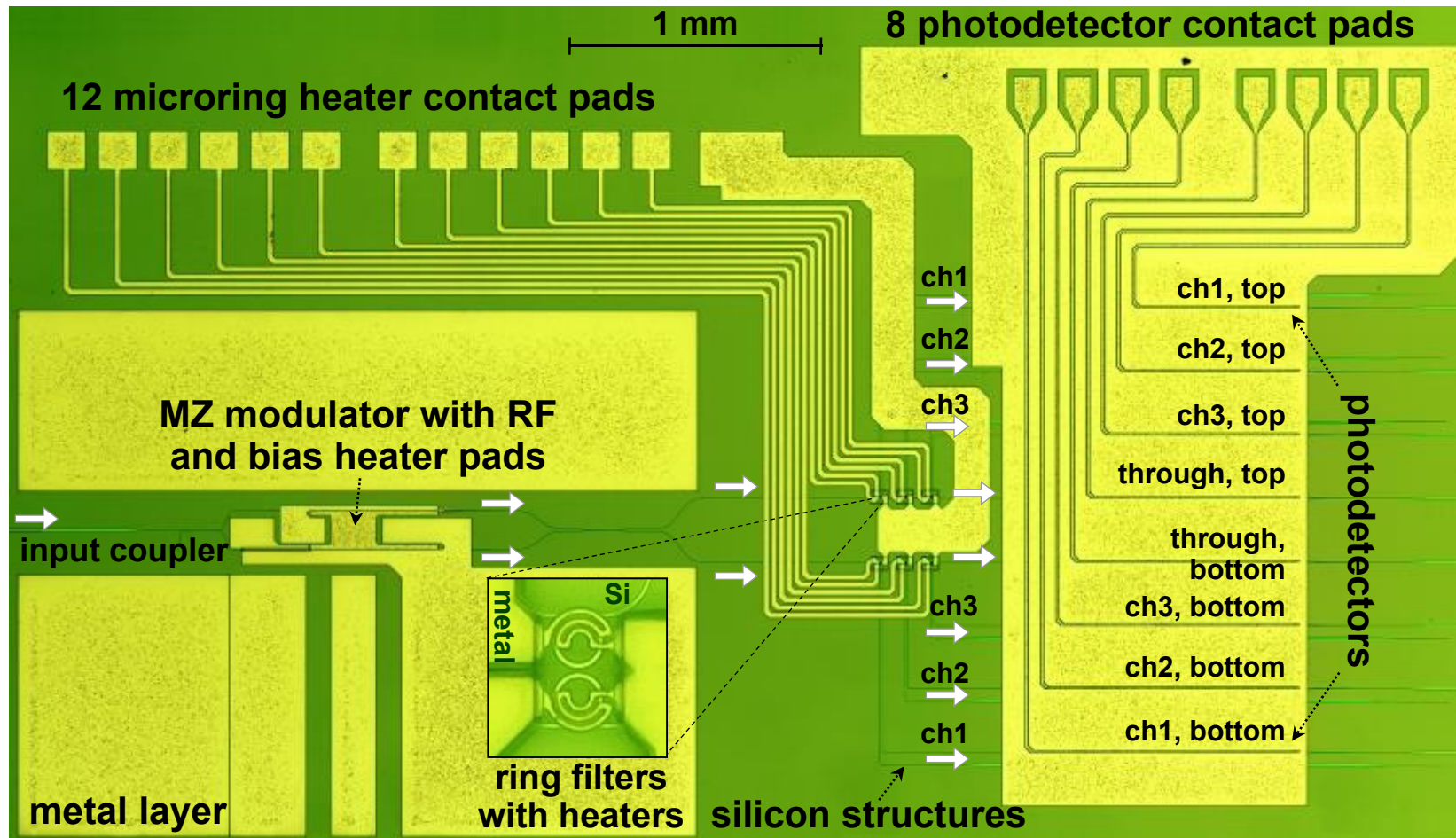
Integrated Silicon Photonic ADC



Grein *et al.*, CLEO 2011

Khilo *et al.*, Opt. Exp. (20) 4454 (2012)

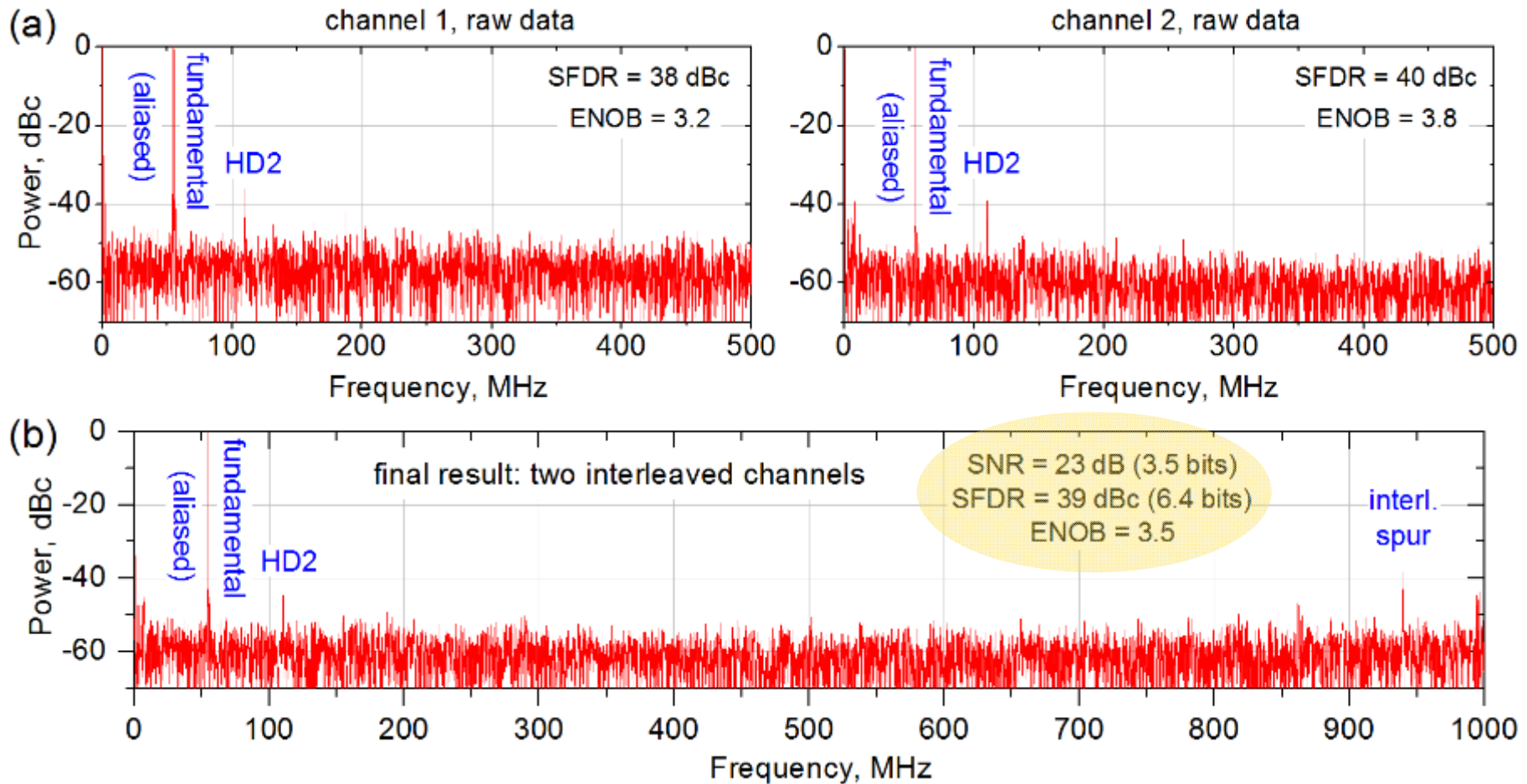
Integrated Silicon Photonic ADC



Grein *et al.*, CLEO 2011

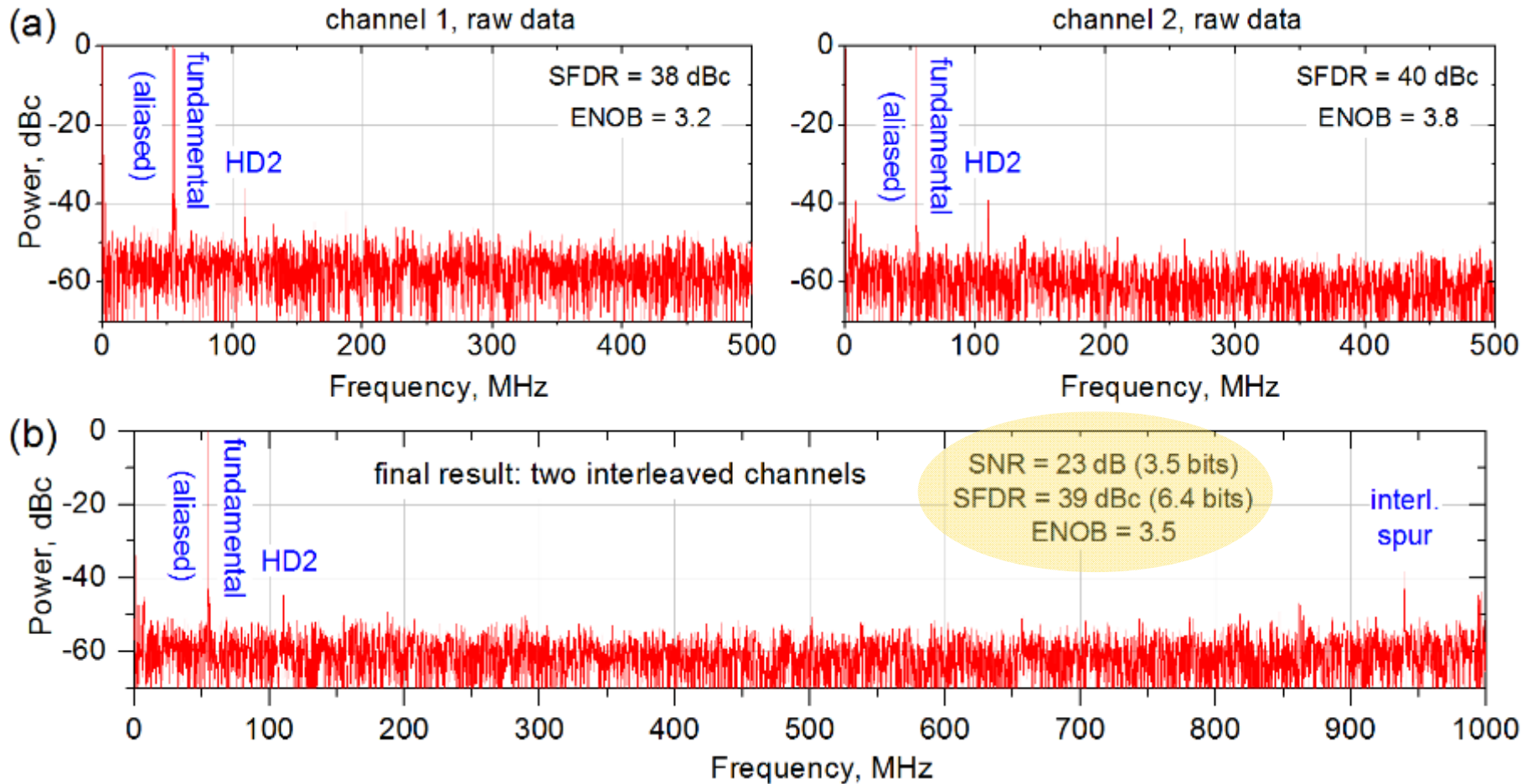
Khilo *et al.*, Opt. Exp. (20) 4454 (2012)

Integrated Silicon Photonic ADC



- 2 wavelength channels

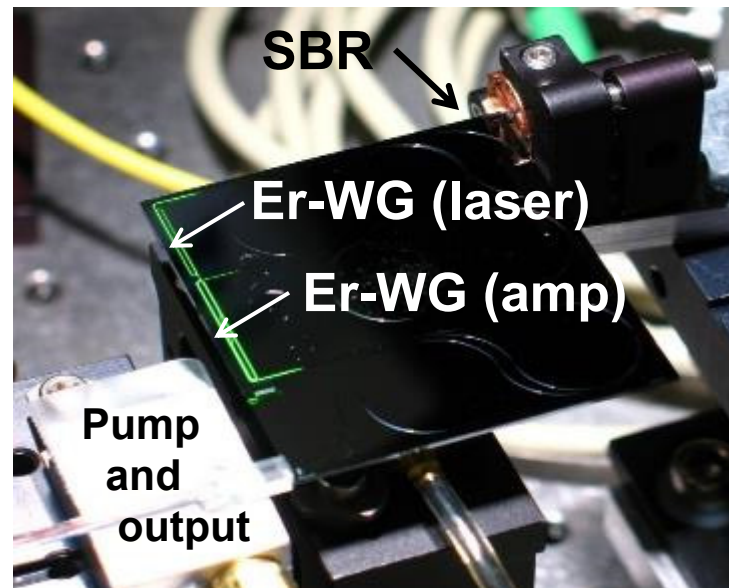
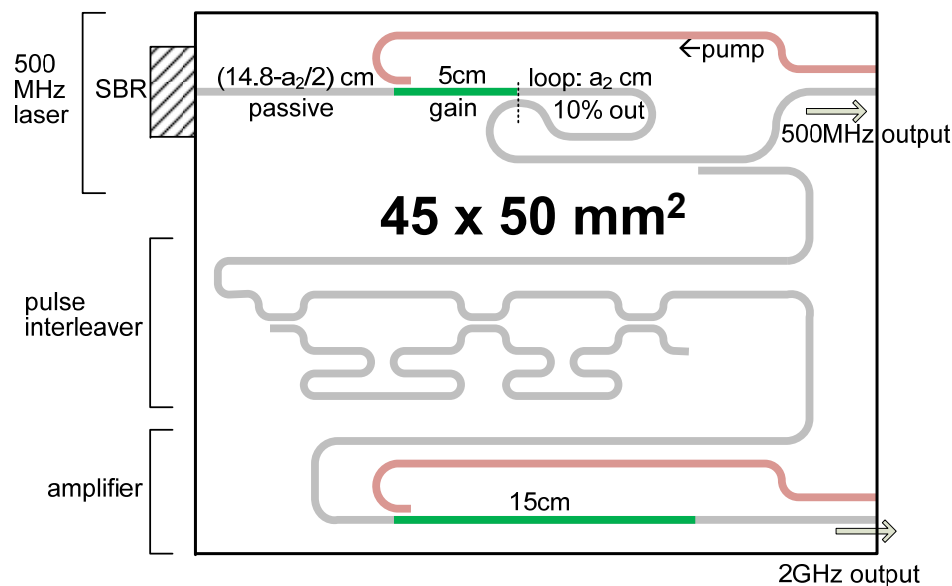
Integrated Silicon Photonic ADC



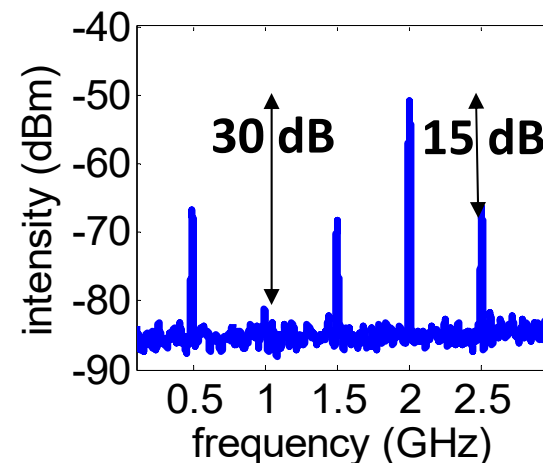
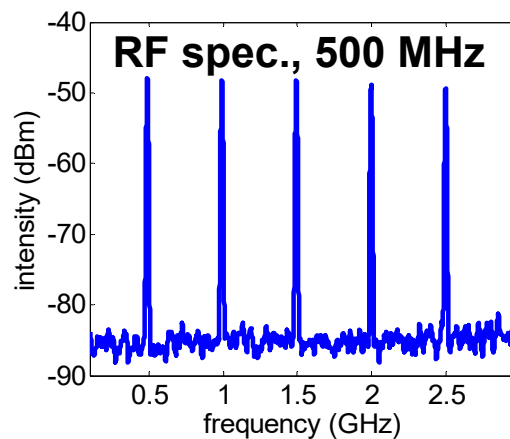
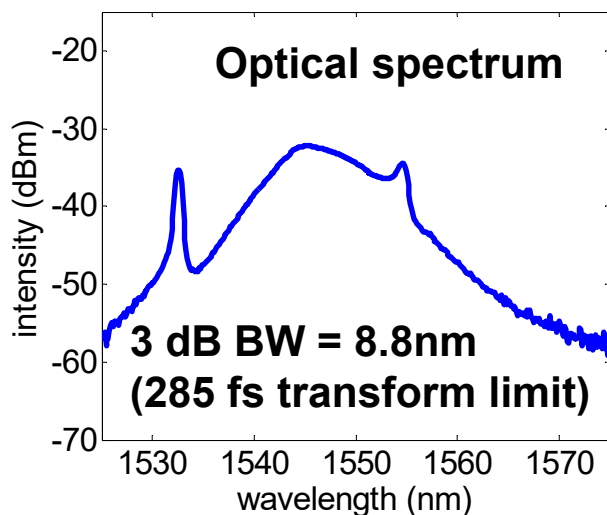
- 2 wavelength channels

**3.5 ENOB
@ 1 GHz**

2 GHz integrated waveguide lasers



Waveguide laser setup



(CS-EPS)

Michael Watts (Principal Investigator),
Franz Kärtner, & Erich Ippen, MIT

*Si photonic, CW and mode-locked laser/pulse generator, and
electronics design and test*



Vladimir Stojanovic, UC Berkeley

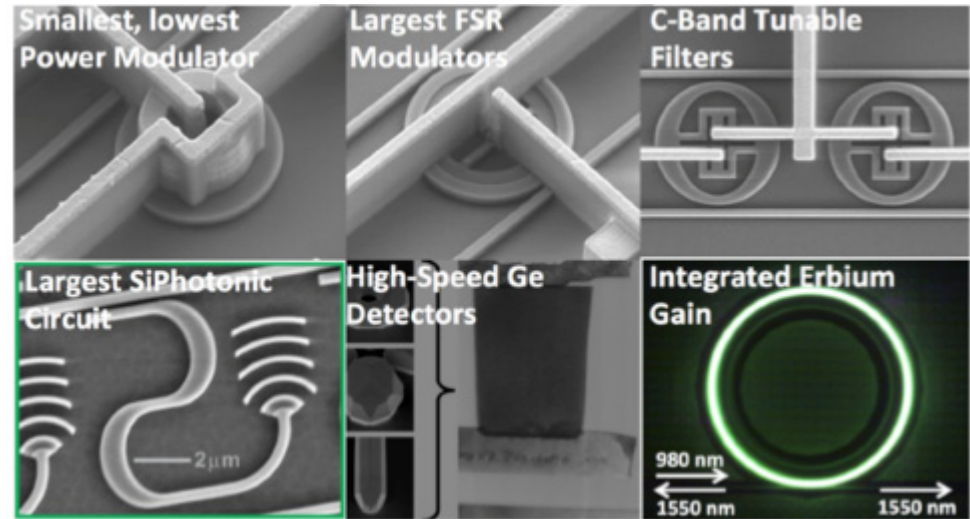
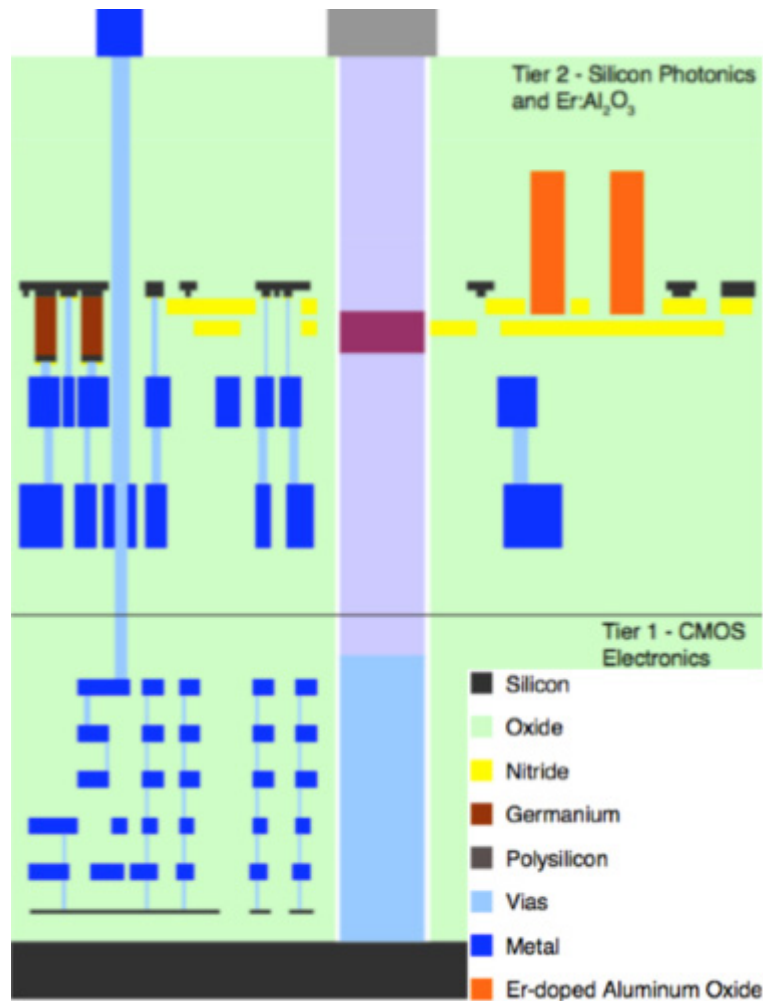
*Electronic-photonic system modeling & CMOS loop and
component design*



Douglas Coolbaugh, SUNY-CNSE

CMOS and silicon photonics fabrication

MIT 3D Electronic-Photonic Integration Platform



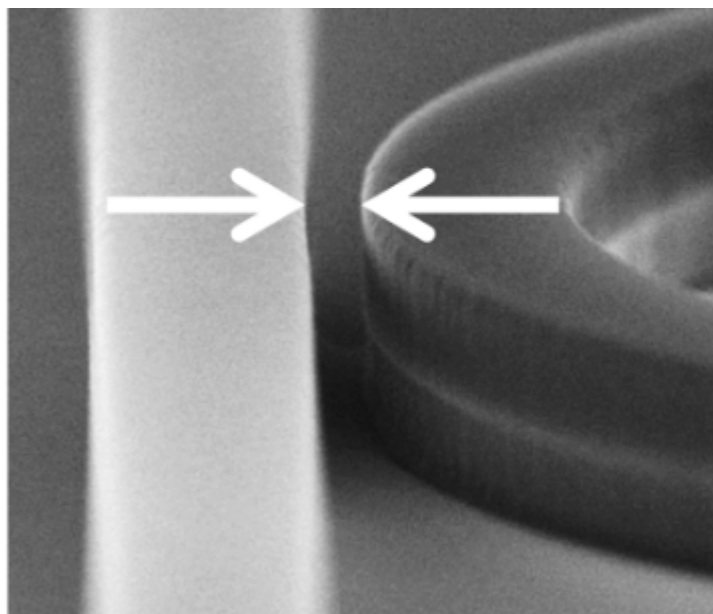
Comprehensive Device Library:

- Low loss Si, SiN waveguides
- Tunable micro-ring filters
- Ultralow power modulators, phase shifters, switches, tuners
- High speed Ge-detectors
- Low loss Si – SiN – transitions
- Low loss fiber-to-chip couplers
- Erbium/Thulium on-chip gain, lasers
- Largest Si-photonic circ. (phased array)

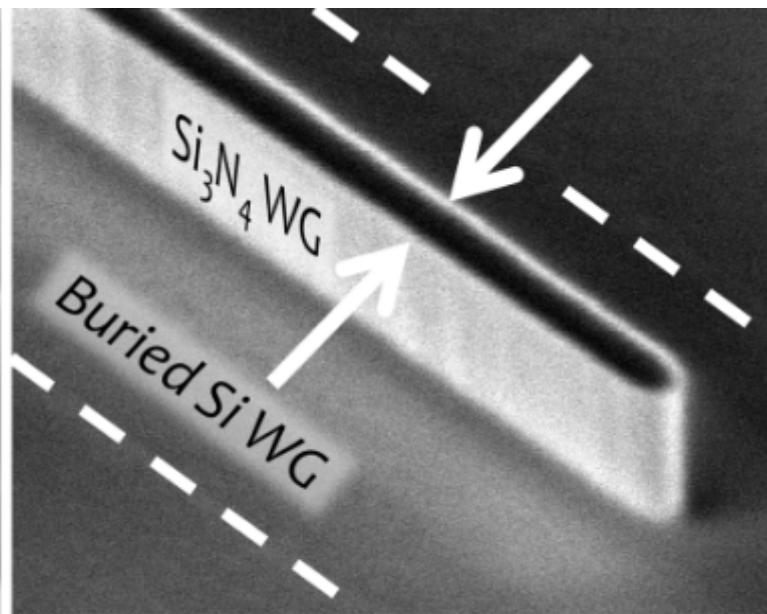
300mm Wafer-Scale Fabrication Capability

Typical Resolution w/ 193nm Immersion, Chrome-on-Glass:

- Current Resolution: 95nm lines and spaces without proximity corrections or phase shift masks.
- CNSE's Capability: 20nm lines and spaces, but feel the effort below 65nm is too great to be justified for SiPhotonics



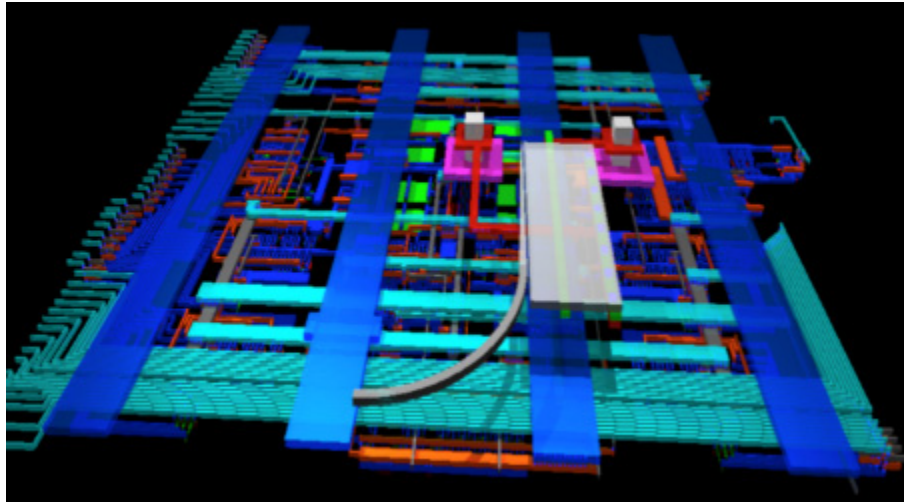
95nm gap in Si.



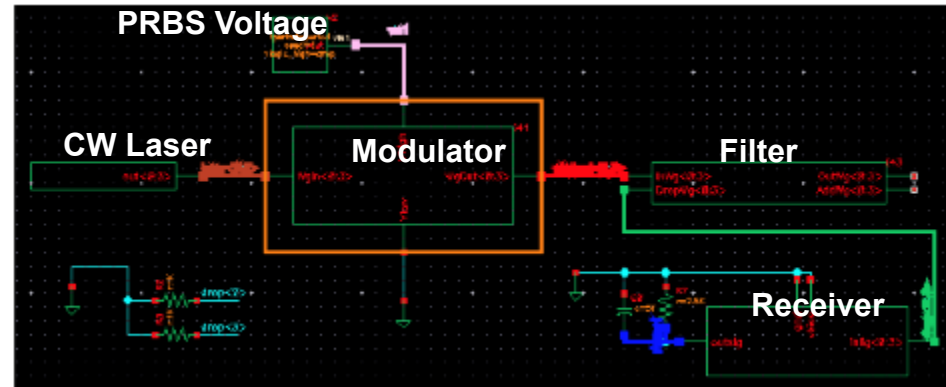
95nm Si₃N₄ taper on Si waveguide.

Modeling: Library-Based Design in CADENCE

Receiver



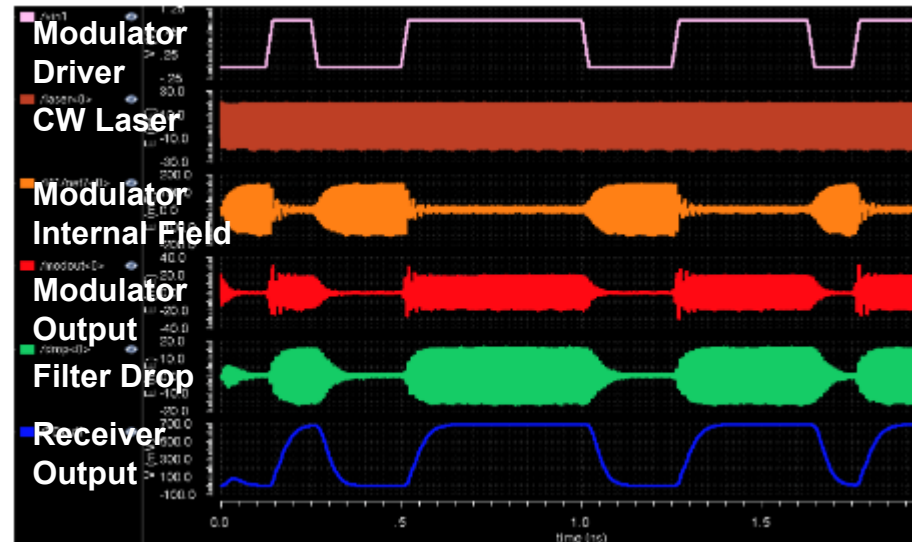
Verilog A Schematic: Communication Link



Electronic-Photonic Co-Design:

- CADENCE: All 55 CMOS, Photonic and 3D via layers
- VerilogA: Able to fully simulate both electronic and photonic signals for system output

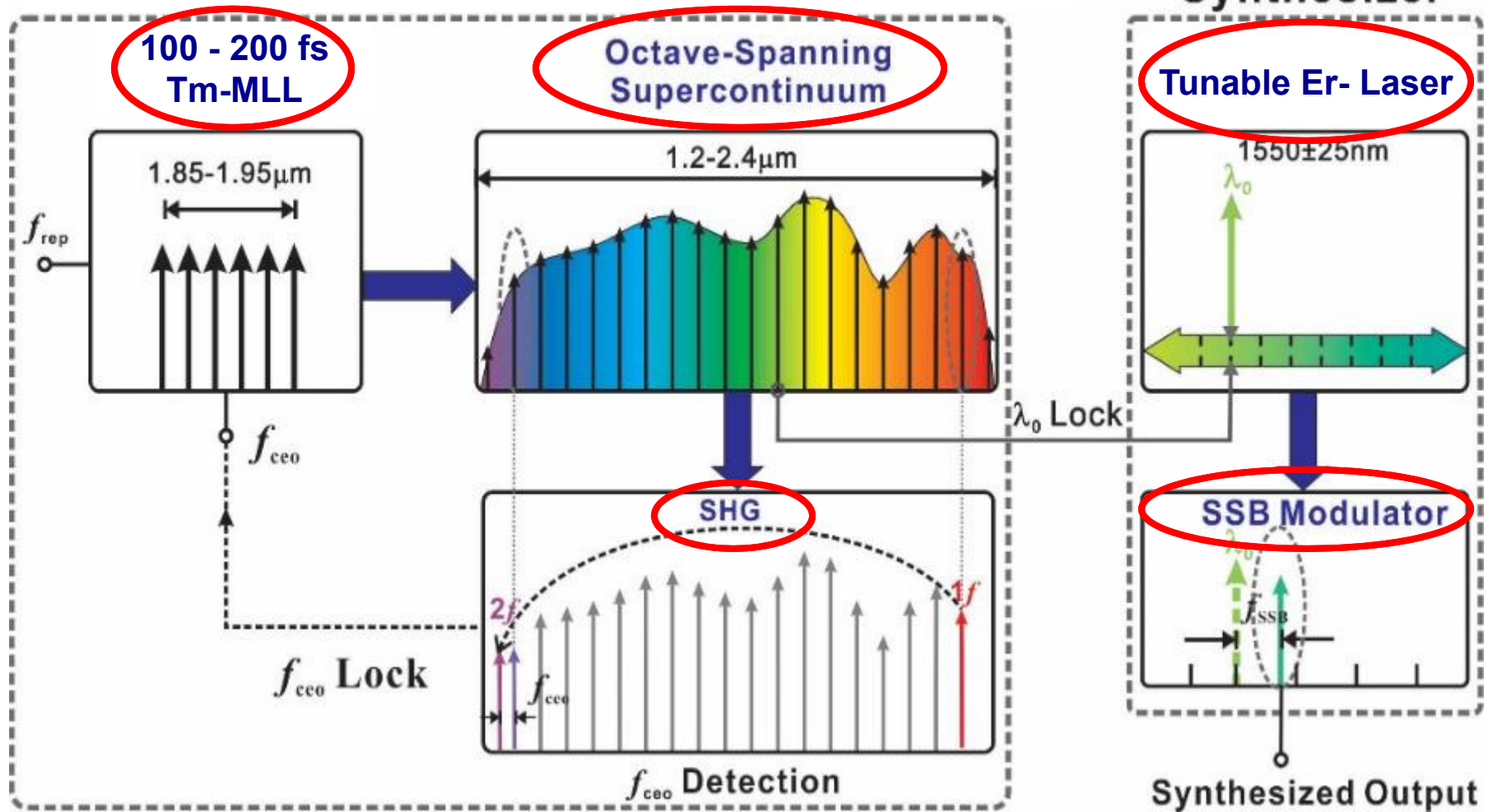
Verilog A Output: Communication Link



C. Sorace-Agaskar, J. Leu, M. R. Watts, and V. Stojanovic, "Electro-Optical Co-Simulation for Integrated CMOS Photonic Circuits with VerilogA," Opt. Express, vol. 23, no. 21 (2015).

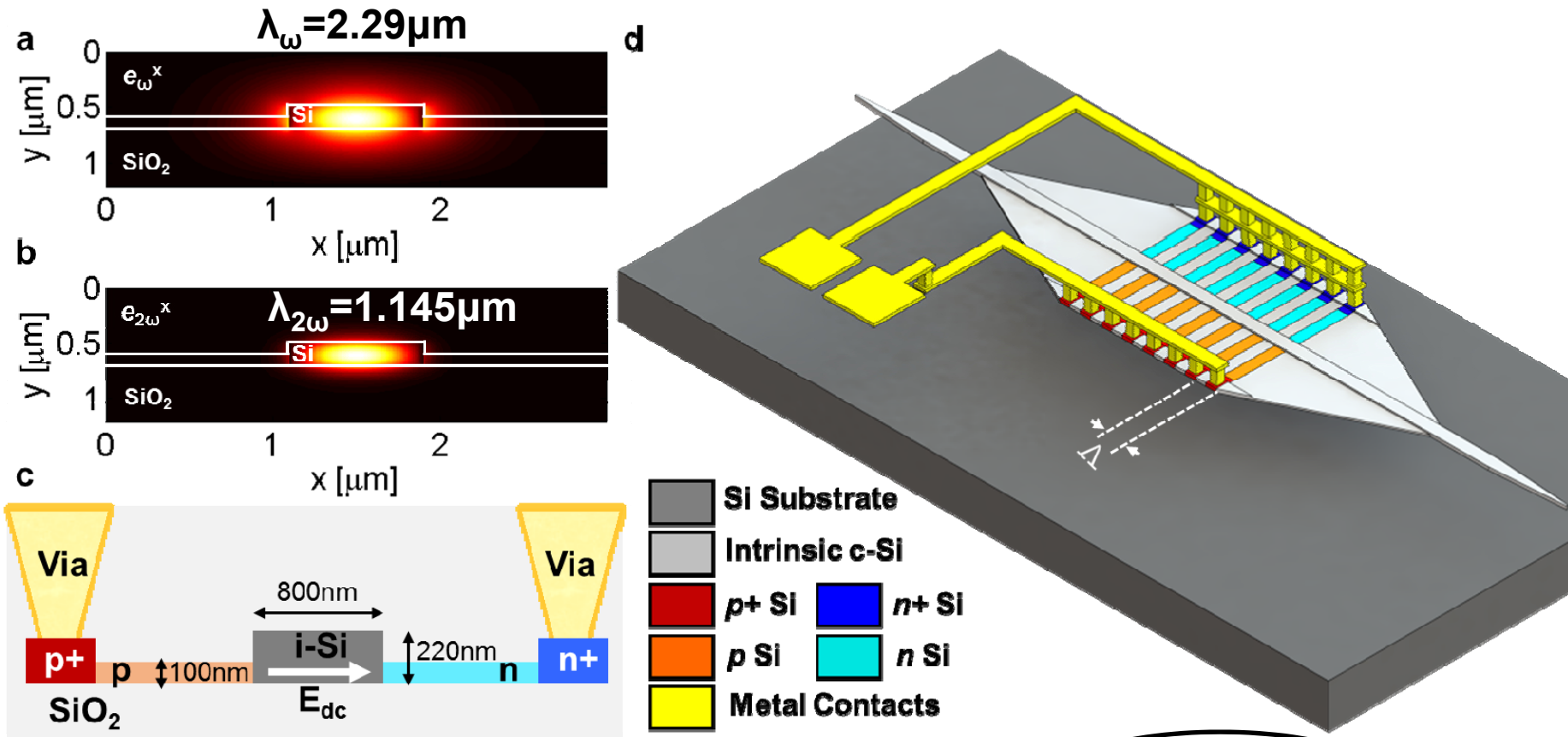
DARPA – DODOS Program

Femtosecond Laser Frequency Comb Generator



T. Hänsch & J. Hall, Nobel Prize 2005

Second Harmonic Generation in Silicon by EFISH



❑ Quasi-phase-matching as an alternative

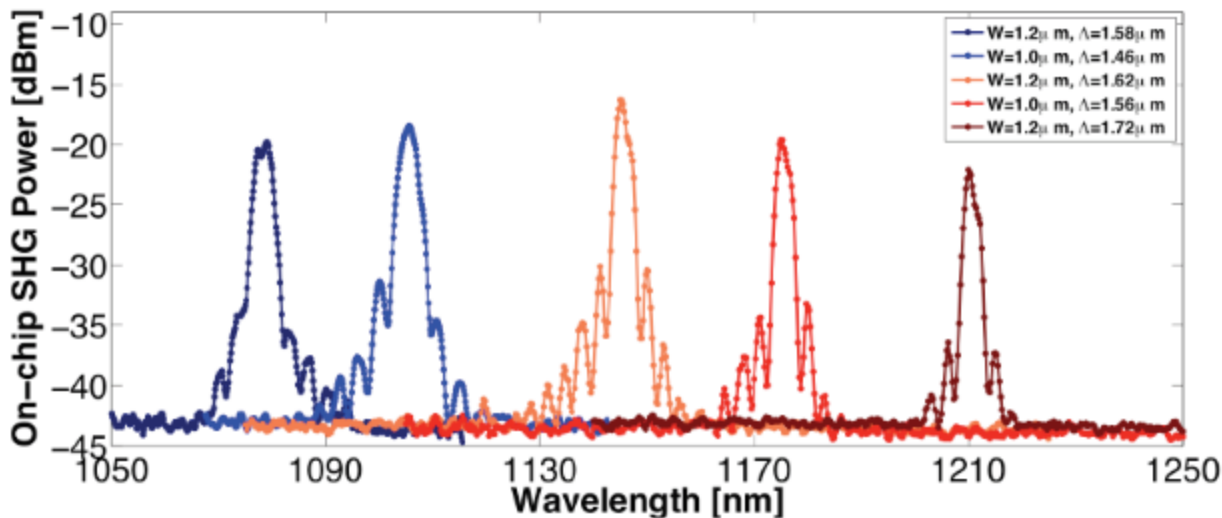
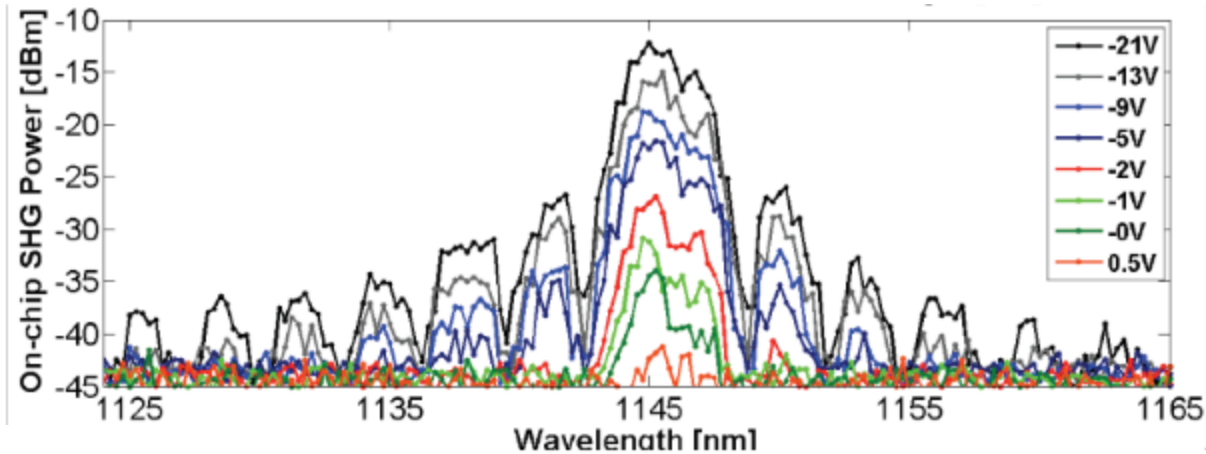
$$\bar{\chi}_{113}^{(2)} = 3\chi_{113}^{(2)} \sqrt{\nu_1} \int_0^L e_{2\omega}^z e_{\omega}^z e_{\omega}^z E_{dc}^x dy$$

❑ Field induced χ^2 in silicon \rightarrow break the crystalline symmetry

Large Overlap

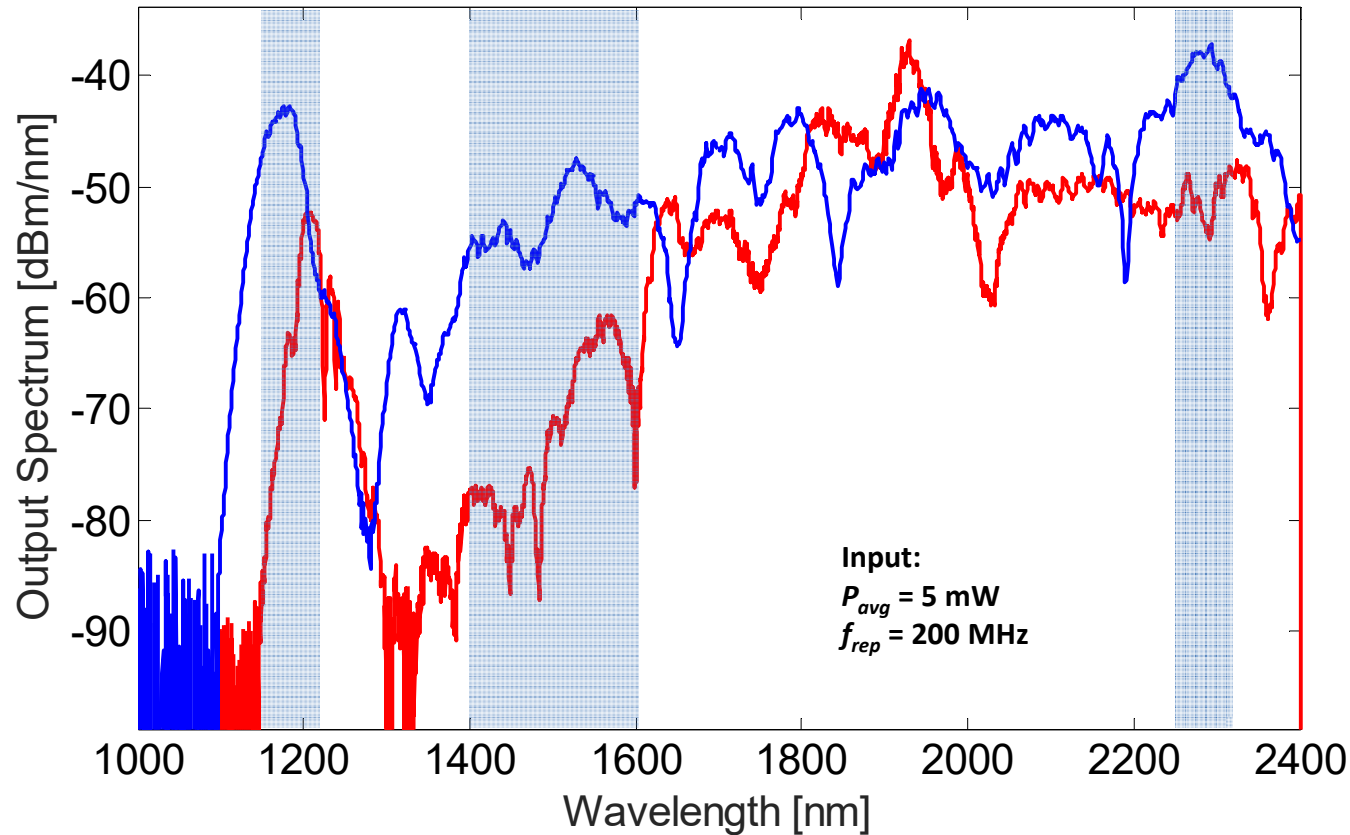
Frequency Doubler

- Broadband Second Harmonic Generation in Silicon demonstrated

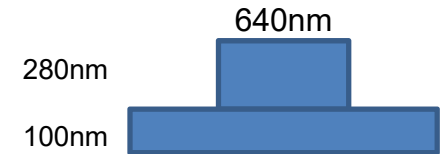


- 13%/W conversion efficiency measured with CW and pulsed input sources
- Devices can be optimized for a wide variety of wavelengths by adjusting the phase-matching period

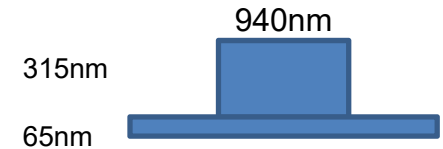
Supercontinuum Generation



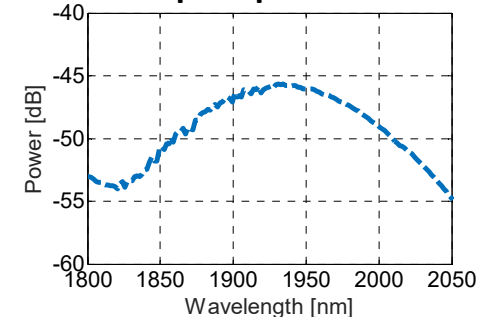
Phase 1 Design (red):



Phase 1.5 Design (blue):

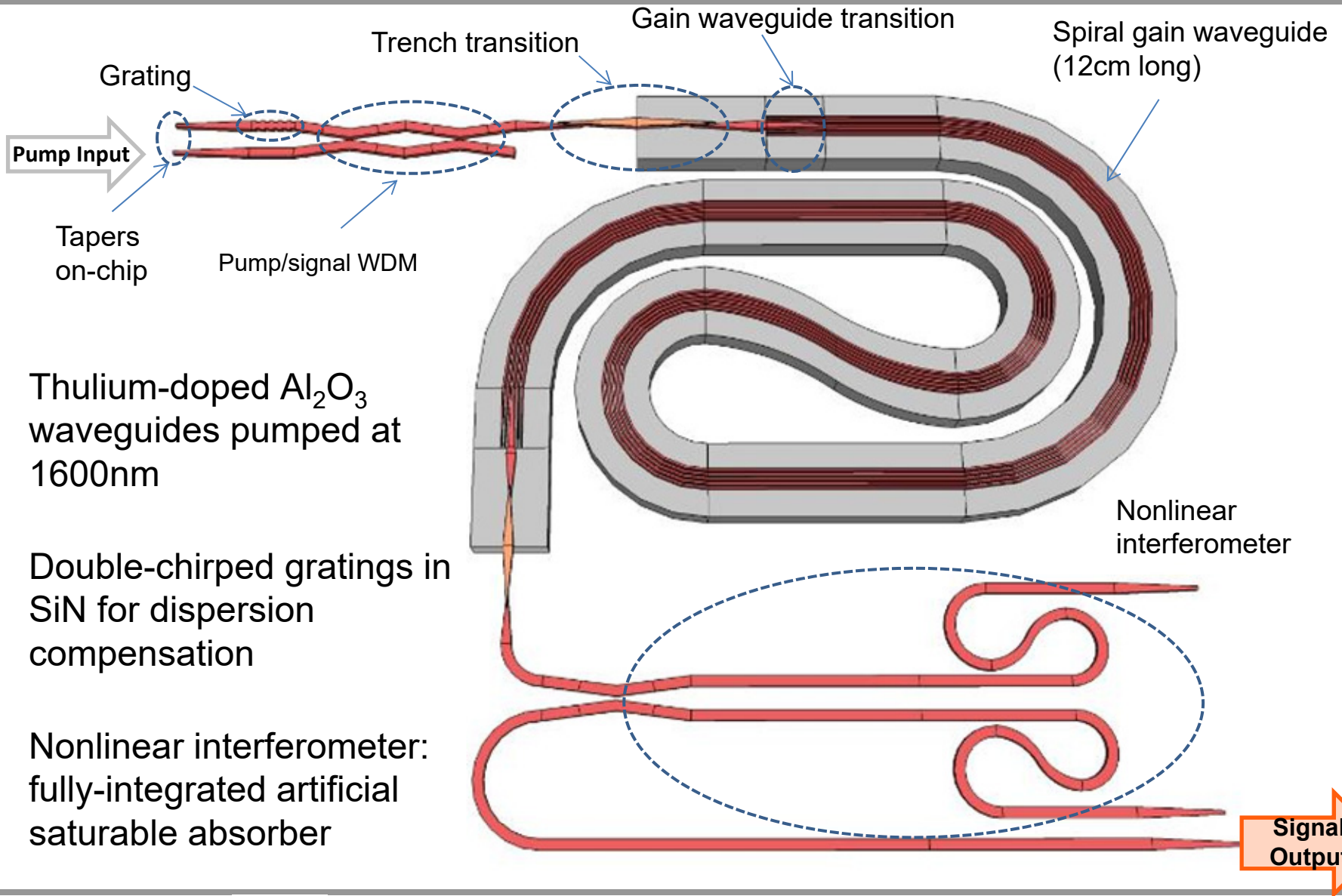


Input Spectrum:



Improved output spectrum with new generation of SC devices
Stronger spectrum around 1550nm
Stronger signal at 1150nm, enables using 2.3um for SHG

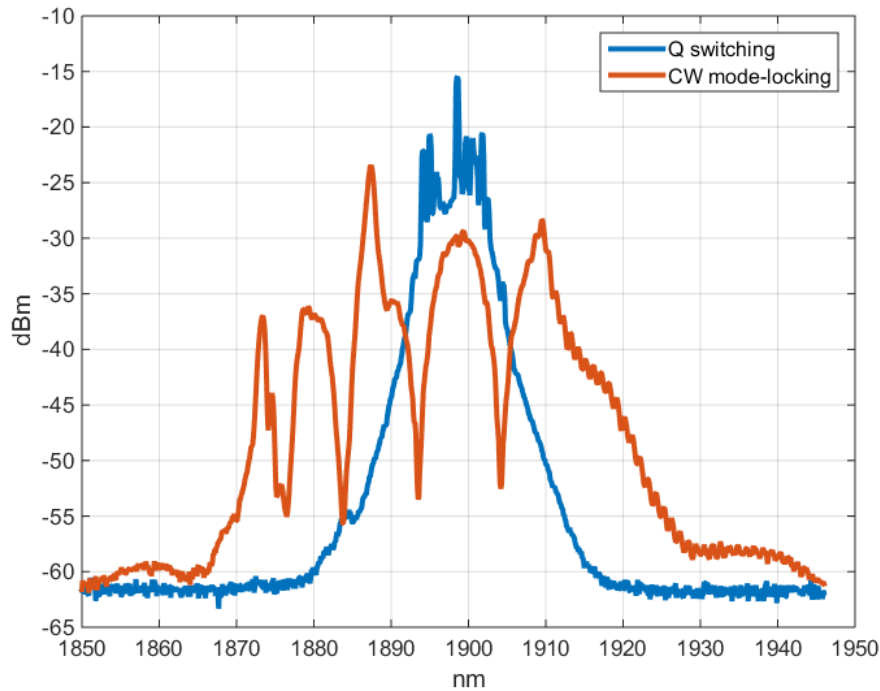
Integrated Thulium Mode-Locked Laser



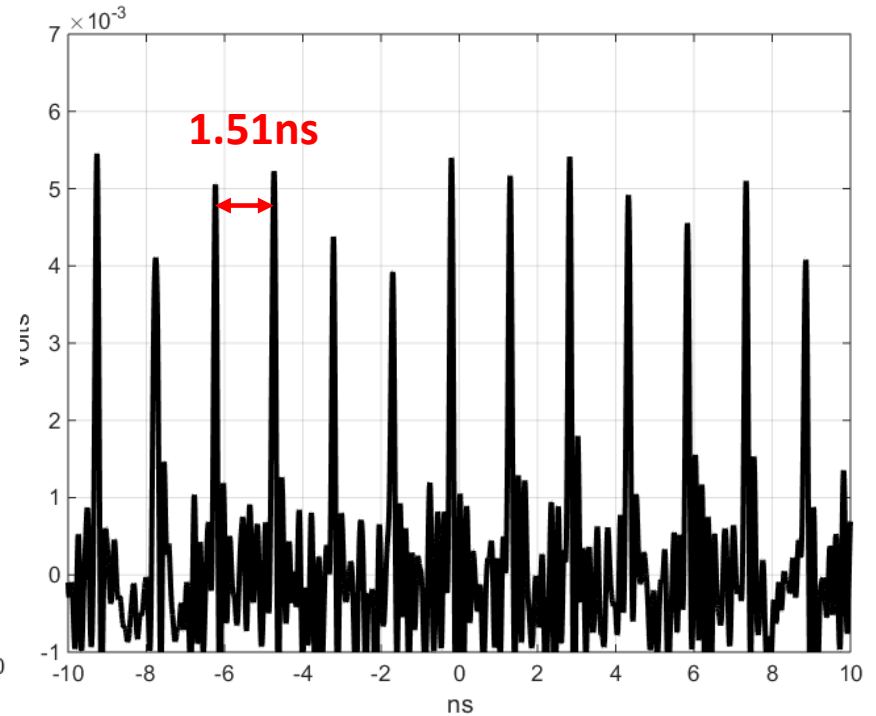
- Thulium-doped Al_2O_3 waveguides pumped at 1600nm
- Double-chirped gratings in SiN for dispersion compensation
- Nonlinear interferometer: fully-integrated artificial saturable absorber

First Results

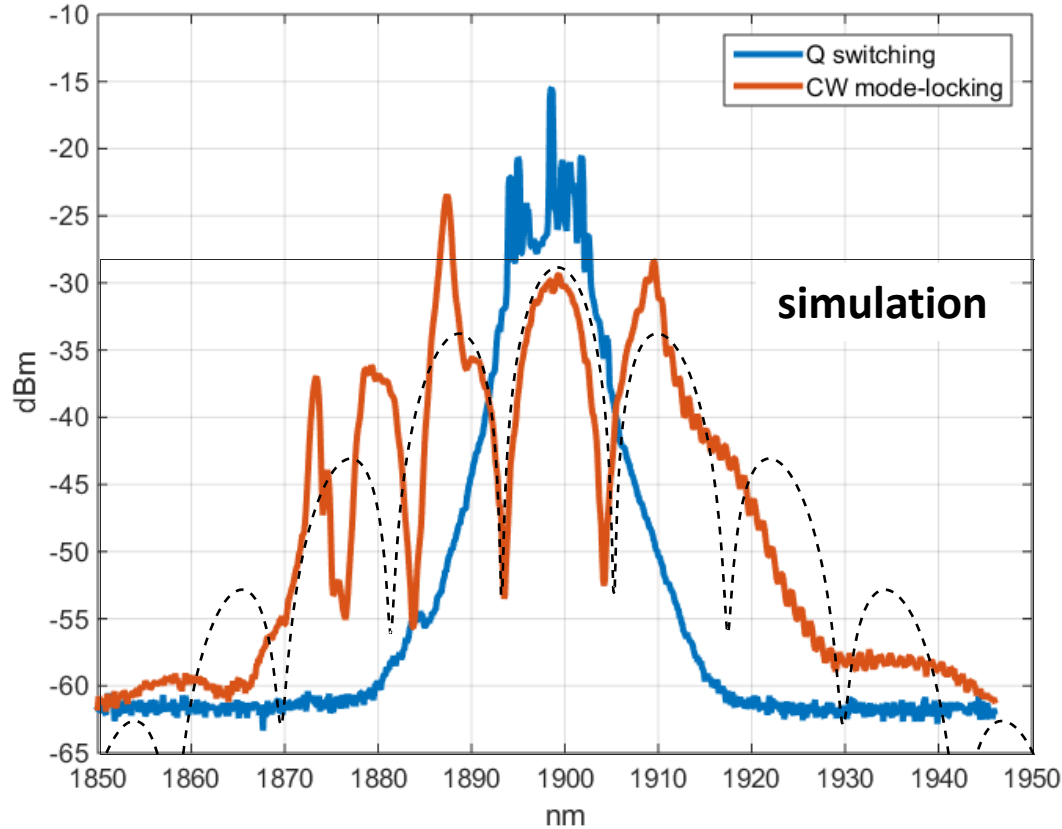
Spectral domain data



Time-domain data



First Results



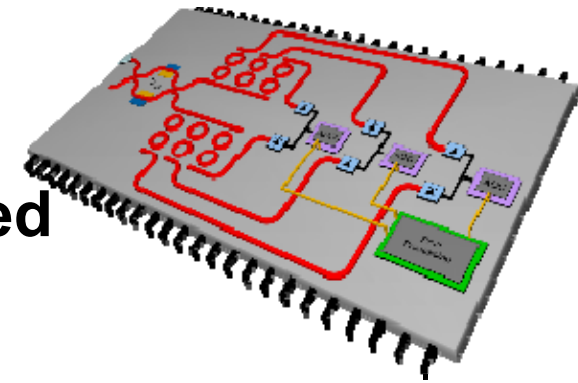
Simulation:

- Two pulses: 250 fs & 265 fs pulse duration
- Delay between pulses: 1ps

Fringe width is inversely proportional to delay.

Conclusions and Outlook

- Accelerator and XFEL facilities are combined accelerator and laser facility.
- Mode-locked lasers provide low jitter (atto-sec.) pulse trains for timing and diagnostics everywhere
- A down converting sampler at 41 GHz with 2.1 GSa/s and 7.0 ENOB has been demonstrated
~ 15 fs jitter
- Enabling High speed, high resolution photonicly assisted ADCs
- Complex opto-electronic circuitry, optical table sized, including modelocked lasers will become available on a finger nail sized chip over the next decade.



Thank You!

